



MPC5675K

MPC5675K Microcontroller Data Sheet

1 Introduction

1.1 Document overview

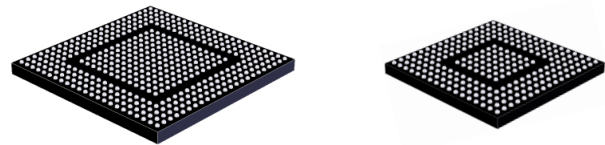
This document provides electrical specifications, pin assignments, and package diagrams for the MPC5675K series of microcontroller units (MCUs).

1.2 Description

The MPC5675K microcontroller, a SafeAssure solution, is a 32-bit embedded controller designed for advanced driver assistance systems with RADAR, CMOS imaging, LIDAR and ultrasonic sensors, and multiple 3-phase motor control applications as in hybrid electric vehicles (HEV) in automotive and high temperature industrial applications.

A member of NXP Semiconductor’s MPC5500/5600 family, it contains the Book E compliant Power Architecture® technology core with Variable Length Encoding (VLE). This core complies with the Power Architecture embedded category, and is 100 percent user mode compatible with the original Power PC™ user instruction set architecture (UISA). It offers system performance up to four times that of its MPC5561 predecessor, while bringing you the reliability and familiarity of the proven Power Architecture technology.

A comprehensive suite of hardware and software development tools is available to help simplify and speed system design. Development support is available from leading tools vendors providing compilers, debuggers and simulation development environments.



473 MAPBGA
(19 x 19 mm)

257 MAPBGA
(14 x 14 mm)

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1.3 Device comparison

Table 1. MPC5675K family device comparison

| Features | | MPC5673K | MPC5674K | MPC5675K |
|----------|---|--|---------------------------|-------------------------|
| CPU | Type | 2 × e200z7d (SoR ¹) in lock-step or decoupled operation | | |
| | Architecture | Harvard | | |
| | Execution speed | 0–150 MHz (+2% FM) | 0–180 MHz (+2% FM) | 0–180 MHz (+2% FM) |
| | Nominal platform frequency (in 1:1, 1:2, and 1:3 modes) | 0–75 MHz (+2% FM) | 0–90 MHz (+2% FM) | 0–90 MHz (+2% FM) |
| | MMU | 64 entries (SoR) | | |
| | Instruction set PPC | Yes | | |
| | Instruction set VLE | Yes | | |
| | Instruction cache | 16 KB, 4-way with EDC (SoR) | | |
| | Data cache | 16 KB, 4-way with Parity (SoR) | | |
| | MPU | Yes (SoR) | | |
| Buses | Core bus | 32-bit address, 64-bit data | | |
| | Internal periphery bus | 32-bit address, 32-bit data | | |
| XBAR | Master × slave ports | Yes (SoR) | | |
| Memory | Static RAM (SRAM) | 256 KB (ECC) | 384 KB (ECC) | 512 KB (ECC) |
| | Code flash memory | 1 MB ² (ECC) | 1.5 MB ² (ECC) | 2 MB ² (ECC) |
| | Data flash memory | 64 KB ² (ECC) | | |
| Modules | Analog-to-Digital Converter (ADC) | 257 pin pkg: 4 × 12 bit (22 external channels) 473 pin pkg: 4 × 12 bit (up to 34 external channels) | | |
| | CRC unit | 2 (3 contexts each) | | |
| | Cross Triggering Unit (CTU) | 2 modules | | |
| | Deserial Serial Peripheral Interface (DSPI) | 2 modules (3 chip selects) ³ | 3 modules ⁴ | |
| | Digital I/Os | ≥ 16 | | |
| | DRAM Controller (DRAMC) | No | Yes ⁵ | |
| | Enhanced Direct Memory Access (eDMA) | 2 modules, 32 channels each | | |
| | eTimer | 3 modules, 6 channels each | | |

Table 1. MPC5675K family device comparison (continued)

| Features | | MPC5673K | MPC5674K | MPC5675K |
|------------------------|---|---|-----------|----------|
| Modules (cont.) | External Bus Interface (EBI) | 1 module ⁵ 16-bit Data + Address or 32-bit Data with Address bus muxed ⁸ | | |
| | Fast Ethernet Controller (FEC) | 1 module | | |
| | Fault Collection and Control Unit (FCCU) | 1 module | | |
| | FlexCAN | 4 modules (32 message buffers each) | | |
| | FlexPWM | 3 modules (each 4 × 3 channels) | | |
| | FlexRay | Optional | | |
| | I ² C | 2 modules ⁶ | 3 modules | |
| | Interrupt Controller (INTC) | Yes (SoR) | | |
| | LINFlex | 3 modules ⁷ | 4 modules | |
| | Parallel Data Interface (PDI) | 1 module ⁸ | | |
| | Periodic Interrupt Timer (PIT) | 1 module, 4 channels | | |
| | Software Watchdog Timer (SWT) | Yes (SoR) | | |
| | System Timer Module (STM) | Yes (SoR) | | |
| | Temperature sensor | 1 module | | |
| | Wakeup Unit (WKPU) | Yes | | |
| Crossbar switch (XBAR) | 3 modules, 2 are user-configurable | | | |
| Clocking | Clock monitor unit (CMU) | 3 modules | | |
| | Frequency-modulated phase-locked loop (FMPLL) | 2 modules (system and auxiliary) | | |
| | IRCOSC – 16 MHz | 1 | | |
| | XOSC 4–40 MHz | 1 | | |
| Supply | Power management unit (PMU) | Yes | | |
| | 1.2 V low-voltage detector (LVD12) | 1 | | |
| | 1.2 V high-voltage detector (HVD12) | 1 | | |
| | 2.7 V low-voltage detector (LVD27) | 4 | | |
| Debug | Nexus | Class 3+ (for cores and SRAM ports) | | |

Table 1. MPC5675K family device comparison (continued)

| Features | | MPC5673K | MPC5674K | MPC5675K |
|-------------|---------|--|----------------------|----------|
| Packages | MAPBGA | | 257 pins 473 pins | |
| Temperature | Ambient | See the T_A recommended operating condition in the device data sheet | | |

¹ Sphere of Replication.

² Does not include Test or Shadow Flash memory space.

³ DSPI_0 and DSPI_1.

⁴ DSPI_0 has 8 chip selects; DSPI_1 and DSPI_2 have 4 chip selects each.

⁵ Available only on 473-pin package.

⁶ Any two of the three I2C can be chosen.

⁷ LinFlex_0, LinFlex_1, and LinFlex_2.

⁸ DDR available only on 473 package. Other modules available as follows:
 EBI or DDR on 473 package
 EBI + PDI on 473 package
 DDR + PDI on 473 package
 PDI only on 257 package

1.4 Block diagram

Figure 1 shows a top-level block diagram of the MPC5675K device.

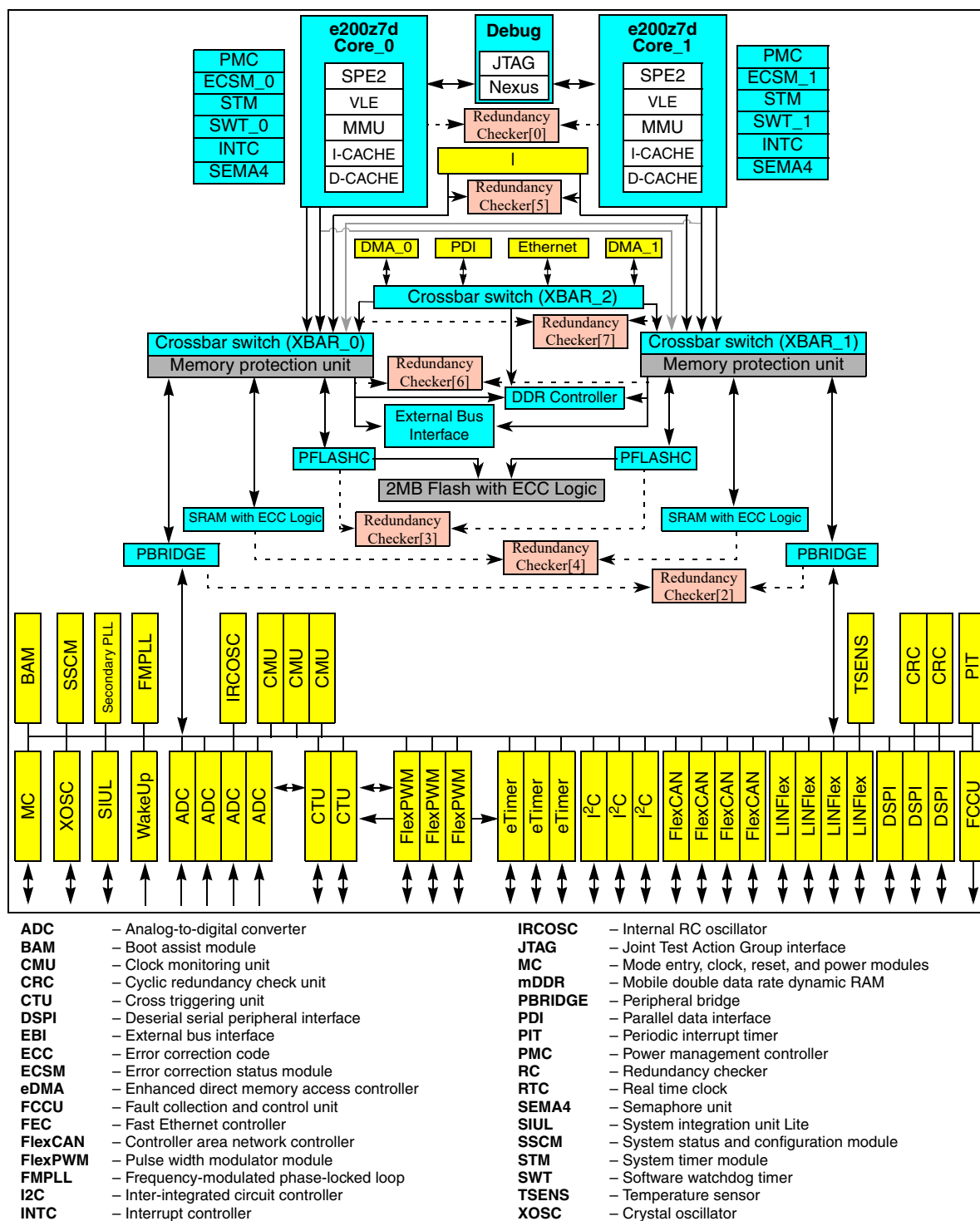


Figure 1. MPC5675K block diagram

1.5 Feature list

- High-performance e200z7d dual core
 - 32-bit Power Architecture® technology CPU
 - Up to 180 MHz core frequency
 - Dual-issue core
 - Variable length encoding (VLE)
 - Memory management unit (MMU) with 64 entries
 - 16 KB instruction cache and 16 KB data cache
- Memory available
 - Up to 2 MB code flash memory with ECC
 - 64 KB data flash memory with ECC
 - Up to 512 KB on-chip SRAM with ECC
- SIL3/ASILD innovative safety concept: LockStep mode and fail-safe protection
 - Sphere of replication (SoR) for key components
 - Redundancy checking units on outputs of the SoR connected to FCCU
 - Fault collection and control unit (FCCU)
 - Boot-time built-in self-test for memory (MBIST) and logic (LBIST) triggered by hardware
 - Boot-time built-in self-test for ADC and flash memory
 - Replicated safety-enhanced watchdog timer
 - Silicon substrate (die) temperature sensor
 - Non-maskable interrupt (NMI)
 - 16-region memory protection unit (MPU)
 - Clock monitoring units (CMU)
 - Power management unit (PMU)
 - Cyclic redundancy check (CRC) units
- Decoupled Parallel mode for high-performance use of replicated cores
- Nexus Class 3+ interface
- Interrupts
 - Replicated 16-priority interrupt controller
- GPIOs individually programmable as input, output, or special function
- 3 general-purpose eTimer units (6 channels each)
- 3 FlexPWM units with four 16-bit channels per module
- Communications interfaces
 - 4 LINFlex modules
 - 3 DSPI modules with automatic chip select generation
 - 4 FlexCAN interfaces (2.0B Active) with 32 message objects
 - FlexRay module (V2.1) with dual channel, up to 128 message objects and up to 10 Mbit/s
 - Fast Ethernet Controller (FEC)
 - 3 I²C modules
- Four 12-bit analog-to-digital converters (ADCs)
 - 22 input channels
 - Programmable cross triggering unit (CTU) to synchronize ADC conversion with timer and PWM
- External bus interface
- 16-bit external DDR memory controller
- Parallel digital interface (PDI)

- On-chip CAN/UART bootstrap loader
- Capable of operating on a single 3.3 V voltage supply
 - 3.3 V-only modules: I/O, oscillators, flash memory
 - 3.3 V or 5 V modules: ADCs, supply to internal VREG
 - 1.8–3.3 V supply range: DRAM/PDI
- Operating junction temperature range –40 to 150 °C

1.6 Feature details

1.6.1 High-performance e200z7d core processor

- Dual 32-bit Power Architecture® processor core
- Loose or tight core coupling
- NXP Variable Length Encoding (VLE) enhancements for code size footprint reduction
- Thirty-two 64-bit general-purpose registers (GPRs)
- Memory management unit (MMU) with 64-entry fully-associative translation look-aside buffer (TLB)
- Branch processing unit
- Fully pipelined load/store unit
- 16 KB Instruction and 16 KB Data caches per core with line locking
 - Four way set associative
 - Two 32-bit fetches per clock
 - Eight-entry store buffer
 - Way locking
 - Supports tag and data cache parity
 - Supports EDC for instruction cache
- Vectored interrupt support
- Signal processing engine 2 (SPE2) auxiliary processing unit (APU) operating on 64-bit general purpose registers
- Floating point
 - IEEE® 754 compatible with software wrapper
 - Single precision in hardware; double precision with software library
 - Conversion instructions between single precision floating point and fixed point
- Long cycle time instructions (except for guarded loads) do not increase interrupt latency in the MPC5675K
- To reduce latency, long cycle time instructions are aborted upon interrupt requests
- Extensive system development support through Nexus debug module

1.6.2 Crossbar Switch (XBAR)

- 32-bit address bus, 64-bit data bus
- Simultaneous accesses from different masters to different slaves (there is no clock penalty when a parked master accesses a slave)

1.6.3 Memory Protection Unit (MPU)

Each master (eDMA, FlexRay, CPU) can be assigned different access rights to each region.

- 16-region MPU with concurrent checks against each master access
- 32-byte granularity for protected address region

1.6.4 Enhanced Direct Memory Access (eDMA) controller

- 32 channels support independent 8-, 16-, 32-bit single value or block transfers
- Supports variable-sized queues and circular queues
- Source and destination address registers are independently configured to post-increment or remain constant
- Each transfer is initiated by a peripheral, CPU, or eDMA channel request
- Each eDMA channel can optionally send an interrupt request to the CPU on completion of a single value or block transfer

1.6.5 Interrupt Controller (INTC)

- 208 peripheral interrupt requests
- 8 software settable sources
- Unique 9-bit vector per interrupt source
- 16 priority levels with fixed hardware arbitration within priority levels for each interrupt source
- Priority elevation for shared resources

1.6.6 Frequency-Modulated Phase-Locked Loop (FMPLL)

Two FMPLLs are available on each device.

Each FMPLL allows the user to generate high speed system clocks starting from a minimum reference of 4 MHz input clock. Further, the FMPLL supports programmable frequency modulation of the system clock. The PLL multiplication factor and output clock divider ratio are software configurable. The FMPLLs have the following major features:

- Input frequency: 4–40 MHz continuous range (limited by the crystal oscillator)
- Voltage controlled oscillator (VCO) range: 256–512 MHz
- Frequency modulation via software control to reduce and control emission peaks
 - Modulation depth $\pm 2\%$ if centered or 0% to -4% if downshifted via software control register
 - Modulation frequency: triangular modulation with 25 kHz nominal rate
- Option to switch modulation on and off via software interface
- Reduced frequency divider (RFD) for reduced frequency operation without re-lock
- 2 modes of operation
 - Normal PLL mode with crystal reference (default)
 - Normal PLL mode with external reference
- Lock monitor circuitry with lock status
- Loss-of-lock detection for reference and feedback clocks
- Self-clocked mode (SCM) operation
- Auxiliary FMPLL
 - Used for FlexRay due to precise symbol rate requirement by the protocol
 - Used for motor control periphery and connected IP (A/D digital interface CTU) to allow independent frequencies of operation for PWM and timers as well as jitter-free control
 - Option to enable/disable modulation to avoid protocol violation on jitter and/or potential unadjusted error in electric motor control loop
 - Allows running motor control periphery at different (precisely lower, equal, or higher, as required) frequency than the system to ensure higher resolution

1.6.7 External Bus Interface (EBI)

- Available on 473-pin devices
- Data and address options:
 - 16-bit data and address (non-muxed)
 - 32-bit data and address (bus-muxed)
- MPC5561 324 BGA compatibility mode: 16-bit data bus, 24-bit address bus is default ADDR[8:31], but configurable to 26-bit address bus
- Memory controller with support for various memory types
 - Non-burst and burst mode SDR flash and SRAM
 - Asynchronous/legacy flash and SRAM
- Configurable bus speed modes
- Support for 2 MB address space
- Chip select and write/byte enable options as presented in the pin-muxing table in the “Signal Description” chapter of the MPC5675K reference manual
- Configurable wait states (via chip selects)
- Optional automatic CLKOUT gating to save power and reduce EMI

1.6.8 On-chip flash memory

- Up to 2 MB code flash memory with ECC
- 64 KB data flash memory with ECC
- Censorship protection scheme to prevent flash content visibility
- Multiple block sizes to support features such as boot block, operating system block, and EEPROM emulation
- Read-while-write with multiple partitions
- Parallel programming mode to support rapid end-of-line programming
- Hardware programming state machine

1.6.9 Cache memory

- Harvard architecture cache
- 16 KB instruction / 16 KB data
- Four-way set-associative Harvard (instruction and data) 256-bit long cache
 - Two 32-bit fetches per clock
 - Eight-entry store buffer
 - Way locking
 - Supports tag and data cache parity
 - Supports EDC for instruction cache

1.6.10 On-chip internal static RAM (SRAM)

- Up to 512 KB general-purpose SRAM
- ECC performs single-bit correction, double-bit error detection
 - Address included in ECC checkbase

1.6.11 DRAM controller

The DRAM controller (available only on 473-pin devices) is a multi-port controller that monitors incoming requests on the three AHB slave ports and decides (at each rising clock edge) what command needs to be sent to the external DRAM.

The DRAM controller on this device supports the following types of memories:

- Mobile DDR (mDDR)
- DDR 1
- DDR 2 (optional)
- SDR

The controller has the following features:

- Optimized timing for 32-byte bursts and single read accesses on the AHB interface
- Optimized timing for 8-byte and 16-byte bursts on the DRAMC interface
- Supports priority elevation on the slave ports for single accesses
- 16-bit wide DRAM interface
- One chip select (CS)
- mDDR memory controller
 - 16-bit external interface
 - Address range up to 8 MB

1.6.12 Boot Assist Module (BAM)

- Enables booting via serial mode (FlexCAN, LINFlex)
- Handles static mode in case of an erroneous boot procedure
- Implemented in 8 KB ROM
- Supports Lock Step Mode (LSM) and Decoupled Parallel Mode (DPM)

1.6.13 Parallel Data Interface (PDI)

- Support for external ADC and CMOS image sensors
- Parallel interface operation up to MCU system bus frequency
- Selectable data capture from rising or falling edge
- Receive FIFO with adjustable trigger thresholds
- Data width for 8, 10, 12, 14, and 16 bits
- Data Packing Unit to pack input data on 64-bit words — data packed on 8- or 16- bit boundary, depending on input data width
- Binary increasing channel select that allows as many as eight channels to be selected
- Frame synchronization through Vsync, Hsync, PIXCLK

1.6.14 Deserial Serial Peripheral Interface (DSPI) modules

- Three serial peripheral interfaces
 - Full duplex communication ports with interrupt and eDMA request support
 - Support for all functional modes from QSPI submodule of QSMCM (MPC5xx family)
 - Support for queues in RAM
 - Six chip selects, expandable to 64 with external demultiplexers
 - Programmable frame size, baud rate, clock delay, and clock phase on a per-frame basis

- Modified SPI mode for interfacing to peripherals with longer setup time requirements
- Support for up to 60 Mbit/s in slave only Rx mode

1.6.15 Serial Communication Interface Module (LINFlex)

The LINFlex on this device features the following:

- Supports LIN Master mode, LIN Slave mode, and UART mode
- LIN state machine compliant to LIN1.3, 2.0, and 2.1 specifications
- Manages LIN frame transmission and reception without CPU intervention
- LIN features
 - Autonomous LIN frame handling
 - Message buffer to store as many as 8 data bytes
 - Supports messages as long as 64 bytes
 - Detection and flagging of LIN errors (Sync field, delimiter, ID parity, bit framing, checksum and timeout errors)
 - Classic or extended checksum calculation
 - Configurable break duration of up to 36-bit times
 - Programmable baud rate prescalers (13-bit mantissa, 4-bit fractional)
 - Diagnostic features (loop back, LIN bus stuck dominant detection)
 - Interrupt-driven operation with 16 interrupt sources
- LIN slave mode features
 - Autonomous LIN header handling
 - Autonomous LIN response handling
- UART mode
 - Full-duplex operation
 - Standard non return-to-zero (NRZ) mark/space format
 - Data buffers with 4-byte receive, 4-byte transmit
 - Configurable word length (8-bit, 9-bit, or 16-bit words)
 - Configurable parity scheme: none, odd, even, always 0
 - Speed as fast as 2 Mbit/s
 - Error detection and flagging (parity, noise, and framing errors)
 - Interrupt-driven operation with four interrupt sources
 - Separate transmitter and receiver CPU interrupt sources
 - 16-bit programmable baud-rate modulus counter and 16-bit fractional
 - Two receiver wake-up methods
- Support for DMA-enabled transfers

1.6.16 FlexCAN

- Thirty-two message buffers each
- Full implementation of the CAN protocol specification, Version 2.0B
- Programmable acceptance filters
- Individual Rx filtering per message buffer
- Short latency time for high priority transmit messages
- Arbitration scheme according to message ID or message buffer number
- Listen-only mode capabilities
- Programmable clock source: system clock or oscillator clock

Introduction

- Reception queue possible by setting more than one Rx message buffer with the same ID
- Backwards compatible with previous FlexCAN modules
- Safety CAN features on 1 CAN module as implemented on MPC5604P

1.6.17 Dual-channel FlexRay controller

- Full implementation of FlexRay Protocol Specification 2.1
- Sixty-four configurable message buffers can be handled
- Message buffers configurable as Tx, Rx, or RxFIFO
- Message buffer size configurable
- Message filtering for all message buffers based on FrameID, cycle count, and message ID
- Programmable acceptance filters for RxFIFO message buffers
- Dual channel, each at up to 10 Mbit/s data rate

1.6.18 Periodic Interrupt Timer (PIT)

The PIT module implements the features below:

- Four general-purpose interrupt timers
- 32-bit counter resolution
- Clocked by system clock frequency
- 32-bit counter for real time interrupt, clocked from main external oscillator
- Can be used for software tick or DMA trigger operation

1.6.19 System Timer Module (STM)

The STM implements the features below:

- Replicated periphery to provide safety measures respective to high safety integrity levels (for example, SIL 3, ASIL D)
- Up-counter with four output compare registers
- OS task protection and hardware tick implementation as per current state-of-the-art AUTOSAR requirement

1.6.20 Motor control (MOTC) peripherals

The peripherals in this section can be used for general-purpose applications, but are specifically designed for motor control (MOTC) applications.

1.6.20.1 FlexPWM

The pulse width modulator module (FlexPWM) contains three PWM channels, each of which is configured to control a single half-bridge power stage. There may also be one or more fault channels.

This PWM is capable of controlling most motor types: AC induction motors (ACIM), permanent magnet AC motors (PMAC), both brushless (BLDC) and brush DC motors (BDC), switched (SRM) and variable reluctance motors (VRM), and stepper motors.

A FlexPWM module implements the following features:

- 16 bits of resolution for center, edge aligned, and asymmetrical PWMs
- Maximum operating frequency lower than or equal to platform frequency
- Clock source not modulated and independent from system clock (generated via auxiliary PLL)
- Fine granularity control for enhanced resolution of the PWM period

- PWM outputs can operate as complementary pairs or independent channels
- Ability to accept signed numbers for PWM generation
- Independent control of both edges of each PWM output
- Synchronization to external hardware or other PWM is supported
- Double-buffered PWM registers
 - Integral reload rates from 1 to 16
 - Half-cycle reload capability
- Multiple ADC trigger events can be generated per PWM cycle via hardware
- Fault inputs can be assigned to control multiple PWM outputs
- Programmable filters for fault inputs
- Independently programmable PWM output polarity
- Independent top and bottom deadtime insertion
- Each complementary pair can operate with its own PWM frequency and deadtime values
- Individual software control for each PWM output
- All outputs can be forced to a value simultaneously
- PWMX pin can optionally output a third signal from each channel
- Channels not used for PWM generation can be used for:
 - buffered output compare functions
 - input capture functions
- Enhanced dual-edge capture functionality
- Option to supply the source for each complementary PWM signal pair from any of the following:
 - External digital pin
 - Internal timer channel
 - External ADC input, taking into account values set in ADC high and low limit registers
- Supports safety measures using DMA

1.6.20.2 Cross Triggering Unit (CTU)

The CTU provides automatic generation of ADC conversion requests on user-selected conditions without CPU load during the PWM period and with minimized CPU load for dynamic configuration.

The CTU implements the following features:

- Cross triggering between ADC, FlexPWM, eTimer, and external pins
- Double-buffered trigger generation unit with as many as eight independent triggers generated from external triggers
- Maximum operating frequency lower than or equal to platform
- Trigger generation unit configurable in sequential mode or in triggered mode
- Trigger delay unit to compensate the delay of external low-pass filter
- Double-buffered global trigger unit allowing eTimer synchronization and/or ADC command generation
- Double-buffered ADC command list pointers to minimize ADC trigger unit update
- Double-buffered ADC conversion command list with as many as twenty-four ADC commands
- Each trigger has the capability to generate consecutive commands
- ADC conversion command allows controlling ADC channel from each ADC, single or synchronous sampling, independent result queue selection
- Supports safety measures using DMA

1.6.20.3 Analog-To-Digital Converter (ADC)

- Four independent ADCs with 12-bit A/D resolution
- Common mode conversion range of 0–5 V or 0–3.3 V
- Twenty-two single-ended input channels
- Supports eight FIFO queues with fixed priority
- Queue modes with priority-based preemption; initiated by software command, internal, or external triggers
- DMA and interrupt request support

1.6.20.4 eTimer module

Three 16-bit general purpose up/down timer/counters per module are implemented with the following features:

- Ability to operate up to platform frequency
- Individual channel capability
 - Input capture trigger
 - Output compare
 - Double buffer (to capture rising edge and falling edge)
 - Separate prescaler for each counter
 - Selectable clock source
 - 0–100% pulse measurement
 - Rotation direction flag (quad decoder mode)
- Maximum count rate
 - Equals peripheral clock/2 for external event counting
 - Equals peripheral clock for internal clock counting
- Cascadeable counters
- Programmable count modulo
- Quadrature decode capabilities
- Counters can share available input pins
- Count once or repeatedly
- Preloadable counters
- Pins available as GPIO when timer functionality is not in use
- DMA support

1.6.21 Redundancy Control and Checker Unit (RCCU)

The RCCU checks all outputs of the sphere of replication (addresses, data, control signals). It has the following features:

- Duplicated module to enable high diagnostic coverage (check of checker)
- Replicated IP to be used as checkers on the PBRIDGE output, Flash Controller output, SRAM output, DMA Channel Mux inputs

1.6.22 Software Watchdog Timer (SWT)

This module implements the features below:

- Replicated periphery to provide safety measures respective to high safety integrity levels (for example, SIL 3, ASIL D)
- Fault-tolerant output
- Safe internal RC oscillator as reference clock
- Windowed watchdog

- Program flow control monitor with 16-bit pseudorandom key generation
- Provides measures to target high safety integrity levels (for example, SIL 3, ASIL D)

1.6.23 Fault Collection and Control Unit (FCCU)

The FCCU module has the following features:

- Redundant collection of hardware checker results
- Redundant collection of error information and latch of faults from critical modules on the device
- Collection of test results
- Configurable and graded fault control
 - Internal reactions (no internal reaction, NMI, reset, or safe mode)
 - External reaction (failure is reported to the outside world via configurable output pins)

1.6.24 System Integration Unit Lite (SIUL)

The SIUL controls MCU reset configuration, pad configuration, external interrupt, general purpose I/O (GPIO), internal peripheral multiplexing, and the system reset operation. The reset configuration block contains the external pin boot configuration logic. The pad configuration block controls the static electrical characteristics of I/O pins. The GPIO block provides uniform and discrete input/output control of the I/O pins of the MCU.

The SIUL provides the following features:

- Centralized pad control on a per-pin basis
 - Pin function selection
 - Configurable weak pullup/pulldown
 - Configurable slew rate control (slow/medium/fast)
 - Hysteresis on GPIO pins
 - Configurable automatic safe mode pad control
- Input filtering for external interrupts

1.6.25 Cyclic Redundancy Checker (CRC) unit

The CRC module is a configurable multiple data flow unit to compute CRC signatures on data written to an input register.

The CRC unit has the following features:

- Three sets of registers to allow three concurrent contexts with possibly different CRC computations, each with a selectable polynomial and seed
- Computes 16- or 32-bit wide CRC on the fly (single-cycle computation) and stores the result in an internal register
- Implements the following standard CRC polynomials:
 - $x^{16} + x^{12} + x^5 + 1$ [16-bit CRC-CCITT]
 - $x^{32} + x^{26} + x^{23} + x^{22} + x^{16} + x^{12} + x^{11} + x^{10} + x^8 + x^7 + x^5 + x^4 + x^2 + x + 1$ [32-bit CRC-ethernet(32)]
- Key engine to be coupled with communication periphery where CRC application is added to support implementation of safe communication protocol
- Offloads the core from cycle-consuming CRC and helps in checking the configuration signature for safe start-up or periodic procedures
- Connected as a peripheral on the internal peripheral bus
- Provides DMA support

1.6.26 Non-Maskable Interrupt (NMI)

The non-maskable interrupt with de-glitching filter is available to support high priority core exceptions.

1.6.27 System Status and Configuration Module (SSCM)

The SSCM on the MPC5675K features the following:

- System configuration and status
- Debug port status and debug port enable
- Multiple boot code starting locations out of reset through implementation of search for valid reset configuration halfword
- Sets up the MMU to allow user boot code to execute as either Classic Power Architecture Book E code (default) or as NXP VLE code out of flash
- Supports serial bootloading of either Classic Power Architecture Book E code (default) or NXP VLE code
- Detection of user boot code
- Automatic switch to serial boot mode if internal flash is blank or invalid

1.6.28 Nexus Development Interface (NDI)

- Per IEEE-ISTO 5001-2008
- Real-time development support for Power Architecture core through Nexus class 3 (some class 4 support)
- Nexus support to snoop system SRAM traffic
- Data trace of FlexRay accesses
- Read and write access
- Configured via the IEEE 1149.1 (JTAG) port
- High bandwidth mode for fast message transmission
- Reduced bandwidth mode for reduced pin usage

1.6.29 IEEE 1149.1 JTAG Controller (JTAGC)

- IEEE 1149.1-2001 Test Access Port (TAP) interface
- JCOMP input that provides the ability to share the TAP —selectable modes of operation include JTAGC/debug or normal system operation
- 5-bit instruction register that supports IEEE 1149.1-2001 defined instructions
- 5-bit instruction register that supports additional public instructions
- Three test data registers:
 - Bypass register
 - Boundary scan register
 - Device identification register
- TAP controller state machine that controls the operation of the data registers, instruction register, and associated circuitry

2 Package pinouts and signal descriptions

2.1 Package pinouts

Figure 2 shows the MPC5675K in the 257 MAPBGA package. Figure 3, Figure 4, Figure 5, and Figure 6 show the MPC5675K in the 473 MAPBGA package.

| | | | | | | | | | | | | | | | | | | | | |
|---|-----------------|-----------------|----------------|----------------|----------------|----------------|------------------|------------------|----------------|------------|------------------|------------------|----------------|------------------|----------------|----------------|----------------|--------------|--------------|---|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | 16 | 17 | | | |
| A | VSS_HV_IO | VSS_HV_IO | VDD_HV_IO | nexus MDO[5] | nexus MDO[7] | nexus MDO[9] | flexray CB_TX | flexray CA_TR_EN | VDD_HV_IO | fec RXD[2] | fec RX_CLK | fec RXD[0] | fec MDIO | fec TX_EN | fec TXD[3] | VSS_HV_IO | VSS_HV_IO | A | | |
| B | VSS_HV_IO | VSS_HV_IO | mc_cgl clk_out | can1 TXD | nexus MDO [14] | dspi2 CS1 | flexray CB_TR_EN | flexray CA_TX | VSS_HV_IO | fec RXD[3] | fec RX_ER | fec RXD[1] | fec TX_ER | fec TX_CLK | can0 TXD | VDD_HV_IO | VSS_HV_IO | B | | |
| C | VDD_HV_IO | nexus MDO [15] | VSS_HV_IO | FCCU_F[1] | flexray CB_RX | etimer0 ETC[0] | etimer0 ETC[1] | etimer0 ETC[2] | etimer0 ETC[3] | JCOMP | fec CRS | fec TXD[0] | fec COL | can0 RXD | VSS_HV_PDI | pdi DATA [5] | pdi CLOCK | C | | |
| D | nexus MDO [2] | nexus MDO [3] | can1 RXD | dspi0 SOUT | RESERVED | etimer0 ETC[5] | etimer0 ETC[4] | VDD_HV_FL A | VSS_HV_FL A | fec TXD[2] | fec TXD[1] | fec RX_DV | fec MDC | VDD_HV_PDI | VSS_HV_IO | pdi DATA [0] | pdi DATA [1] | D | | |
| E | nexus MDO [0] | nexus MDO [1] | flexray CA_RX | NMI | | | | | | | | | | | | pdi LINE_V | pdi DATA [2] | pdi DATA [3] | pdi DATA [4] | E |
| F | nexus MDO[6] | nexus MDO [11] | dspi1 SOUT | dspi1 SIN | | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | | mc_cgl clk_out | pdi DATA [6] | pdi DATA [7] | pdi DATA [8] | F | | |
| G | nexus MDO [4] | VDD_HV_IO | dspi0 SCK | dspi1 SCK | | VDD_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VDD_LV_COR | | pdi DATA [9] | pdi DATA [10] | pdi DATA [11] | pdi FRAME_V | G | | |
| H | nexus MDO [10] | VSS_HV_IO | dspi0 CS0 | dspi1 CS0 | | VDD_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VDD_LV_COR | | pdi DATA [12] | pdi DATA [13] | VDD_HV_PDI | flexpwm 0 X[0] | H | | |
| J | nexus MCKO | nexus MDO[8] | dspi2 CS0 | dspi2 CS2 | | VDD_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VDD_LV_COR | | pdi DATA [14] | pdi DATA [15] | VSS_HV_PDI | flexpwm 0 X[1] | J | | |
| K | nexus MSEO_B[0] | nexus MSEO_B[1] | nexus RDY_B | dspi0 SIN | | VDD_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VDD_LV_COR | | flexpwm 0 X[2] | flexpwm 0 X[3] | flexpwm 0 A[1] | flexpwm 0 B[0] | K | | |
| L | nexus EVTO_B | nexus EVTI_B | dspi2 SCK | nexus MDO [13] | | VDD_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VDD_LV_COR | | VDD_HV_DRAM_VREF | TCK | flexpwm 0 B[1] | TDO | L | | |
| M | VDD_HV_OSC | VDD_HV_IO | dspi1 CS2 | nexus MDO [12] | | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | | flexpwm 0 B[2] | TDI | TMS | flexpwm 1 A[1] | M | | |
| N | XTALIN | VSS_HV_IO | dspi0 CS3 | VSS_LV_PLL | | | | | | | | | | flexpwm 0 B[3] | flexpwm 0 A[2] | flexpwm 1 A[0] | flexpwm 1 B[0] | N | | |
| P | VSS_HV_OSC | RESET | dspi0 CS2 | VDD_LV_PLL | etimer1 ETC[1] | etimer1 ETC[2] | adc0 AN[0] | etimer1 ETC[3] | VSS_HV_IO | VDD_HV_IO | adc0_adc1 AN[14] | etimer1 ETC[4] | etimer1 ETC[5] | VDD_HV_IO | flexpwm 0 A[3] | flexpwm 0 A[0] | flexpwm 1 B[1] | P | | |
| R | XTAL OUT | FCCU_F[0] | VSS_HV_IO | dspi1 CS3 | adc2 AN[0] | adc2 AN[3] | VDD_HV_ADR_13 | adc2_adc3 AN[14] | VDD_HV_ADR_02 | adc0 AN[2] | adc0_adc1 AN[13] | adc1 AN[1] | VREG_C TRL | lin0 TXD | VSS_HV_IO | flexpwm 1 A[2] | flexpwm 1 B[2] | R | | |
| T | VSS_HV_IO | VDD_HV_IO | dspi2 SOUT | adc3 AN[0] | adc3 AN[3] | adc2 AN[2] | VSS_HV_ADR_13 | adc2_adc3 AN[13] | VSS_HV_ADR_02 | adc0 AN[1] | adc0_adc1 AN[12] | adc1 AN[0] | adc1 AN[2] | lin0 RXD | etimer1 ETC[0] | VDD_HV_IO | VSS_HV_IO | T | | |
| U | VSS_HV_IO | VSS_HV_IO | dspi2 SIN | adc3 AN[1] | adc3 AN[2] | adc2 AN[1] | adc2_adc3 AN[11] | adc2_adc3 AN[12] | VDD_HV_ADV | VSS_HV_ADV | adc0_adc1 AN[11] | VREG_INT_EN ABLE | RESET_SUP | VDD_HV_PMU | VSS_HV_PMU | VSS_HV_IO | VSS_HV_IO | U | | |
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | 16 | 17 | | | |

Figure 2. MPC5675K 257 MAPBGA pinout (top view)

Package pinouts and signal descriptions

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 |
|---|---------------|---------------|-----------------|-----------------|---------------|----------------|------------------|------------------|----------------|------------|------------|------------|
| A | VSS_HV_IO | VSS_HV_IO | VDD_HV_IO | nexus MDO[5] | nexus MDO[7] | nexus MDO[9] | flexray CB_TX | flexray CA_TR_EN | fec RX_DV | fec MDIO | fec TX_CLK | fec TX_EN |
| B | VSS_HV_IO | VSS_HV_IO | mc_cgl clk_out | can1 TXD | nexus MDO[14] | dspl2 CS1 | flexray CB_TR_EN | flexray CA_TX | fec RXD[3] | fec RX_ER | fec TXD[0] | fec RXD[0] |
| C | VDD_HV_IO | nexus MDO[15] | VSS_HV_IO | FCCU_F[1] | flexray CB_RX | etimer0 ETC[4] | etimer0 ETC[1] | etimer0 ETC[2] | etimer0 ETC[3] | fec TXD[2] | fec TXD[1] | fec CRS |
| D | nexus MDO[1] | nexus MDO[3] | can1 RXD | dspl0 SOUT | RESERVED | etimer0 ETC[5] | etimer0 ETC[0] | VDD_HV_IO | VSS_HV_IO | JCOMP | VSS_HV_IO | VSS_HV_FL |
| E | nexus MDO[0] | nexus MDO[2] | flexray CA_RX | NMI | | | | | | | | |
| F | nexus MDO[10] | nexus MDO[11] | nexus MDO[6] | nexus MDO[4] | | | | | | | | |
| G | nexus MCKO | VDD_HV_IO | nexus MDO[8] | nexus MSEO_B[1] | | | | | | | | |
| H | nexus EVTO_B | VSS_HV_IO | nexus MSEO_B[0] | nexus EVTI_B | | | | | | | | |
| J | nexus RDY_B | nexus MDO[13] | nexus MDO[12] | dspl1 SIN | | | | | | | | |
| K | dspl0 SCK | dspl1 CS0 | dspl1 SCK | dspl1 SOUT | | | | | | | | |
| L | dspl0 CS0 | dspl2 CS2 | dspl2 CS0 | VSS_HV_IO | | | | | | | | |
| M | flexpwm0 X[0] | VDD_HV_IO | dspl0 SIN | VDD_HV_IO | | | | | | | | |
| | | | | | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR | VDD_LV_COR |
| | | | | | VDD_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR |
| | | | | | VDD_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR |
| | | | | | VDD_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR |
| | | | | | VDD_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR | VSS_LV_COR |

Figure 3. MPC5675K 473 MAPBGA pinout (northwest, viewed from above)

| | | | | | | | | | | | | |
|----|------------------|------------------|------------------|------------------|------------------|----------------|---------------------|---------------------|-------------------|-------------------|-------------------|------------------|
| N | flexpwm0 A[0] | VSS_ HV_IO | flexpwm0 X[1] | flexpwm0 B[2] | VDD_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | |
| P | flexpwm0 B[0] | flexpwm0 B[1] | flexpwm0 A[2] | flexpwm0 A[3] | VDD_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | |
| R | flexpwm0 X[2] | flexpwm0 X[3] | flexpwm0 A[1] | VSS_ HV_IO | VDD_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | |
| T | flexpwm0 B[3] | flexpwm1 A[0] | flexpwm1 A[1] | VDD_ HV_IO | VDD_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | |
| U | flexpwm1 B[0] | flexpwm1 B[1] | flexpwm1 A[2] | dspl2 SCK | VDD_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | |
| V | VDD_ HV_OSC | VDD_ HV_IO | flexpwm1 B[2] | dspl1 CS2 | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | |
| W | XTALIN | VSS_ HV_IO | dspl0 CS3 | VSS_ LV_PLL | | | | | | | | |
| Y | VSS_ HV_OSC | RESET | dspl0 CS2 | VDD_ LV_PLL | flexpwm1 X[0] | adc3 AN[0] | adc2_adc3 AN[11] | adc2_adc3 AN[14] | etimer1 ETC[1] | etimer1 ETC[2] | etimer1 ETC[3] | VSS_ HV_IO |
| AA | XTALOUT | FCCU_ F[0] | VSS_ HV_IO | dspl1 CS3 | flexpwm1 X[1] | adc3 AN[1] | adc2_adc3 AN[12] | adc2 AN[0] | VDD_ HV_ADV | VSS_ HV_ADV | adc0 AN[2] | adc0 AN[5] |
| AB | VSS_ HV_IO | VDD_ HV_IO | dspl2 SOUT | flexpwm1 X[2] | flexpwm1 X[3] | adc3 AN[2] | adc2_adc3 AN[13] | adc2 AN[1] | adc2 AN[2] | adc0 AN[0] | adc0 AN[4] | adc0 AN[6] |
| AC | VSS_ HV_IO | VSS_ HV_IO | dspl2 SIN | flexpwm1 A[3] | flexpwm1 B[3] | adc3 AN[3] | VDD_HV_ ADR_23 | VSS_HV_ ADR_23 | adc2 AN[3] | adc0 AN[1] | adc0 AN[3] | VDD_ HV_ADR_0 |
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 |

Figure 4. MPC5675K 473 MAPBGA pinout (southwest, viewed from above)

| | | | | | | | | | | | | |
|---|-----------------|----------------|----------------|----------------|----------------|-----------------|-----------------|-------------------|---------------------|-------------------|-----------------|--|
| | 13 | 14 | 15 | 16 | 17 | 18 | 19 | 20 | 21 | 22 | 23 | |
| A | fec TXD[3] | VDD_ HV_IO | pdi DATA[3] | pdi DATA[1] | pdi CLOCK | pdi DATA[7] | pdi DATA[10] | pdi DATA[13] | pdi DATA[15] | VSS_ HV_IO | VSS_ HV_IO | |
| B | fec TX_ER | VSS_ HV_IO | pdi DATA[6] | pdi DATA[4] | pdi DATA[0] | pdi LINE_V | pdi DATA[9] | pdi DATA[14] | can0 TXD | VDD_ HV_IO | VSS_ HV_IO | |
| C | fec RX_CLK | fec RXD[1] | fec COL | pdi DATA[5] | pdi DATA[2] | pdi DATA[8] | pdi DATA[12] | can0 RXD | VSS_ HV_PDI | siul GPIO[197] | dramc CAS | |
| D | VDD_ HV_FL_A | fec RXD[2] | fec MDC | VDD_ HV_PDI | VSS_ HV_PDI | pdi DATA[11] | pdi FRAME_V | VDD_ HV_PDI | dramc BA[1] | siul GPIO[195] | dramc BA[0] | |
| E | | | | | | | | mc_cgl clk_out | siul GPIO[149] | dramc CS0 | dramc BA[2] | |
| F | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | dramc RAS | siul GPIO[194] | siul GPIO[148] | dramc D[5] | |
| G | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | siul GPIO[196] | dramc DQS[0] | dramc DM[0] | dramc D[7] | |
| H | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VDD_ LV_COR | dramc D[2] | VDD_HV_ DRAM_VTT | VDD_HV_ DRAM | VSS_HV_ DRAM | |
| J | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VDD_ LV_COR | dramc D[0] | dramc D[1] | dramc D[3] | dramc D[6] | |
| K | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VDD_ LV_COR | VSS_ HV_IO | dramc D[4] | dramc D[8] | dramc D[9] | |
| L | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VDD_ LV_COR | VDD_ HV_IO | VDD_HV_ DRAM_VTT | VSS_HV_ DRAM | VDD_HV_ DRAM | |
| M | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VDD_ LV_COR | dramc ODT | dramc WEB | dramc D[11] | dramc D[10] | |

Figure 5. MPC5675K 473 MAPBGA pinout (northeast, viewed from above)

Package pinouts and signal descriptions

| | | | | | | | | | | | |
|------------------|---------------------|-------------------|-------------------|----------------|----------------|----------------|----------------------|---------------------|------------------|------------------|----|
| VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VDD_ LV_COR | | dramc DQS[1] | dramc DM[1] | dramc D[13] | dramc D[12] | N |
| VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VDD_ LV_COR | | dramc D[14] | dramc D[15] | VSS_HV_ DRAM | VDD_HV_ DRAM | P |
| VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VDD_ LV_COR | | VDD_HV_ DRAM_VREF | dramc ADD[3] | dramc CKE | dramc CLKB | R |
| VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VDD_ LV_COR | | dramc ADD[8] | dramc ADD[9] | dramc ADD[1] | dramc CLK | T |
| VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VSS_ LV_COR | VDD_ LV_COR | | dramc ADD[6] | dramc ADD[12] | VDD_HV_ DRAM | dramc ADD[0] | U |
| VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | VDD_ LV_COR | | lin0 TXD | dramc ADD[13] | VSS_HV_ DRAM | dramc ADD[2] | V |
| | | | | | | | lin0 RXD | dramc ADD[14] | dramc ADD[7] | dramc ADD[4] | W |
| VDD_ HV_IO | adc0_adc1 AN[11] | etimer1 ETC[5] | etimer1 ETC[4] | adc1 AN[8] | adc1 AN[6] | TCK | VDD_HV_IO | dramc ADD[15] | dramc ADD[11] | dramc ADD[5] | Y |
| adc0 AN[8] | adc0_adc1 AN[12] | adc1 AN[0] | adc1 AN[2] | adc1 AN[5] | adc1 AN[7] | TDI | etimer1 ETC[0] | VSS_HV_IO | lin1 TXD | dramc ADD[10] | AA |
| adc0 AN[7] | adc0_adc1 AN[13] | adc1 AN[1] | adc1 AN[3] | adc1 AN[4] | TDO | TMS | RESERVED | lin1 RXD | VDD_ HV_IO | VSS_ HV_IO | AB |
| VSS_ HV_ADR_0 | adc0_adc1 AN[14] | VDD_ HV_ADR_1 | VSS_ HV_ADR_1 | VDD_ HV_PMU | VREG_CTRL | VSS_ HV_PMU | RESET_ SUP | VREG_INT_ ENABLE | VSS_ HV_IO | VSS_ HV_IO | AC |
| 13 | 14 | 15 | 16 | 17 | 18 | 19 | 20 | 21 | 22 | 23 | |

Figure 6. MPC5675K 473 MAPBGA pinout (southeast, viewed from above)

2.2 Pin descriptions

The following sections provide signal descriptions and related information about the functionality and configuration for this device.

2.2.1 Pad types

Table 2 lists the pad types used on the MPC5675K.

Table 2. Pad types

| Pad Type | Description |
|-------------------|---|
| GP Slow | Slow buffer with CMOS Schmitt trigger and pullup/pulldown. |
| GP Slow/Fast | Programmable slow/fast buffer with CMOS Schmitt trigger, pullup/pulldown. |
| GP Slow/Medium | Programmable slow/medium buffer with CMOS Schmitt trigger, pullup/pulldown. Programmable slow/medium buffer with CMOS Schmitt trigger, pullup/pulldown and Injection proof analog switch. |
| GP Slow/Symmetric | Programmable slow/symmetric buffer with CMOS Schmitt trigger, pullup/pulldown. |
| PDI Medium | Medium slew-rate output with four selectable slew rates. Contains an input buffer and weak pullup/pulldown. |
| PDI Fast | Fast slew-rate output with four selectable slew rates. Contains an input buffer and weak pullup/pulldown. |

Table 2. Pad types (continued)

| Pad Type | Description |
|---------------|--|
| DRAM ACC | Bidirectional DDR pad. Can be configured to support LPDDR half strength, LPDDR full strength, DDR1, DDR2 half strength, DDR2 full strength, and SDR. |
| DRAM CLK | Differential clock driver. |
| DRAM DQ | Bidirectional DDR pad with integrated ODT. Can be configured to support LPDDR half strength, LPDDR full strength, DDR1, DDR2 half strength, DDR2 full strength, and SDR. |
| DRAM ODT CTL | Enable On Die Termination control. |
| Analog | CMOS Schmitt trigger cell with injection proof analog switch. |
| Analog Shared | CMOS Schmitt trigger cell with two injection-proof analog switches. |

2.2.2 Power supply and reference voltage pins

Table 3 shows the supply pins for the MPC5675K in the 257 MAPBGA package. Table 5 shows the supply pins for the MPC5675K in the 473 MAPBGA package.

Table 4 and Table 6 show the pins not populated on the MPC5675K 257 MAPBGA and 473 MAPBGA packages, respectively.

Table 3. 257 MAPBGA supply pins

| Ball number | Ball name | Pad type | Ball number | Ball name | Pad type |
|-----------------------|------------------|----------|-------------|------------|----------|
| V_{DD} | | | | | |
| A3 | VDD_HV_IO | VDD_HV | F9 | VDD_LV_COR | VDD_LV |
| A9 | VDD_HV_IO | VDD_HV | F10 | VDD_LV_COR | VDD_LV |
| B16 | VDD_HV_IO | VDD_HV | F11 | VDD_LV_COR | VDD_LV |
| C1 | VDD_HV_IO | VDD_HV | F12 | VDD_LV_COR | VDD_LV |
| G2 | VDD_HV_IO | VDD_HV | G6 | VDD_LV_COR | VDD_LV |
| M2 | VDD_HV_IO | VDD_HV | G12 | VDD_LV_COR | VDD_LV |
| P10 | VDD_HV_IO | VDD_HV | H6 | VDD_LV_COR | VDD_LV |
| P14 | VDD_HV_IO | VDD_HV | H12 | VDD_LV_COR | VDD_LV |
| T2 | VDD_HV_IO | VDD_HV | J6 | VDD_LV_COR | VDD_LV |
| T16 | VDD_HV_IO | VDD_HV | J12 | VDD_LV_COR | VDD_LV |
| L14 | VDD_HV_DRAM_VREF | VDD_HV | K6 | VDD_LV_COR | VDD_LV |
| D8 | VDD_HV_FLTA | VDD_HV | K12 | VDD_LV_COR | VDD_LV |
| M1 | VDD_HV_OSC | VDD_HV | L6 | VDD_LV_COR | VDD_LV |
| D14 | VDD_HV_PDI | VDD_HV | L12 | VDD_LV_COR | VDD_LV |
| H16 | VDD_HV_PDI | VDD_HV | M6 | VDD_LV_COR | VDD_LV |
| U14 | VDD_HV_PMU | VDD_HV | M7 | VDD_LV_COR | VDD_LV |
| R7 | VDD_HV_ADR_13 | VDD_HV_A | M8 | VDD_LV_COR | VDD_LV |

Table 3. 257 MAPBGA supply pins (continued)

| Ball number | Ball name | Pad type | Ball number | Ball name | Pad type |
|-----------------------|---------------|----------|-------------|------------|----------|
| R9 | VDD_HV_ADR_02 | VDD_HV_A | M9 | VDD_LV_COR | VDD_LV |
| U9 | VDD_HV_ADV | VDD_HV_A | M10 | VDD_LV_COR | VDD_LV |
| F6 | VDD_LV_COR | VDD_LV | M11 | VDD_LV_COR | VDD_LV |
| F7 | VDD_LV_COR | VDD_LV | M12 | VDD_LV_COR | VDD_LV |
| F8 | VDD_LV_COR | VDD_LV | P4 | VDD_LV_PLL | VDD_LV |
| V_{SS} | | | | | |
| A1 | VSS_HV_IO | VSS_HV | G7 | VSS_LV_COR | VSS_LV |
| A2 | VSS_HV_IO | VSS_HV | G8 | VSS_LV_COR | VSS_LV |
| A16 | VSS_HV_IO | VSS_HV | G9 | VSS_LV_COR | VSS_LV |
| A17 | VSS_HV_IO | VSS_HV | G10 | VSS_LV_COR | VSS_LV |
| B1 | VSS_HV_IO | VSS_HV | G11 | VSS_LV_COR | VSS_LV |
| B2 | VSS_HV_IO | VSS_HV | H7 | VSS_LV_COR | VSS_LV |
| B9 | VSS_HV_IO | VSS_HV | H8 | VSS_LV_COR | VSS_LV |
| B17 | VSS_HV_IO | VSS_HV | H9 | VSS_LV_COR | VSS_LV |
| C3 | VSS_HV_IO | VSS_HV | H10 | VSS_LV_COR | VSS_LV |
| D15 | VSS_HV_IO | VSS_HV | H11 | VSS_LV_COR | VSS_LV |
| H2 | VSS_HV_IO | VSS_HV | J7 | VSS_LV_COR | VSS_LV |
| N2 | VSS_HV_IO | VSS_HV | J8 | VSS_LV_COR | VSS_LV |
| P9 | VSS_HV_IO | VSS_HV | J9 | VSS_LV_COR | VSS_LV |
| R3 | VSS_HV_IO | VSS_HV | J10 | VSS_LV_COR | VSS_LV |
| R15 | VSS_HV_IO | VSS_HV | J11 | VSS_LV_COR | VSS_LV |
| T1 | VSS_HV_IO | VSS_HV | K7 | VSS_LV_COR | VSS_LV |
| T17 | VSS_HV_IO | VSS_HV | K8 | VSS_LV_COR | VSS_LV |
| U1 | VSS_HV_IO | VSS_HV | K9 | VSS_LV_COR | VSS_LV |
| U2 | VSS_HV_IO | VSS_HV | K10 | VSS_LV_COR | VSS_LV |
| U16 | VSS_HV_IO | VSS_HV | K11 | VSS_LV_COR | VSS_LV |
| U17 | VSS_HV_IO | VSS_HV | L7 | VSS_LV_COR | VSS_LV |
| D9 | VSS_HV_FL A | VSS_HV | L8 | VSS_LV_COR | VSS_LV |
| P1 | VSS_HV_OSC | VSS_HV | L9 | VSS_LV_COR | VSS_LV |
| C15 | VSS_HV_PDI | VSS_HV | L10 | VSS_LV_COR | VSS_LV |
| J16 | VSS_HV_PDI | VSS_HV | L11 | VSS_LV_COR | VSS_LV |
| T9 | VSS_HV_ADR_02 | VSS_HV_A | N4 | VSS_LV_PLL | VSS_LV |
| T7 | VSS_HV_ADR_13 | VSS_HV_A | U15 | VSS_HV_PMU | VSS_LV |
| U10 | VSS_HV_ADV | VSS_HV_A | | | |

Table 4. 257 MAPBGA pins not populated on package

| | | | | | | | |
|-----|----|-----|----|-----|-----|-----|-----|
| E5 | E6 | E7 | E8 | E9 | E10 | E11 | E12 |
| E13 | F5 | F13 | G5 | G13 | H5 | H13 | J5 |
| J13 | K5 | K13 | L5 | L13 | M5 | M13 | N5 |
| N6 | N7 | N8 | N9 | N10 | N11 | N12 | N13 |

Table 5. 473 MAPBGA supply pins

| Ball number | Ball name | Pad type | Ball number | Ball name | Pad type |
|-----------------------|------------------|----------|-------------|------------|----------|
| V_{DD} | | | | | |
| A3 | VDD_HV_IO | VDD_HV | F15 | VDD_LV_COR | VDD_LV |
| A14 | VDD_HV_IO | VDD_HV | F16 | VDD_LV_COR | VDD_LV |
| B22 | VDD_HV_IO | VDD_HV | F17 | VDD_LV_COR | VDD_LV |
| C1 | VDD_HV_IO | VDD_HV | F18 | VDD_LV_COR | VDD_LV |
| D8 | VDD_HV_IO | VDD_HV | G6 | VDD_LV_COR | VDD_LV |
| G2 | VDD_HV_IO | VDD_HV | G18 | VDD_LV_COR | VDD_LV |
| L20 | VDD_HV_IO | VDD_HV | H6 | VDD_LV_COR | VDD_LV |
| M2 | VDD_HV_IO | VDD_HV | H18 | VDD_LV_COR | VDD_LV |
| M4 | VDD_HV_IO | VDD_HV | J6 | VDD_LV_COR | VDD_LV |
| T4 | VDD_HV_IO | VDD_HV | J18 | VDD_LV_COR | VDD_LV |
| V2 | VDD_HV_IO | VDD_HV | K6 | VDD_LV_COR | VDD_LV |
| Y13 | VDD_HV_IO | VDD_HV | K18 | VDD_LV_COR | VDD_LV |
| Y20 | VDD_HV_IO | VDD_HV | L6 | VDD_LV_COR | VDD_LV |
| AB2 | VDD_HV_IO | VDD_HV | L18 | VDD_LV_COR | VDD_LV |
| AB22 | VDD_HV_IO | VDD_HV | M6 | VDD_LV_COR | VDD_LV |
| AC12 | VDD_HV_ADR_0 | VDD_HV_A | M18 | VDD_LV_COR | VDD_LV |
| AC15 | VDD_HV_ADR_1 | VDD_HV_A | N6 | VDD_LV_COR | VDD_LV |
| AC7 | VDD_HV_ADR_23 | VDD_HV_A | N18 | VDD_LV_COR | VDD_LV |
| AA9 | VDD_HV_ADV | VDD_HV_A | P6 | VDD_LV_COR | VDD_LV |
| H22 | VDD_HV_DRAM | VDD_HV | P18 | VDD_LV_COR | VDD_LV |
| L23 | VDD_HV_DRAM | VDD_HV | R6 | VDD_LV_COR | VDD_LV |
| P23 | VDD_HV_DRAM | VDD_HV | R18 | VDD_LV_COR | VDD_LV |
| U22 | VDD_HV_DRAM | VDD_HV | T6 | VDD_LV_COR | VDD_LV |
| R20 | VDD_HV_DRAM_VREF | VDD_HV | T18 | VDD_LV_COR | VDD_LV |
| H21 | VDD_HV_DRAM_VTT | VDD_HV | U6 | VDD_LV_COR | VDD_LV |
| L21 | VDD_HV_DRAM_VTT | VDD_HV | U18 | VDD_LV_COR | VDD_LV |

Table 5. 473 MAPBGA supply pins (continued)

| Ball number | Ball name | Pad type | Ball number | Ball name | Pad type |
|-----------------------|-------------|----------|-------------|------------|----------|
| D13 | VDD_HV_FL A | VDD_HV | V6 | VDD_LV_COR | VDD_LV |
| V1 | VDD_HV_OSC | VDD_HV | V7 | VDD_LV_COR | VDD_LV |
| D16 | VDD_HV_PDI | VDD_HV | V8 | VDD_LV_COR | VDD_LV |
| D20 | VDD_HV_PDI | VDD_HV | V9 | VDD_LV_COR | VDD_LV |
| AC17 | VDD_HV_PMU | VDD_HV | V10 | VDD_LV_COR | VDD_LV |
| F6 | VDD_LV_COR | VDD_LV | V11 | VDD_LV_COR | VDD_LV |
| F7 | VDD_LV_COR | VDD_LV | V12 | VDD_LV_COR | VDD_LV |
| F8 | VDD_LV_COR | VDD_LV | V13 | VDD_LV_COR | VDD_LV |
| F9 | VDD_LV_COR | VDD_LV | V14 | VDD_LV_COR | VDD_LV |
| F10 | VDD_LV_COR | VDD_LV | V15 | VDD_LV_COR | VDD_LV |
| F11 | VDD_LV_COR | VDD_LV | V16 | VDD_LV_COR | VDD_LV |
| F12 | VDD_LV_COR | VDD_LV | V17 | VDD_LV_COR | VDD_LV |
| F13 | VDD_LV_COR | VDD_LV | V18 | VDD_LV_COR | VDD_LV |
| F14 | VDD_LV_COR | VDD_LV | Y4 | VDD_LV_PLL | VDD_LV |
| V_{SS} | | | | | |
| A2 | VSS_HV_IO | VSS_HV | L7 | VSS_LV_COR | VSS_LV |
| A22 | VSS_HV_IO | VSS_HV | L8 | VSS_LV_COR | VSS_LV |
| A23 | VSS_HV_IO | VSS_HV | L9 | VSS_LV_COR | VSS_LV |
| B1 | VSS_HV_IO | VSS_HV | L10 | VSS_LV_COR | VSS_LV |
| B2 | VSS_HV_IO | VSS_HV | L11 | VSS_LV_COR | VSS_LV |
| B14 | VSS_HV_IO | VSS_HV | L12 | VSS_LV_COR | VSS_LV |
| B23 | VSS_HV_IO | VSS_HV | L13 | VSS_LV_COR | VSS_LV |
| C3 | VSS_HV_IO | VSS_HV | L14 | VSS_LV_COR | VSS_LV |
| D9 | VSS_HV_IO | VSS_HV | L15 | VSS_LV_COR | VSS_LV |
| D11 | VSS_HV_IO | VSS_HV | L16 | VSS_LV_COR | VSS_LV |
| H2 | VSS_HV_IO | VSS_HV | L17 | VSS_LV_COR | VSS_LV |
| K20 | VSS_HV_IO | VSS_HV | M7 | VSS_LV_COR | VSS_LV |
| L4 | VSS_HV_IO | VSS_HV | M8 | VSS_LV_COR | VSS_LV |
| N2 | VSS_HV_IO | VSS_HV | M9 | VSS_LV_COR | VSS_LV |
| A1 | VSS_HV_IO | VSS_HV | M10 | VSS_LV_COR | VSS_LV |
| R4 | VSS_HV_IO | VSS_HV | M11 | VSS_LV_COR | VSS_LV |
| W2 | VSS_HV_IO | VSS_HV | M12 | VSS_LV_COR | VSS_LV |
| Y12 | VSS_HV_IO | VSS_HV | M13 | VSS_LV_COR | VSS_LV |
| AA3 | VSS_HV_IO | VSS_HV | M14 | VSS_LV_COR | VSS_LV |

Table 5. 473 MAPBGA supply pins (continued)

| Ball number | Ball name | Pad type | Ball number | Ball name | Pad type |
|-------------|---------------|----------|-------------|------------|----------|
| AA21 | VSS_HV_IO | VSS_HV | M15 | VSS_LV_COR | VSS_LV |
| AB1 | VSS_HV_IO | VSS_HV | M16 | VSS_LV_COR | VSS_LV |
| AB23 | VSS_HV_IO | VSS_HV | M17 | VSS_LV_COR | VSS_LV |
| AC1 | VSS_HV_IO | VSS_HV | N7 | VSS_LV_COR | VSS_LV |
| AC2 | VSS_HV_IO | VSS_HV | N8 | VSS_LV_COR | VSS_LV |
| AC22 | VSS_HV_IO | VSS_HV | N9 | VSS_LV_COR | VSS_LV |
| AC23 | VSS_HV_IO | VSS_HV | N10 | VSS_LV_COR | VSS_LV |
| AC13 | VSS_HV_ADR_0 | VSS_HV_A | N11 | VSS_LV_COR | VSS_LV |
| AC16 | VSS_HV_ADR_1 | VSS_HV_A | N12 | VSS_LV_COR | VSS_LV |
| AC8 | VSS_HV_ADR_23 | VSS_HV_A | N13 | VSS_LV_COR | VSS_LV |
| AA10 | VSS_HV_ADV | VSS_HV_A | N14 | VSS_LV_COR | VSS_LV |
| H23 | VSS_HV_DRAM | VSS_HV | N15 | VSS_LV_COR | VSS_LV |
| L22 | VSS_HV_DRAM | VSS_HV | N16 | VSS_LV_COR | VSS_LV |
| P22 | VSS_HV_DRAM | VSS_HV | N17 | VSS_LV_COR | VSS_LV |
| V22 | VSS_HV_DRAM | VSS_HV | P7 | VSS_LV_COR | VSS_LV |
| D12 | VSS_HV_FLA | VSS_HV | P8 | VSS_LV_COR | VSS_LV |
| Y1 | VSS_HV_OSC | VSS_HV | P9 | VSS_LV_COR | VSS_LV |
| C21 | VSS_HV_PDI | VSS_HV | P10 | VSS_LV_COR | VSS_LV |
| D17 | VSS_HV_PDI | VSS_HV | P11 | VSS_LV_COR | VSS_LV |
| G7 | VSS_LV_COR | VSS_LV | P12 | VSS_LV_COR | VSS_LV |
| G8 | VSS_LV_COR | VSS_LV | P13 | VSS_LV_COR | VSS_LV |
| G9 | VSS_LV_COR | VSS_LV | P14 | VSS_LV_COR | VSS_LV |
| G10 | VSS_LV_COR | VSS_LV | P15 | VSS_LV_COR | VSS_LV |
| G11 | VSS_LV_COR | VSS_LV | P16 | VSS_LV_COR | VSS_LV |
| G12 | VSS_LV_COR | VSS_LV | P17 | VSS_LV_COR | VSS_LV |
| G13 | VSS_LV_COR | VSS_LV | R7 | VSS_LV_COR | VSS_LV |
| G14 | VSS_LV_COR | VSS_LV | R8 | VSS_LV_COR | VSS_LV |
| G15 | VSS_LV_COR | VSS_LV | R9 | VSS_LV_COR | VSS_LV |
| G16 | VSS_LV_COR | VSS_LV | R10 | VSS_LV_COR | VSS_LV |
| G17 | VSS_LV_COR | VSS_LV | R11 | VSS_LV_COR | VSS_LV |
| H7 | VSS_LV_COR | VSS_LV | R12 | VSS_LV_COR | VSS_LV |
| H8 | VSS_LV_COR | VSS_LV | R13 | VSS_LV_COR | VSS_LV |
| H9 | VSS_LV_COR | VSS_LV | R14 | VSS_LV_COR | VSS_LV |
| H10 | VSS_LV_COR | VSS_LV | R15 | VSS_LV_COR | VSS_LV |

Table 5. 473 MAPBGA supply pins (continued)

| Ball number | Ball name | Pad type | Ball number | Ball name | Pad type |
|-------------|------------|----------|-------------|------------|----------|
| H11 | VSS_LV_COR | VSS_LV | R16 | VSS_LV_COR | VSS_LV |
| H12 | VSS_LV_COR | VSS_LV | R17 | VSS_LV_COR | VSS_LV |
| H13 | VSS_LV_COR | VSS_LV | T7 | VSS_LV_COR | VSS_LV |
| H14 | VSS_LV_COR | VSS_LV | T8 | VSS_LV_COR | VSS_LV |
| H15 | VSS_LV_COR | VSS_LV | T9 | VSS_LV_COR | VSS_LV |
| H16 | VSS_LV_COR | VSS_LV | T10 | VSS_LV_COR | VSS_LV |
| H17 | VSS_LV_COR | VSS_LV | T11 | VSS_LV_COR | VSS_LV |
| J7 | VSS_LV_COR | VSS_LV | T12 | VSS_LV_COR | VSS_LV |
| J8 | VSS_LV_COR | VSS_LV | T13 | VSS_LV_COR | VSS_LV |
| J9 | VSS_LV_COR | VSS_LV | T14 | VSS_LV_COR | VSS_LV |
| J10 | VSS_LV_COR | VSS_LV | T15 | VSS_LV_COR | VSS_LV |
| J11 | VSS_LV_COR | VSS_LV | T16 | VSS_LV_COR | VSS_LV |
| J12 | VSS_LV_COR | VSS_LV | T17 | VSS_LV_COR | VSS_LV |
| J13 | VSS_LV_COR | VSS_LV | U7 | VSS_LV_COR | VSS_LV |
| J14 | VSS_LV_COR | VSS_LV | U8 | VSS_LV_COR | VSS_LV |
| J15 | VSS_LV_COR | VSS_LV | U9 | VSS_LV_COR | VSS_LV |
| J16 | VSS_LV_COR | VSS_LV | U10 | VSS_LV_COR | VSS_LV |
| J17 | VSS_LV_COR | VSS_LV | U11 | VSS_LV_COR | VSS_LV |
| K7 | VSS_LV_COR | VSS_LV | U12 | VSS_LV_COR | VSS_LV |
| K8 | VSS_LV_COR | VSS_LV | U13 | VSS_LV_COR | VSS_LV |
| K9 | VSS_LV_COR | VSS_LV | U14 | VSS_LV_COR | VSS_LV |
| K10 | VSS_LV_COR | VSS_LV | U15 | VSS_LV_COR | VSS_LV |
| K11 | VSS_LV_COR | VSS_LV | U16 | VSS_LV_COR | VSS_LV |
| K12 | VSS_LV_COR | VSS_LV | U17 | VSS_LV_COR | VSS_LV |
| K13 | VSS_LV_COR | VSS_LV | W4 | VSS_LV_PLL | VSS_LV |
| K14 | VSS_LV_COR | VSS_LV | AC19 | VSS_HV_PMU | VSS_LV |
| K15 | VSS_LV_COR | VSS_LV | D5 | RESERVED | VSS_HV |
| K16 | VSS_LV_COR | VSS_LV | AB20 | RESERVED | VSS_HV |
| K17 | VSS_LV_COR | VSS_LV | | | |

Table 6. 473 MAPBGA pins not populated on package

| | | | | | | | |
|-----|-----|-----|-----|-----|-----|-----|-----|
| E5 | E6 | E7 | E8 | E9 | E10 | E11 | E12 |
| E13 | E14 | E15 | E16 | E17 | E18 | E19 | F5 |
| F19 | G5 | G19 | H5 | H19 | J5 | J19 | K5 |
| K19 | L5 | L19 | M5 | M19 | N5 | N19 | P5 |
| P19 | R5 | R19 | T5 | T19 | U5 | U19 | V5 |
| V19 | W5 | W6 | W7 | W8 | W9 | W10 | W11 |
| W12 | W13 | W14 | W15 | W16 | W17 | W18 | W19 |

2.2.3 System pins

Table 7 shows the system pins for the MPC5675K in the 257 MAPBGA package. Table 8 shows the system pins for the MPC5675K in the 473 MAPBGA package.

Table 7. 257 MAPBGA system pins

| Ball number | Ball name | Weak pull during reset | Safe mode default condition | Pad type | Power domain |
|-------------|--------------------------------|------------------------|-----------------------------|--------------------|--------------|
| C4 | FCCU_F[1] | disabled | not available | GP Slow/Medium | VDD_HV_IO |
| C10 | JCOMP | pulldown | not available | GP Slow | VDD_HV_IO |
| E1 | Nexus MDO[0] ¹ | — | not available | GP Slow/Fast | VDD_HV_IO |
| E4 | NMI | pullup | not available | GP Slow | VDD_HV_IO |
| L15 | TCK ² | pullup | not available | GP Slow | VDD_HV_IO |
| M16 | TMS | pullup | not available | GP Slow | VDD_HV_IO |
| N1 | XTALIN | — | not available | Analog Feedthrough | VDD_HV_IO |
| P2 | $\overline{\text{RESET}}$ | pulldown | not available | Reset | VDD_HV_IO |
| R1 | XTALOUT | — | not available | Analog Feedthrough | VDD_HV_IO |
| R2 | FCCU_F[0] | disabled | not available | GP Slow/Medium | VDD_HV_IO |
| R13 | VREG_CTRL | — | — | Analog Feedthrough | VDD_REG |
| U12 | VREG_INT_ENABLE | — | — | Analog Feedthrough | VDD_HV_IO |
| U13 | $\overline{\text{RESET_SUP}}$ | pulldown | — | Analog Feedthrough | VDD_HV_IO |

¹ Do not connect pin directly to a power supply or ground.

² If LBIST is enabled, an external pull between 1K and 100K ohm must be connected from TCK to either power or ground to avoid LBIST failures.

Table 8. 473 MAPBGA system pins

| Ball number | Ball name | Weak pull during reset | Safe mode default condition | Pad type | Power domain |
|-------------|-----------|------------------------|-----------------------------|----------------|--------------|
| C4 | FCCU_F[1] | disabled | not available | GP Slow/Medium | VDD_HV_IO |

Table 8. 473 MAPBGA system pins (continued)

| Ball number | Ball name | Weak pull during reset | Safe mode default condition | Pad type | Power domain |
|------------------|--------------------------------|------------------------|-----------------------------|--------------------|--------------|
| D10 | JCOMP | pulldown | not available | GP Slow | VDD_HV_IO |
| E1 | Nexus MDO[0] ¹ | — | not available | GP Slow/Fast | VDD_HV_IO |
| E4 | NMI | pullup | not available | GP Slow | VDD_HV_IO |
| R23 ² | dramc CLKB | — | — | DRAM CLK | VDD_HV_DRAM |
| T23 ² | dramc CLK | disabled | — | DRAM CLK | VDD_HV_DRAM |
| W1 | XTALIN | — | not available | Analog Feedthrough | VDD_HV_IO |
| Y2 | $\overline{\text{RESET}}$ | pulldown | not available | Reset | VDD_HV_IO |
| Y19 | TCK ³ | pullup | not available | GP Slow | VDD_HV_IO |
| AA1 | XTALOUT | — | not available | Analog Feedthrough | VDD_HV_IO |
| AA2 | FCCU_F[0] | disabled | not available | GP Slow/Medium | VDD_HV_IO |
| AB19 | TMS | pullup | not available | GP Slow | VDD_HV_IO |
| AC18 | VREG_CTRL | — | — | Analog Feedthrough | VDD_REG |
| AC20 | $\overline{\text{RESET_SUP}}$ | pulldown | — | Analog Feedthrough | VDD_HV_IO |
| AC21 | VREG_INT_ENABLE | — | — | Analog Feedthrough | VDD_HV_IO |

¹ Do not connect pin directly to a power supply or ground.

² PCR234 can be used to control the slew rate of DRAM CLK and DRAM CLKB. See the “System Integration Unit Lite” chapter of the MPC5675K reference manual.

³ If LBIST is enabled, an external pull between 1K and 100K ohm must be connected from TCK to either power or ground to avoid LBIST failures.

2.2.4 Multiplexed pins

Table 9 shows the pin multiplexing for the MPC5675K in the 257 MAPBGA package. Table 10 shows the pin multiplexing for the 473 MAPBGA package.

Table 9. 257 MAPBGA pin multiplexing

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------------------|---|--|---------------|------------------------|-----------|
| A4 | GPIO | nexus MDO[5] ¹ | A0: siul_GPIO[114] A1: _ A2: npc_wrapper_MDO[5] A3: _ | I: _ I: _ I: _ | — | disabled | GF |
| A5 | GPIO | nexus MDO[7] ¹ | A0: siul_GPIO[112] A1: _ A2: npc_wrapper_MDO[7] A3: _ | I: _ I: _ I: _ | — | disabled | GF |
| A6 | GPIO | nexus MDO[9] ¹ | A0: siul_GPIO[110] A1: _ A2: npc_wrapper_MDO[9] A3: _ | I: _ I: _ I: _ | — | disabled | GF |
| A7 | GPIO | flexray CB_TX | A0: siul_GPIO[51] A1: flexray_CB_TX A2: _ A3: _ | I: _ I: _ I: _ | — | disabled | GF Syn |
| A8 | GPIO | flexray CA_TR_EN | A0: siul_GPIO[47] A1: flexray_CA_TR_EN A2: _ A3: _ | I: ctu0_EXT_IN I: flexpwm0_EXT_SYNC I: _ | — | disabled | GF Syn |
| A10 | GPIO | fec RXD[2] | A0: siul_GPIO[213] A1: _ A2: _ A3: dspI2_SOUT | I: fec_RXD[2] I: _ I: siul_EIRQ[21] | — | disabled | GF M |
| A11 | GPIO | fec RX_CLK | A0: siul_GPIO[209] A1: flexray_DBG2 A2: etimer2_ETC[2] A3: dspI0_CS6 | I: fec_RX_CLK I: _ I: siul_EIRQ[25] | — | disabled | GF M |
| A12 | GPIO | fec RXD[0] | A0: siul_GPIO[211] A1: i2c1_clock A2: _ A3: _ | I: fec_RXD[0] I: _ I: siul_EIRQ[27] | — | disabled | GF M |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|----------------------------|--|--|---------------|------------------------|-----------|
| A13 | GPIO | fec MDIO | A0: siul_GPIO[198] A1: fec_MDIO A2: _ A3: dsp2_CS0 | l: _ l: _ l: siul_EIRQ[28] | — | disabled | GF M |
| A14 | GPIO | fec TX_EN | A0: siul_GPIO[200] A1: fec_TX_EN A2: _ A3: lin0_TXD | l: _ l: _ l: _ | — | disabled | GF M |
| A15 | GPIO | fec TXD[3] | A0: siul_GPIO[204] A1: fec_TXD[3] A2: _ A3: dsp2_CS2 | l: flexpwm1_FAULT[2] l: _ l: siul_EIRQ[29] | — | disabled | GF M |
| B3 | GPIO | mc_cgl clk_out | A0: siul_GPIO[22] A1: mc_cgl_clk_out A2: etimer2_ETC[5] A3: _ | l: _ l: _ l: siul_EIRQ[18] | — | disabled | GF |
| B4 | GPIO | can1 TXD | A0: siul_GPIO[14] A1: can1_TXD A2: _ A3: _ | l: _ l: _ l: siul_EIRQ[13] | — | disabled | GF M |
| B5 | GPIO | nexus MDO[14] ¹ | A0: siul_GPIO[219] A1: _ A2: npc_wrapper_MDO[14] A3: can3_TXD | l: _ l: _ l: _ | — | disabled | GF |
| B6 | GPIO | ds2 CS1 | A0: siul_GPIO[9] A1: ds2_CS1 A2: _ A3: _ | l: flexpwm0_FAULT[0] l: lin3_RXD l: can2_RXD | — | disabled | GF M |
| B7 | GPIO | flexray CB_TR_EN | A0: siul_GPIO[52] A1: flexray_CB_TR_EN A2: _ A3: _ | l: _ l: _ l: _ | — | disabled | GF Syn |
| B8 | GPIO | flexray CA_TX | A0: siul_GPIO[48] A1: flexray_CA_TX A2: _ A3: _ | l: ctu1_EXT_IN l: _ l: _ | — | disabled | GF Syn |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------------------|---|---|---------------|------------------------|---------|
| B10 | GPIO | fec RXD[3] | A0: siul_GPIO[214] A1: i2c1_data A2: _ A3: _ | I: fec_RXD[3] I: _ I: _ | — | disabled | GF M |
| B11 | GPIO | fec RX_ER | A0: siul_GPIO[215] A1: _ A2: _ A3: dspio_CS1 | I: fec_RX_ER I: _ I: _ | — | disabled | GF M |
| B12 | GPIO | fec RXD[1] | A0: siul_GPIO[212] A1: dspio_CS1 A2: etimer2_ETC[5] A3: _ | I: fec_RXD[1] I: _ I: _ | — | disabled | GF M |
| B13 | GPIO | fec TX_ER | A0: siul_GPIO[205] A1: fec_TX_ER A2: dspio_CS3 A3: _ | I: flexpwm1_FAULT[3] I: lin0_RXD I: _ | — | disabled | GF M |
| B14 | GPIO | fec TX_CLK | A0: siul_GPIO[207] A1: flexray_DBG0 A2: etimer2_ETC[4] A3: dspio_CS4 | I: fec_TX_CLK I: _ I: _ | — | disabled | GF M |
| B15 | GPIO | can0 TXD | A0: siul_GPIO[16] A1: can0_TXD A2: _ A3: sscm_DEBUG[0] | I: _ I: _ I: siul_EIRQ[15] | — | disabled | GF M |
| C2 | GPIO | nexus MDO[15] ¹ | A0: siul_GPIO[220] A1: _ A2: npc_wrapper_MDO[15] A3: _ | I: can3_RXD I: can2_RXD I: _ | — | disabled | GF |
| C5 | GPIO | flexray CB_RX | A0: siul_GPIO[50] A1: _ A2: ctu1_EXT_TGR A3: _ | I: flexray_CB_RX I: _ I: _ | — | disabled | GF M |
| C6 | GPIO | etimer0 ETC[0] | A0: siul_GPIO[0] A1: etimer0_ETC[0] A2: _ A3: _ | I: dspio2_SIN I: _ I: siul_EIRQ[0] | — | disabled | GF M |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------|---|--|---------------|------------------------|---------|
| C7 | GPIO | etimer0 ETC[1] | A0: siul_GPIO[1] A1: etimer0_ETC[1] A2: _ A3: _ | l: _ l: _ l: siul_EIRQ[1] | — | disabled | GF M |
| C8 | GPIO | etimer0 ETC[2] | A0: siul_GPIO[2] A1: etimer0_ETC[2] A2: _ A3: _ | l: _ l: _ l: siul_EIRQ[2] | — | disabled | GF M |
| C9 | GPIO | etimer0 ETC[3] | A0: siul_GPIO[3] A1: etimer0_ETC[3] A2: _ A3: _ | l: _ l: mc_rgm_ABS[2] l: siul_EIRQ[3] | — | pulldown | GF M |
| C11 | GPIO | fec CRS | A0: siul_GPIO[208] A1: flexray_DBG1 A2: etimer2_ETC[3] A3: dspio_CS5 | l: fec_CRIS l: _ l: _ | — | disabled | GF M |
| C12 | GPIO | fec TXD[0] | A0: siul_GPIO[201] A1: fec_TXD[0] A2: etimer2_ETC[1] A3: _ | l: _ l: _ l: _ | — | disabled | GF M |
| C13 | GPIO | fec COL | A0: siul_GPIO[206] A1: fec_COL A2: _ A3: lin1_TXD | l: _ l: _ l: _ | — | disabled | GF M |
| C14 | GPIO | can0 RXD | A0: siul_GPIO[17] A1: _ A2: _ A3: sscm_DEBUG[1] | l: can0_RXD l: can1_RXD l: siul_EIRQ[16] | — | disabled | GF M |
| C16 | GPIO | pdi DATA[5] | A0: siul_GPIO[136] A1: flexpwm2_A[0] A2: _ A3: etimer1_ETC[0] | l: pdi_DATA[5] l: _ l: _ | — | disabled | M |
| C17 | GPIO | pdi CLOCK | A0: siul_GPIO[128] A1: flexpwm2_B[1] A2: _ A3: etimer1_ETC[3] | l: pdi_CLOCK l: _ l: _ | — | disabled | M |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------------------|---|--|---------------|------------------------|---------|
| D1 | GPIO | nexus MDO[2] ¹ | A0: siul_GPIO[85] A1: _ A2: npc_wrapper_MDO[2] A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| D2 | GPIO | nexus MDO[3] ¹ | A0: siul_GPIO[84] A1: _ A2: npc_wrapper_MDO[3] A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| D3 | GPIO | can1 RXD | A0: siul_GPIO[15] A1: _ A2: _ A3: _ | l: can1_RXD l: can0_RXD l: siul_EIRQ[14] | — | disabled | GF M |
| D4 | GPIO | dspi0 SOUT | A0: siul_GPIO[38] A1: dspi0_SOUT A2: _ A3: sscm_DEBUG[6] | l: _ l: _ l: siul_EIRQ[24] | — | disabled | GF M |
| D6 | GPIO | etimer0 ETC[5] | A0: siul_GPIO[44] A1: etimer0_ETC[5] A2: _ A3: _ | l: _ l: _ l: _ | — | disabled | GF M |
| D7 | GPIO | etimer0 ETC[4] | A0: siul_GPIO[43] A1: etimer0_ETC[4] A2: _ A3: _ | l: _ l: mc_rgm_ABS[0] l: _ | — | pulldown | GF M |
| D10 | GPIO | fec TXD[2] | A0: siul_GPIO[203] A1: fec_TXD[2] A2: _ A3: _ | l: flexpwm1_FAULT[1] l: _ l: _ | — | disabled | GF M |
| D11 | GPIO | fec TXD[1] | A0: siul_GPIO[202] A1: fec_TXD[1] A2: _ A3: dspi2_SCK | l: flexpwm1_FAULT[0] l: _ l: _ | — | disabled | GF M |
| D12 | GPIO | fec RX_DV | A0: siul_GPIO[210] A1: flexray_DBG3 A2: etimer2_ETC[0] A3: dspi0_CS7 | l: fec_RX_DV l: _ l: _ | — | disabled | GF M |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------------------|--|--|---------------|------------------------|---------|
| D13 | GPIO | fec MDC | A0: siul_GPIO[199] A1: fec_MDC A2: _ A3: _ | l: _ l: lin1_RXD l: _ | — | disabled | GF M |
| D16 | GPIO | pdi DATA[0] | A0: siul_GPIO[131] A1: _ A2: lin3_TXD A3: _ | l: pdi_DATA[0] l: _ l: flexpwm2_FAULT[2] | — | disabled | M |
| D17 | GPIO | pdi DATA[1] | A0: siul_GPIO[132] A1: flexpwm2_B[3] A2: _ A3: _ | l: pdi_DATA[1] l: _ l: _ | — | disabled | M |
| E2 | GPIO | nexus MDO[1] ¹ | A0: siul_GPIO[86] A1: _ A2: npc_wrapper_MDO[1] A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| E3 | GPIO | flexray CA_RX | A0: siul_GPIO[49] A1: _ A2: ctu0_EXT_TGR A3: _ | l: flexray_CA_RX l: _ l: _ | — | disabled | GF M |
| E14 | GPIO | pdi LINE_V | A0: siul_GPIO[129] A1: _ A2: lin2_TXD A3: _ | l: pdi_LINE_V l: _ l: flexpwm2_FAULT[0] | — | disabled | M |
| E15 | GPIO | pdi DATA[2] | A0: siul_GPIO[133] A1: flexpwm2_A[1] A2: _ A3: etimer1_ETC[2] | l: pdi_DATA[2] l: _ l: _ | — | disabled | M |
| E16 | GPIO | pdi DATA[3] | A0: siul_GPIO[134] A1: flexpwm2_X[1] A2: _ A3: _ | l: pdi_DATA[3] l: _ l: _ | — | disabled | M |
| E17 | GPIO | pdi DATA[4] | A0: siul_GPIO[135] A1: flexpwm2_A[2] A2: _ A3: etimer1_ETC[4] | l: pdi_DATA[4] l: _ l: _ | — | disabled | M |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|----------------------------|---|---|---------------|------------------------|---------|
| F1 | GPIO | nexus MDO[6] ¹ | A0: siul_GPIO[113] A1: _ A2: npc_wrapper_MDO[6] A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| F2 | GPIO | nexus MDO[11] ¹ | A0: siul_GPIO[108] A1: _ A2: npc_wrapper_MDO[11] A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| F3 | GPIO | dspi1 SOUT | A0: siul_GPIO[7] A1: dspi1_SOUT A2: _ A3: _ | l: _ l: _ l: siul_EIRQ[7] | — | disabled | GF M |
| F4 | GPIO | dspi1 SIN | A0: siul_GPIO[8] A1: _ A2: _ A3: _ | l: dspi1_SIN l: _ l: siul_EIRQ[8] | — | disabled | GF M |
| F14 | GPIO | mc_cgl clk_out | A0: siul_GPIO[233] A1: mc_cgl_clk_out A2: etimer2_ETC[5] A3: _ | l: _ l: _ l: _ | — | disabled | PD |
| F15 | GPIO | pdi DATA[6] | A0: siul_GPIO[137] A1: flexpwm2_B[0] A2: _ A3: etimer1_ETC[1] | l: pdi_DATA[6] l: _ l: _ | — | disabled | M |
| F16 | GPIO | pdi DATA[7] | A0: siul_GPIO[138] A1: flexpwm2_B[2] A2: _ A3: etimer1_ETC[5] | l: pdi_DATA[7] l: _ l: _ | — | disabled | M |
| F17 | GPIO | pdi DATA[8] | A0: siul_GPIO[139] A1: flexpwm2_A[3] A2: _ A3: _ | l: pdi_DATA[8] l: _ l: _ | — | disabled | M |
| G1 | GPIO | nexus MDO[4] ¹ | A0: siul_GPIO[115] A1: _ A2: npc_wrapper_MDO[4] A3: _ | l: _ l: _ l: _ | — | disabled | GF |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|----------------------------|--|---|---------------|------------------------|---------|
| G3 | GPIO | dspi0 SCK | A0: siul_GPIO[37] A1: dspi0_SCK A2: _ A3: sscm_DEBUG[5] | l: flexpwm0_FAULT[3] l: _ l: siul_EIRQ[23] | — | disabled | GF M |
| G4 | GPIO | dspi1 SCK | A0: siul_GPIO[6] A1: dspi1_SCK A2: _ A3: _ | l: _ l: _ l: siul_EIRQ[6] | — | disabled | GF M |
| G14 | GPIO | pdi DATA[9] | A0: siul_GPIO[140] A1: flexpwm2_X[2] A2: _ A3: _ | l: pdi_DATA[9] l: _ l: _ | — | disabled | M |
| G15 | GPIO | pdi DATA[10] | A0: siul_GPIO[141] A1: flexpwm2_X[3] A2: _ A3: _ | l: pdi_DATA[10] l: _ l: _ | — | disabled | M |
| G16 | GPIO | pdi DATA[11] | A0: siul_GPIO[142] A1: flexpwm2_X[0] A2: _ A3: _ | l: pdi_DATA[11] l: _ l: _ | — | disabled | M |
| G17 | GPIO | pdi FRAME_V | A0: siul_GPIO[130] A1: _ A2: _ A3: _ | l: pdi_FRAME_V l: lin2_RXD l: flexpwm2_FAULT[1] | — | disabled | M |
| H1 | GPIO | nexus MDO[10] ¹ | A0: siul_GPIO[109] A1: _ A2: npc_wrapper_MDO[10] A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| H3 | GPIO | dspi0 CS0 | A0: siul_GPIO[36] A1: dspi0_CS0 A2: _ A3: sscm_DEBUG[4] | l: _ l: _ l: siul_EIRQ[22] | — | disabled | GF M |
| H4 | GPIO | dspi1 CS0 | A0: siul_GPIO[5] A1: dspi1_CS0 A2: _ A3: dspi0_CS7 | l: _ l: _ l: siul_EIRQ[5] | — | disabled | GF M |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------------------|--|--|---------------|------------------------|---------|
| H14 | GPIO | pdi DATA[12] | A0: siul_GPIO[143] A1: _ A2: _ A3: _ | l: pdi_DATA[12] l: lin3_RXD l: flexpwm2_FAULT[3] | — | disabled | M |
| H15 | GPIO | pdi DATA[13] | A0: siul_GPIO[144] A1: pdi_SENS_SEL[2] A2: ctu1_EXT_TGR A3: _ | l: pdi_DATA[13] l: _ l: _ | — | disabled | M |
| H17 | GPIO | flexpwm0 X[0] | A0: siul_GPIO[194] A1: flexpwm0_X[0] A2: ebi_AD28 A3: _ | l: _ l: _ l: _ | — | disabled | D / |
| J1 | GPIO | nexus MCKO | A0: siul_GPIO[87] A1: _ A2: npc_wrapper_MCKO A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| J2 | GPIO | nexus MDO[8] ¹ | A0: siul_GPIO[111] A1: _ A2: npc_wrapper_MDO[8] A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| J3 | GPIO | dspi2 CS0 | A0: siul_GPIO[10] A1: dspi2_CS0 A2: _ A3: can3_TXD | l: _ l: _ l: siul_EIRQ[9] | — | disabled | GF M |
| J4 | GPIO | dspi2 CS2 | A0: siul_GPIO[42] A1: dspi2_CS2 A2: lin3_TXD A3: can2_TXD | l: flexpwm0_FAULT[1] l: _ l: _ | — | disabled | GF M |
| J14 | GPIO | pdi DATA[14] | A0: siul_GPIO[145] A1: pdi_SENS_SEL[1] A2: i2c2_clock A3: _ | l: pdi_DATA[14] l: _ l: _ | — | disabled | M |
| J15 | GPIO | pdi DATA[15] | A0: siul_GPIO[146] A1: pdi_SENS_SEL[0] A2: i2c2_data A3: _ | l: pdi_DATA[15] l: ctu1_EXT_IN l: _ | — | disabled | M |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------------------|--|------------------------------|---------------|------------------------|---------|
| J17 | GPIO | flexpwm0_X[1] | A0: siul_GPIO[195] A1: flexpwm0_X[1] A2: ebi_AD29 A3: _ | l: _ l: _ l: _ | — | disabled | D A |
| K1 | GPIO | nexus_MSEO_B[0] ¹ | A0: siul_GPIO[89] A1: _ A2: npc_wrapper_MSEO_B[0] A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| K2 | GPIO | nexus_MSEO_B[1] ¹ | A0: siul_GPIO[88] A1: _ A2: npc_wrapper_MSEO_B[1] A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| K3 | GPIO | nexus_RDY_B | A0: siul_GPIO[216] A1: _ A2: nexus_RDY_B A3: _ | l: _ l: _ l: _ | — | disabled | GF |
| K4 | GPIO | dspl0_SIN | A0: siul_GPIO[39] A1: _ A2: _ A3: sscm_DEBUG[7] | l: dspl0_SIN l: _ l: _ | — | disabled | GF M |
| K14 | GPIO | flexpwm0_X[2] | A0: siul_GPIO[196] A1: flexpwm0_X[2] A2: ebi_AD30 A3: _ | l: _ l: _ l: _ | — | disabled | D A |
| K15 | GPIO | flexpwm0_X[3] | A0: siul_GPIO[197] A1: flexpwm0_X[3] A2: ebi_AD31 A3: _ | l: _ l: _ l: _ | — | disabled | D A |
| K16 | GPIO | flexpwm0_A[1] | A0: siul_GPIO[149] A1: _ A2: ebi_RD_WR A3: flexpwm0_A[1] | l: _ l: _ l: _ | — | disabled | D A |
| K17 | GPIO | flexpwm0_B[0] | A0: siul_GPIO[148] A1: _ A2: ebi_CLKOUT A3: flexpwm0_B[0] | l: _ l: _ l: _ | — | disabled | D A |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------------------|---|---|---------------|------------------------|---------|
| L1 | GPIO | nexus EVTO_B | A0: siul_GPIO[90] A1: _ A2: npc_wrapper_EVTO_B A3: _ | I: _ I: _ I: _ | — | disabled | GF |
| L2 | GPIO | nexus EVTI_B | A0: siul_GPIO[91] A1: _ A2: leo_sor_proxy_EVTI_B A3: _ | I: _ I: _ I: _ | — | disabled | GF M |
| L3 | GPIO | dspi2 SCK | A0: siul_GPIO[11] A1: dspi2_SCK A2: _ A3: _ | I: can3_RXD I: _ I: siul_EIRQ[10] | — | disabled | GF M |
| L4 | GPIO | nexus MDO[13] ¹ | A0: siul_GPIO[218] A1: _ A2: npc_wrapper_MDO[13] A3: _ | I: can2_RXD I: can3_RXD I: _ | — | disabled | GF |
| L16 | GPIO | flexpwm0 B[1] | A0: siul_GPIO[150] A1: dramc_CS0 A2: ebi_TS A3: flexpwm0_B[1] | I: _ I: _ I: _ | — | disabled | D A |
| L17 | GPIO | TDO | A0: siul_GPIO[20] A1: jtagc_TDO A2: _ A3: _ | I: _ I: _ I: _ | — | disabled | GF |
| M3 | GPIO | dspi1 CS2 | A0: siul_GPIO[56] A1: dspi1_CS2 A2: _ A3: dspi0_CS5 | I: flexpwm0_FAULT[3] I: lin2_RXD I: _ | — | disabled | GF M |
| M4 | GPIO | nexus MDO[12] ¹ | A0: siul_GPIO[217] A1: _ A2: npc_wrapper_MDO[12] A3: can2_TXD | I: _ I: _ I: _ | — | disabled | GF |
| M14 | GPIO | flexpwm0 B[2] | A0: siul_GPIO[152] A1: dramc_CAS A2: ebi_WE_BE_1 A3: flexpwm0_B[2] | I: _ I: _ I: _ | — | disabled | D A |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------|---|--|---------------|------------------------|---------|
| M15 | GPIO | TDI | A0: siul_GPIO[21] A1: _ A2: _ A3: _ | l: jtagc_TDI l: _ l: _ | — | pullup | GF M |
| M17 | GPIO | flexpwm1 A[1] | A0: siul_GPIO[157] A1: dramc_ODT A2: ebi_CS1 A3: flexpwm1_A[1] | l: _ l: _ l: _ | — | disabled | D A |
| N3 | GPIO | dspi0 CS3 | A0: siul_GPIO[53] A1: dspi0_CS3 A2: i2c2_clock A3: _ | l: flexpwm0_FAULT[2] l: _ l: _ | — | disabled | GF M |
| N14 | GPIO | flexpwm0 B[3] | A0: siul_GPIO[154] A1: dramc_BA[0] A2: ebi_WE_BE_3 A3: flexpwm0_B[3] | l: _ l: _ l: _ | — | disabled | D A |
| N15 | GPIO | flexpwm0 A[2] | A0: siul_GPIO[151] A1: dramc_RAS A2: ebi_WE_BE_0 A3: flexpwm0_A[2] | l: _ l: _ l: _ | — | disabled | D A |
| N16 | GPIO | flexpwm1 A[0] | A0: siul_GPIO[155] A1: dramc_BA[1] A2: ebi_BDIP A3: flexpwm1_A[0] | l: _ l: _ l: _ | — | disabled | D A |
| N17 | GPIO | flexpwm1 B[0] | A0: siul_GPIO[156] A1: dramc_BA[2] A2: ebi_CS0 A3: flexpwm1_B[0] | l: _ l: _ l: _ | — | disabled | D A |
| P3 | GPIO | dspi0 CS2 | A0: siul_GPIO[54] A1: dspi0_CS2 A2: i2c2_data A3: _ | l: flexpwm0_FAULT[1] l: _ l: _ | — | disabled | GF M |
| P5 | GPIO | etimer1 ETC[1] | A0: siul_GPIO[45] A1: etimer1_ETC[1] A2: _ A3: _ | l: ctu0_EXT_IN l: flexpwm0_EXT_SYNC l: ctu1_EXT_IN | — | disabled | GF M |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------------|--|---|----------------------|------------------------|---------|
| P6 | GPIO | etimer1 ETC[2] | A0: siul_GPIO[46] A1: etimer1_ETC[2] A2: ctu0_EXT_TGR A3: _ | l: _ l: _ l: _ | — | disabled | GF M |
| P7 | ANA | adc0 AN[0] | — | siul_GPI[23] lin0_RXD | AN: adc0_AN[0] | | A |
| P8 | GPIO | etimer1 ETC[3] | A0: siul_GPIO[92] A1: etimer1_ETC[3] A2: _ A3: _ | l: ctu1_EXT_IN l: mc_rgm_FAB l: siul_EIRQ[30] | — | pulldown | GF M |
| P11 | ANA | adc0_adc1 AN[14] | — | siul_GPI[28] | AN: adc0_adc1_AN[14] | | A S |
| P12 | GPIO | etimer1 ETC[4] | A0: siul_GPIO[93] A1: etimer1_ETC[4] A2: ctu1_EXT_TGR A3: _ | l: _ l: _ l: siul_EIRQ[31] | — | disabled | GF M |
| P13 | GPIO | etimer1 ETC[5] | A0: siul_GPIO[78] A1: etimer1_ETC[5] A2: _ A3: _ | l: _ l: _ l: siul_EIRQ[26] | — | disabled | GF M |
| P15 | GPIO | flexpwm0 A[3] | A0: siul_GPIO[153] A1: dramc_WEB A2: ebi_WE_BE_2 A3: flexpwm0_A[3] | l: _ l: _ l: _ | — | disabled | D A |
| P16 | GPIO | flexpwm0 A[0] | A0: siul_GPIO[147] A1: dramc_CKE A2: ebi_OE A3: flexpwm0_A[0] | l: _ l: _ l: _ | — | disabled | D A |
| P17 | GPIO | flexpwm1 B[1] | A0: siul_GPIO[163] A1: dramc_ADD[5] A2: ebi_ADD13 A3: flexpwm1_B[1] | l: _ l: _ l: _ | — | disabled | D A |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------|--|---|----------------------|------------------------|---------|
| R4 | GPIO | dspi1 CS3 | A0: siul_GPIO[55] A1: dsp1_CS3 A2: lin2_TXD A3: dsp1_CS4 | I: _ I: _ I: _ | — | disabled | GF M |
| R5 | ANA | adc2 AN[0] | — | siul_GPI[221] | AN: adc2_AN[0] | — | A |
| R6 | ANA | adc2 AN[3] | — | siul_GPI[224] | AN: adc2_AN[3] | — | A |
| R8 | ANA | adc2_adc3 AN[14] | — | siul_GPI[228] | AN: adc2_adc3_AN[14] | — | A S |
| R10 | ANA | adc0 AN[2] | — | siul_GPI[33] | AN: adc0_AN[2] | — | A |
| R11 | ANA | adc0_adc1 AN[13] | — | siul_GPI[27] | AN: adc0_adc1_AN[13] | — | A S |
| R12 | ANA | adc1 AN[1] | — | siul_GPI[30] etimer0_ETC[4] siul_EIRQ[19] | AN: adc1_AN[1] | — | A |
| R14 | GPIO | lin0 TXD | A0: siul_GPIO[18] A1: lin0_TXD A2: i2c0_clock A3: sscm_DEBUG[2] | I: _ I: _ I: siul_EIRQ[17] | — | disabled | GF M |
| R16 | GPIO | flexpwm1 A[2] | A0: siul_GPIO[164] A1: dramc_ADD[6] A2: ebi_ADD14 A3: flexpwm1_A[2] | I: _ I: _ I: _ | — | disabled | D A |
| R17 | GPIO | flexpwm1 B[2] | A0: siul_GPIO[165] A1: dramc_ADD[7] A2: ebi_ADD15 A3: flexpwm1_B[2] | I: _ I: _ I: _ | — | disabled | D A |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------------|--|----------------------------------|----------------------|------------------------|---------|
| T3 | GPIO | dspi2 SOUT | A0: siul_GPIO[12] A1: dsp2_SOUT A2: _ A3: _ | I: _ I: _ I: siul_EIRQ[11] | — | disabled | GF M |
| T4 | ANA | adc3 AN[0] | — | siul_GPI[229] | AN: adc3_AN[0] | — | A |
| T5 | ANA | adc3 AN[3] | — | siul_GPI[232] | AN: adc3_AN[3] | — | A |
| T6 | ANA | adc2 AN[2] | — | siul_GPI[223] | AN: adc2_AN[2] | — | A |
| T8 | ANA | adc2_adc3 AN[13] | — | siul_GPI[227] | AN: adc2_adc3_AN[13] | — | A S |
| T10 | ANA | adc0 AN[1] | — | siul_GPI[24] etimer0_ETC[5] | AN: adc0_AN[1] | — | A |
| T11 | ANA | adc0_adc1 AN[12] | — | siul_GPI[26] | AN: adc0_adc1_AN[12] | — | A S |
| T12 | ANA | adc1 AN[0] | — | siul_GPI[29] lin1_RXD | AN: adc1_AN[0] | — | A |
| T13 | ANA | adc1 AN[2] | — | siul_GPI[31] siul_EIRQ[20] | AN: adc1_AN[2] | — | A |
| T14 | GPIO | lin0 RXD | A0: siul_GPIO[19] A1: _ A2: i2c0_data A3: sscm_DEBUG[3] | I: lin0_RXD I: _ I: _ | — | disabled | GF M |

Table 9. 257 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional inputs | Analog inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------------|--|--|----------------------|------------------------|---------|
| T15 | GPIO | etimer1 ETC[0] | A0: siul_GPIO[4] A1: etimer1_ETC[0] A2: _ A3: _ | I: _ I: _ I: siul_EIRQ[4] | — | disabled | GF M |
| U3 | GPIO | dspl2 SIN | A0: siul_GPIO[13] A1: _ A2: _ A3: _ | I: dspl2_SIN I: flexpwm0_FAULT[0] I: siul_EIRQ[12] | — | disabled | GF M |
| U4 | ANA | adc3 AN[1] | — | siul_GPI[230] | AN: adc3_AN[1] | — | A |
| U5 | ANA | adc3 AN[2] | — | siul_GPI[231] | AN: adc3_AN[2] | — | A |
| U6 | ANA | adc2 AN[1] | — | siul_GPI[222] | AN: adc2_AN[1] | — | A |
| U7 | ANA | adc2_adc3 AN[11] | — | siul_GPI[225] | AN: adc2_adc3_AN[11] | — | A S |
| U8 | ANA | adc2_adc3 AN[12] | — | siul_GPI[226] | AN: adc2_adc3_AN[12] | — | A S |
| U11 | ANA | adc0_adc1 AN[11] | — | siul_GPI[25] | AN: adc0_adc1_AN[11] | — | A S |

END OF 257 MAPBGA PIN MULTIPLEXING TABLE

¹ Do not connect pin directly to a power supply or ground.

Table 10. 473 MAPBGA pin multiplexing

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------------------|---|--|---------------|------------------------|----------|
| A4 | GPIO | nexus MDO[5] ¹ | A0: siul_GPIO[114] A1: _ A2: npc_wrapper_MDO[5] A3: _ | l: _ l: _ l: _ | — | disabled | Gl |
| A5 | GPIO | nexus MDO[7] ¹ | A0: siul_GPIO[112] A1: _ A2: npc_wrapper_MDO[7] A3: _ | l: _ l: _ l: _ | — | disabled | Gl |
| A6 | GPIO | nexus MDO[9] ¹ | A0: siul_GPIO[110] A1: _ A2: npc_wrapper_MDO[9] A3: _ | l: _ l: _ l: _ | — | disabled | Gl |
| A7 | GPIO | flexray CB_TX | A0: siul_GPIO[51] A1: flexray_CB_TX A2: _ A3: _ | l: _ l: _ l: _ | — | disabled | Gl Sy |
| A8 | GPIO | flexray CA_TR_EN | A0: siul_GPIO[47] A1: flexray_CA_TR_EN A2: _ A3: _ | l: ctu0_EXT_IN l: flexpwm0_EXT_SYNC l: _ | — | disabled | Gl Sy |
| A9 | GPIO | fec RX_DV | A0: siul_GPIO[210] A1: flexray_DBG3 A2: etimer2_ETC[0] A3: dspio_CS7 | l: fec_RX_DV l: _ l: _ | — | disabled | Gl M |
| A10 | GPIO | fec MDIO | A0: siul_GPIO[198] A1: fec_MDIO A2: _ A3: dspio2_CS0 | l: _ l: _ l: siul_EIRQ[28] | — | disabled | Gl M |
| A11 | GPIO | fec TX_CLK | A0: siul_GPIO[207] A1: flexray_DBG0 A2: etimer2_ETC[4] A3: dspio_CS4 | l: fec_TX_CLK l: _ l: _ | — | disabled | Gl M |
| A12 | GPIO | fec TX_EN | A0: siul_GPIO[200] A1: fec_TX_EN A2: _ A3: lin0_TXD | l: _ l: _ l: _ | — | disabled | Gl M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------|--|--|---------------|------------------------|---------|
| A13 | GPIO | fec TXD[3] | A0: siul_GPIO[204] A1: fec_TXD[3] A2: _ A3: dsp2_CS2 | I: flexpwm1_FAULT[2] I: _ I: siul_EIRQ[29] | — | disabled | GI M |
| A15 | GPIO | pdi DATA[3] | A0: siul_GPIO[134] A1: flexpwm2_X[1] A2: _ A3: _ | I: pdi_DATA[3] I: _ I: _ | — | disabled | M |
| A16 | GPIO | pdi DATA[1] | A0: siul_GPIO[132] A1: flexpwm2_B[3] A2: _ A3: _ | I: pdi_DATA[1] I: _ I: _ | — | disabled | M |
| A17 | GPIO | pdi CLOCK | A0: siul_GPIO[128] A1: flexpwm2_B[1] A2: _ A3: etimer1_ETC[3] | I: pdi_CLOCK I: _ I: _ | — | disabled | M |
| A18 | GPIO | pdi DATA[7] | A0: siul_GPIO[138] A1: flexpwm2_B[2] A2: _ A3: etimer1_ETC[5] | I: pdi_DATA[7] I: _ I: _ | — | disabled | M |
| A19 | GPIO | pdi DATA[10] | A0: siul_GPIO[141] A1: flexpwm2_X[3] A2: _ A3: _ | I: pdi_DATA[10] I: _ I: _ | — | disabled | M |
| A20 | GPIO | pdi DATA[13] | A0: siul_GPIO[144] A1: pdi_SENS_SEL[2] A2: ctu1_EXT_TGR A3: _ | I: pdi_DATA[13] I: _ I: _ | — | disabled | M |
| A21 | GPIO | pdi DATA[15] | A0: siul_GPIO[146] A1: pdi_SENS_SEL[0] A2: i2c2_data A3: _ | I: pdi_DATA[15] I: ctu1_EXT_IN I: _ | — | disabled | M |
| B3 | GPIO | mc_cgl clk_out | A0: siul_GPIO[22] A1: mc_cgl_clk_out A2: etimer2_ETC[5] A3: _ | I: _ I: _ I: siul_EIRQ[18] | — | disabled | G |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------------------|--|--|---------------|------------------------|----------|
| B4 | GPIO | can1 TXD | A0: siul_GPIO[14] A1: can1_TXD A2: _ A3: _ | l: _ l: _ l: siul_EIRQ[13] | — | disabled | Gl M |
| B5 | GPIO | nexus MDO[14] ¹ | A0: siul_GPIO[219] A1: _ A2: npc_wrapper_MDO[14] A3: can3_TXD | l: _ l: _ l: _ | — | disabled | Gl |
| B6 | GPIO | dspi2 CS1 | A0: siul_GPIO[9] A1: dspi2_CS1 A2: _ A3: _ | l: flexpwm0_FAULT[0] l: lin3_RXD l: can2_RXD | — | disabled | Gl M |
| B7 | GPIO | flexray CB_TR_EN | A0: siul_GPIO[52] A1: flexray_CB_TR_EN A2: _ A3: _ | l: _ l: _ l: _ | — | disabled | Gl Sy |
| B8 | GPIO | flexray CA_TX | A0: siul_GPIO[48] A1: flexray_CA_TX A2: _ A3: _ | l: ctu1_EXT_IN l: _ l: _ | — | disabled | Gl Sy |
| B9 | GPIO | fec RXD[3] | A0: siul_GPIO[214] A1: i2c1_data A2: _ A3: _ | l: fec_RXD[3] l: _ l: _ | — | disabled | Gl M |
| B10 | GPIO | fec RX_ER | A0: siul_GPIO[215] A1: _ A2: _ A3: dspi0_CS1 | l: fec_RX_ER l: _ l: _ | — | disabled | Gl M |
| B11 | GPIO | fec TXD[0] | A0: siul_GPIO[201] A1: fec_TXD[0] A2: etimer2_ETC[1] A3: _ | l: _ l: _ l: _ | — | disabled | Gl M |
| B12 | GPIO | fec RXD[0] | A0: siul_GPIO[211] A1: i2c1_clock A2: _ A3: _ | l: fec_RXD[0] l: _ l: siul_EIRQ[27] | — | disabled | Gl M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------------------|--|--|---------------|------------------------|---------|
| B13 | GPIO | fec TX_ER | A0: siul_GPIO[205] A1: fec_TX_ER A2: dsp2_CS3 A3: _ | I: flexpwm1_FAULT[3] I: lin0_RXD I: _ | — | disabled | GI M |
| B15 | GPIO | pdi DATA[6] | A0: siul_GPIO[137] A1: flexpwm2_B[0] A2: _ A3: etimer1_ETC[1] | I: pdi_DATA[6] I: _ I: _ | — | disabled | M |
| B16 | GPIO | pdi DATA[4] | A0: siul_GPIO[135] A1: flexpwm2_A[2] A2: _ A3: etimer1_ETC[4] | I: pdi_DATA[4] I: _ I: _ | — | disabled | M |
| B17 | GPIO | pdi DATA[0] | A0: siul_GPIO[131] A1: _ A2: lin3_TXD A3: _ | I: pdi_DATA[0] I: _ I: flexpwm2_FAULT[2] | — | disabled | M |
| B18 | GPIO | pdi LINE_V | A0: siul_GPIO[129] A1: _ A2: lin2_TXD A3: _ | I: pdi_LINE_V I: _ I: flexpwm2_FAULT[0] | — | disabled | M |
| B19 | GPIO | pdi DATA[9] | A0: siul_GPIO[140] A1: flexpwm2_X[2] A2: _ A3: _ | I: pdi_DATA[9] I: _ I: _ | — | disabled | M |
| B20 | GPIO | pdi DATA[14] | A0: siul_GPIO[145] A1: pdi_SENS_SEL[1] A2: i2c2_clock A3: _ | I: pdi_DATA[14] I: _ I: _ | — | disabled | M |
| B21 | GPIO | can0 TXD | A0: siul_GPIO[16] A1: can0_TXD A2: _ A3: sscm_DEBUG[0] | I: _ I: _ I: siul_EIRQ[15] | — | disabled | GI M |
| C2 | GPIO | nexus MDO[15] ¹ | A0: siul_GPIO[220] A1: _ A2: npc_wrapper_MDO[15] A3: _ | I: can3_RXD I: can2_RXD I: _ | — | disabled | G |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------|--|---|---------------|------------------------|--------|
| C5 | GPIO | flexray CB_RX | A0: siul_GPIO[50] A1: _ A2: ctu1_EXT_TGR A3: _ | I: flexray_CB_RX I: _ I: _ | — | disabled | G M |
| C6 | GPIO | etimer0 ETC[4] | A0: siul_GPIO[43] A1: etimer0_ETC[4] A2: _ A3: _ | I: _ I: mc_rgm_ABS[0] I: _ | — | pulldown | G M |
| C7 | GPIO | etimer0 ETC[1] | A0: siul_GPIO[1] A1: etimer0_ETC[1] A2: _ A3: _ | I: _ I: _ I: siul_EIRQ[1] | — | disabled | G M |
| C8 | GPIO | etimer0 ETC[2] | A0: siul_GPIO[2] A1: etimer0_ETC[2] A2: _ A3: _ | I: _ I: _ I: siul_EIRQ[2] | — | disabled | G M |
| C9 | GPIO | etimer0 ETC[3] | A0: siul_GPIO[3] A1: etimer0_ETC[3] A2: _ A3: _ | I: _ I: mc_rgm_ABS[2] I: siul_EIRQ[3] | — | pulldown | G M |
| C10 | GPIO | fec TXD[2] | A0: siul_GPIO[203] A1: fec_TXD[2] A2: _ A3: _ | I: flexpwm1_FAULT[1] I: _ I: _ | — | disabled | G M |
| C11 | GPIO | fec TXD[1] | A0: siul_GPIO[202] A1: fec_TXD[1] A2: _ A3: dsp_i2_SCK | I: flexpwm1_FAULT[0] I: _ I: _ | — | disabled | G M |
| C12 | GPIO | fec CRS | A0: siul_GPIO[208] A1: flexray_DBG1 A2: etimer2_ETC[3] A3: dsp_i0_CS5 | I: fec_CRIS I: _ I: _ | — | disabled | G M |
| C13 | GPIO | fec RX_CLK | A0: siul_GPIO[209] A1: flexray_DBG2 A2: etimer2_ETC[2] A3: dsp_i0_CS6 | I: fec_RX_CLK I: _ I: siul_EIRQ[25] | — | disabled | G M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------|---|--|---------------|------------------------|---------|
| C14 | GPIO | fec RXD[1] | A0: siul_GPIO[212] A1: dsp1_CS1 A2: etimer2_ETC[5] A3: _ | l: fec_RXD[1] l: _ l: _ | — | disabled | GI M |
| C15 | GPIO | fec COL | A0: siul_GPIO[206] A1: fec_COL A2: _ A3: lin1_TXD | l: _ l: _ l: _ | — | disabled | GI M |
| C16 | GPIO | pdi DATA[5] | A0: siul_GPIO[136] A1: flexpwm2_A[0] A2: _ A3: etimer1_ETC[0] | l: pdi_DATA[5] l: _ l: _ | — | disabled | M |
| C17 | GPIO | pdi DATA[2] | A0: siul_GPIO[133] A1: flexpwm2_A[1] A2: _ A3: etimer1_ETC[2] | l: pdi_DATA[2] l: _ l: _ | — | disabled | M |
| C18 | GPIO | pdi DATA[8] | A0: siul_GPIO[139] A1: flexpwm2_A[3] A2: _ A3: _ | l: pdi_DATA[8] l: _ l: _ | — | disabled | M |
| C19 | GPIO | pdi DATA[12] | A0: siul_GPIO[143] A1: _ A2: _ A3: _ | l: pdi_DATA[12] l: lin3_RXD l: flexpwm2_FAULT[3] | — | disabled | M |
| C20 | GPIO | can0 RXD | A0: siul_GPIO[17] A1: _ A2: _ A3: sscm_DEBUG[1] | l: can0_RXD l: can1_RXD l: siul_EIRQ[16] | — | disabled | GI M |
| C22 | GPIO | siul GPIO[197] | A0: siul_GPIO[197] A1: flexpwm0_X[3] A2: ebi_AD31 A3: _ | l: _ l: _ l: _ | — | disabled | D |
| C23 | GPIO | dramc CAS | A0: siul_GPIO[152] A1: dramc_CAS A2: ebi_WE_BE_1 A3: flexpwm0_B[2] | l: _ l: _ l: _ | — | disabled | D |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------------------|---|--|---------------|------------------------|---------|
| D1 | GPIO | nexus MDO[1] ¹ | A0: siul_GPIO[86] A1: _ A2: npc_wrapper_MDO[1] A3: _ | l: _ l: _ l: _ | — | disabled | Gl |
| D2 | GPIO | nexus MDO[3] ¹ | A0: siul_GPIO[84] A1: _ A2: npc_wrapper_MDO[3] A3: _ | l: _ l: _ l: _ | — | disabled | Gl |
| D3 | GPIO | can1 RXD | A0: siul_GPIO[15] A1: _ A2: _ A3: _ | l: can1_RXD l: can0_RXD l: siul_EIRQ[14] | — | disabled | Gl M |
| D4 | GPIO | dspi0 SOUT | A0: siul_GPIO[38] A1: dspi0_SOUT A2: _ A3: sscm_DEBUG[6] | l: _ l: _ l: siul_EIRQ[24] | — | disabled | Gl M |
| D6 | GPIO | etimer0 ETC[5] | A0: siul_GPIO[44] A1: etimer0_ETC[5] A2: _ A3: _ | l: _ l: _ l: _ | — | disabled | Gl M |
| D7 | GPIO | etimer0 ETC[0] | A0: siul_GPIO[0] A1: etimer0_ETC[0] A2: _ A3: _ | l: dspi2_SIN l: _ l: siul_EIRQ[0] | — | disabled | Gl M |
| D14 | GPIO | fec RXD[2] | A0: siul_GPIO[213] A1: _ A2: _ A3: dspi2_SOUT | l: fec_RXD[2] l: _ l: siul_EIRQ[21] | — | disabled | Gl M |
| D15 | GPIO | fec MDC | A0: siul_GPIO[199] A1: fec_MDC A2: _ A3: _ | l: _ l: lin1_RXD l: _ | — | disabled | Gl M |
| D18 | GPIO | pdi DATA[11] | A0: siul_GPIO[142] A1: flexpwm2_X[0] A2: _ A3: _ | l: pdi_DATA[11] l: _ l: _ | — | disabled | M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------------------|---|---|---------------|------------------------|---------|
| D19 | GPIO | pdi FRAME_V | A0: siul_GPIO[130] A1: _ A2: _ A3: _ | l: pdi_FRAME_V l: lin2_RXD l: flexpwm2_FAULT[1] | — | disabled | M |
| D21 | GPIO | dramc BA[1] | A0: siul_GPIO[155] A1: dramc_BA[1] A2: ebi_BDIP A3: flexpwm1_A[0] | l: _ l: _ l: _ | — | disabled | D |
| D22 | GPIO | siul GPIO[195] | A0: siul_GPIO[195] A1: flexpwm0_X[1] A2: ebi_AD29 A3: _ | l: _ l: _ l: _ | — | disabled | D |
| D23 | GPIO | dramc BA[0] | A0: siul_GPIO[154] A1: dramc_BA[0] A2: ebi_WE_BE_3 A3: flexpwm0_B[3] | l: _ l: _ l: _ | — | disabled | D |
| E2 | GPIO | nexus MDO[2] ¹ | A0: siul_GPIO[85] A1: _ A2: npc_wrapper_MDO[2] A3: _ | l: _ l: _ l: _ | — | disabled | GL |
| E3 | GPIO | flexray CA_RX | A0: siul_GPIO[49] A1: _ A2: ctu0_EXT_TGR A3: _ | l: flexray_CA_RX l: _ l: _ | — | disabled | GL M |
| E20 | GPIO | mc_cgl clk_out | A0: siul_GPIO[233] A1: mc_cgl_clk_out A2: etimer2_ETC[5] A3: _ | l: _ l: _ l: _ | — | disabled | P |
| E21 | GPIO | siul GPIO[149] | A0: siul_GPIO[149] A1: _ A2: ebi_RD_WR A3: flexpwm0_A[1] | l: _ l: _ l: _ | — | disabled | D |
| E22 | GPIO | dramc CS0 | A0: siul_GPIO[150] A1: dramc_CS0 A2: ebi_TS A3: flexpwm0_B[1] | l: _ l: _ l: _ | — | disabled | D |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------------------|---|----------------------|---------------|------------------------|----|
| E23 | GPIO | dramc BA[2] | A0: siul_GPIO[156] A1: dramc_BA[2] A2: ebi_CS0 A3: flexpwm1_B[0] | I: _ I: _ I: _ | — | disabled | D |
| F1 | GPIO | nexus MDO[10] ¹ | A0: siul_GPIO[109] A1: _ A2: npc_wrapper_MDO[10] A3: _ | I: _ I: _ I: _ | — | disabled | GI |
| F2 | GPIO | nexus MDO[11] ¹ | A0: siul_GPIO[108] A1: _ A2: npc_wrapper_MDO[11] A3: _ | I: _ I: _ I: _ | — | disabled | GI |
| F3 | GPIO | nexus MDO[6] ¹ | A0: siul_GPIO[113] A1: _ A2: npc_wrapper_MDO[6] A3: _ | I: _ I: _ I: _ | — | disabled | GI |
| F4 | GPIO | nexus MDO[4] ¹ | A0: siul_GPIO[115] A1: _ A2: npc_wrapper_MDO[4] A3: _ | I: _ I: _ I: _ | — | disabled | GI |
| F20 | GPIO | dramc RAS | A0: siul_GPIO[151] A1: dramc_RAS A2: ebi_WE_BE_0 A3: flexpwm0_A[2] | I: _ I: _ I: _ | — | disabled | D |
| F21 | GPIO | siul GPIO[194] | A0: siul_GPIO[194] A1: flexpwm0_X[0] A2: ebi_AD28 A3: _ | I: _ I: _ I: _ | — | disabled | D |
| F22 | GPIO | siul GPIO[148] | A0: siul_GPIO[148] A1: _ A2: ebi_CLKOUT A3: flexpwm0_B[0] | I: _ I: _ I: _ | — | disabled | D |
| F23 | GPIO | dramc D[5] | A0: siul_GPIO[179] A1: dramc_D[5] A2: ebi_AD13 A3: ebi_ADD29 | I: _ I: _ I: _ | — | disabled | DF |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------------------------|---|----------------------|---------------|------------------------|----|
| G1 | GPIO | nexus MCKO | A0: siul_GPIO[87] A1: _ A2: npc_wrapper_MCKO A3: _ | l: _ l: _ l: _ | — | disabled | Gl |
| G3 | GPIO | nexus MDO[8] ¹ | A0: siul_GPIO[111] A1: _ A2: npc_wrapper_MDO[8] A3: _ | l: _ l: _ l: _ | — | disabled | Gl |
| G4 | GPIO | nexus MSEO_B[1] ¹ | A0: siul_GPIO[88] A1: _ A2: npc_wrapper_MSEO_B[1] A3: _ | l: _ l: _ l: _ | — | disabled | Gl |
| G20 | GPIO | siul GPIO[196] | A0: siul_GPIO[196] A1: flexpwm0_X[2] A2: ebi_AD30 A3: _ | l: _ l: _ l: _ | — | disabled | I |
| G21 | GPIO | dramc DQS[0] | A0: siul_GPIO[190] A1: dramc_DQS[0] A2: ebi_AD24 A3: _ | l: _ l: _ l: _ | — | disabled | DF |
| G22 | GPIO | dramc DM[0] | A0: siul_GPIO[192] A1: dramc_DM[0] A2: ebi_AD26 A3: _ | l: _ l: _ l: _ | — | disabled | DF |
| G23 | GPIO | dramc D[7] | A0: siul_GPIO[181] A1: dramc_D[7] A2: ebi_AD15 A3: ebi_ADD31 | l: _ l: _ l: _ | — | disabled | DF |
| H1 | GPIO | nexus EVTO_B | A0: siul_GPIO[90] A1: _ A2: npc_wrapper_EVTO_B A3: _ | l: _ l: _ l: _ | — | disabled | Gl |
| H3 | GPIO | nexus MSEO_B[0] ¹ | A0: siul_GPIO[89] A1: _ A2: npc_wrapper_MSEO_B[0] A3: _ | l: _ l: _ l: _ | — | disabled | Gl |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|-------------------------------|--|--|---------------|------------------------|---------|
| H4 | GPIO | nexus EVTI_B | A0: siul_GPIO[91] A1: _ A2: leo_sor_proxy_EVTI_B A3: _ | l: _ l: _ l: _ | — | disabled | GI M |
| H20 | GPIO | dramc D[2] | A0: siul_GPIO[176] A1: dramc_D[2] A2: ebi_AD10 A3: ebi_ADD26 | l: _ l: _ l: _ | — | disabled | DF |
| J1 | GPIO | nexus RDY_B | A0: siul_GPIO[216] A1: _ A2: nexus_RDY_B A3: _ | l: _ l: _ l: _ | — | disabled | G |
| J2 | GPIO | nexus MDO[13] ¹ | A0: siul_GPIO[218] A1: _ A2: npc_wrapper_MDO[13] A3: _ | l: can2_RXD l: can3_RXD l: _ | — | disabled | GI |
| J3 | GPIO | nexus MDO[12] ¹ | A0: siul_GPIO[217] A1: _ A2: npc_wrapper_MDO[12] A3: can2_TXD | l: _ l: _ l: _ | — | disabled | GI |
| J4 | GPIO | dspi1 SIN | A0: siul_GPIO[8] A1: _ A2: _ A3: _ | l: dsp1_SIN l: _ l: siul_EIRQ[8] | — | disabled | GI M |
| J20 | GPIO | dramc D[0] | A0: siul_GPIO[174] A1: dramc_D[0] A2: ebi_AD8 A3: ebi_ADD24 | l: _ l: _ l: _ | — | disabled | DF |
| J21 | GPIO | dramc D[1] | A0: siul_GPIO[175] A1: dramc_D[1] A2: ebi_AD9 A3: ebi_ADD25 | l: _ l: _ l: _ | — | disabled | DF |
| J22 | GPIO | dramc D[3] | A0: siul_GPIO[177] A1: dramc_D[3] A2: ebi_AD11 A3: ebi_ADD27 | l: _ l: _ l: _ | — | disabled | DF |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|------------|---|--|---------------|------------------------|---------|
| J23 | GPIO | dramc D[6] | A0: siul_GPIO[180] A1: dramc_D[6] A2: ebi_AD14 A3: ebi_ADD30 | I: _ I: _ I: _ | — | disabled | DF |
| K1 | GPIO | dspi0 SCK | A0: siul_GPIO[37] A1: dspi0_SCK A2: _ A3: sscm_DEBUG[5] | I: flexpwm0_FAULT[3] I: _ I: siul_EIRQ[23] | — | disabled | GI M |
| K2 | GPIO | dspi1 CS0 | A0: siul_GPIO[5] A1: dspi1_CS0 A2: _ A3: dspi0_CS7 | I: _ I: _ I: siul_EIRQ[5] | — | disabled | GI M |
| K3 | GPIO | dspi1 SCK | A0: siul_GPIO[6] A1: dspi1_SCK A2: _ A3: _ | I: _ I: _ I: siul_EIRQ[6] | — | disabled | GI M |
| K4 | GPIO | dspi1 SOUT | A0: siul_GPIO[7] A1: dspi1_SOUT A2: _ A3: _ | I: _ I: _ I: siul_EIRQ[7] | — | disabled | GI M |
| K21 | GPIO | dramc D[4] | A0: siul_GPIO[178] A1: dramc_D[4] A2: ebi_AD12 A3: ebi_ADD28 | I: _ I: _ I: _ | — | disabled | DF |
| K22 | GPIO | dramc D[8] | A0: siul_GPIO[182] A1: dramc_D[8] A2: ebi_AD16 A3: _ | I: _ I: _ I: _ | — | disabled | DF |
| K23 | GPIO | dramc D[9] | A0: siul_GPIO[183] A1: dramc_D[9] A2: ebi_AD17 A3: _ | I: _ I: _ I: _ | — | disabled | DF |
| L1 | GPIO | dspi0 CS0 | A0: siul_GPIO[36] A1: dspi0_CS0 A2: _ A3: sscm_DEBUG[4] | I: _ I: _ I: siul_EIRQ[22] | — | disabled | GI M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------|---|--------------------------------------|---------------|------------------------|---------|
| L2 | GPIO | dspl2 CS2 | A0: siul_GPIO[42] A1: dspl2_CS2 A2: lin3_TXD A3: can2_TXD | I: flexpwm0_FAULT[1] I: _ I: _ | — | disabled | GI M |
| L3 | GPIO | dspl2 CS0 | A0: siul_GPIO[10] A1: dspl2_CS0 A2: _ A3: can3_TXD | I: _ I: _ I: siul_EIRQ[9] | — | disabled | GI M |
| M1 | GPIO | flexpwm0 X[0] | A0: siul_GPIO[57] A1: flexpwm0_X[0] A2: lin2_TXD A3: _ | I: _ I: _ I: _ | — | disabled | GI M |
| M3 | GPIO | dspl0 SIN | A0: siul_GPIO[39] A1: _ A2: _ A3: sscm_DEBUG[7] | I: dspl0_SIN I: _ I: _ | — | disabled | GI M |
| M20 | GPIO | dramc ODT | A0: siul_GPIO[157] A1: dramc_ODT A2: ebi_CS1 A3: flexpwm1_A[1] | I: _ I: _ I: _ | — | disabled | I |
| M21 | GPIO | dramc WEB | A0: siul_GPIO[153] A1: dramc_WEB A2: ebi_WE_BE_2 A3: flexpwm0_A[3] | I: _ I: _ I: _ | — | disabled | D |
| M22 | GPIO | dramc D[11] | A0: siul_GPIO[185] A1: dramc_D[11] A2: ebi_AD19 A3: _ | I: _ I: _ I: _ | — | disabled | DF |
| M23 | GPIO | dramc D[10] | A0: siul_GPIO[184] A1: dramc_D[10] A2: ebi_AD18 A3: _ | I: _ I: _ I: _ | — | disabled | DF |
| N1 | GPIO | flexpwm0 A[0] | A0: siul_GPIO[58] A1: flexpwm0_A[0] A2: _ A3: _ | I: _ I: etimer0_ETC[0] I: _ | — | disabled | GI M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------|---|-----------------------------------|---------------|------------------------|---------|
| N3 | GPIO | flexpwm0_X[1] | A0: siul_GPIO[60] A1: flexpwm0_X[1] A2: _ A3: _ | l: lin2_RXD l: _ l: _ | — | disabled | GI M |
| N4 | GPIO | flexpwm0_B[2] | A0: siul_GPIO[100] A1: flexpwm0_B[2] A2: _ A3: _ | l: _ l: etimer0_ETC[5] l: _ | — | disabled | GI M |
| N20 | GPIO | dramc_DQS[1] | A0: siul_GPIO[191] A1: dramc_DQS[1] A2: ebi_AD25 A3: _ | l: _ l: _ l: _ | — | disabled | DF |
| N21 | GPIO | dramc_DM[1] | A0: siul_GPIO[193] A1: dramc_DM[1] A2: ebi_AD27 A3: _ | l: _ l: _ l: _ | — | disabled | DF |
| N22 | GPIO | dramc_D[13] | A0: siul_GPIO[187] A1: dramc_D[13] A2: ebi_AD21 A3: _ | l: _ l: _ l: _ | — | disabled | DF |
| N23 | GPIO | dramc_D[12] | A0: siul_GPIO[186] A1: dramc_D[12] A2: ebi_AD20 A3: _ | l: _ l: _ l: _ | — | disabled | DF |
| P1 | GPIO | flexpwm0_B[0] | A0: siul_GPIO[59] A1: flexpwm0_B[0] A2: _ A3: _ | l: _ l: etimer0_ETC[1] l: _ | — | disabled | GI M |
| P2 | GPIO | flexpwm0_B[1] | A0: siul_GPIO[62] A1: flexpwm0_B[1] A2: _ A3: _ | l: _ l: etimer0_ETC[3] l: _ | — | disabled | GI M |
| P3 | GPIO | flexpwm0_A[2] | A0: siul_GPIO[99] A1: flexpwm0_A[2] A2: _ A3: _ | l: _ l: etimer0_ETC[4] l: _ | — | disabled | GI M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------|--|-----------------------------------|---------------|------------------------|---------|
| P4 | GPIO | flexpwm0_A[3] | A0: siul_GPIO[102] A1: flexpwm0_A[3] A2: _ A3: _ | I: _ I: _ I: _ | — | disabled | GI M |
| P20 | GPIO | dramc_D[14] | A0: siul_GPIO[188] A1: dramc_D[14] A2: ebi_AD22 A3: _ | I: _ I: _ I: _ | — | disabled | DF |
| P21 | GPIO | dramc_D[15] | A0: siul_GPIO[189] A1: dramc_D[15] A2: ebi_AD23 A3: _ | I: _ I: _ I: _ | — | disabled | DF |
| R1 | GPIO | flexpwm0_X[2] | A0: siul_GPIO[98] A1: flexpwm0_X[2] A2: lin3_TXD A3: _ | I: _ I: _ I: _ | — | disabled | GI M |
| R2 | GPIO | flexpwm0_X[3] | A0: siul_GPIO[101] A1: flexpwm0_X[3] A2: _ A3: _ | I: lin3_RXD I: _ I: _ | — | disabled | GI M |
| R3 | GPIO | flexpwm0_A[1] | A0: siul_GPIO[80] A1: flexpwm0_A[1] A2: _ A3: _ | I: _ I: etimer0_ETC[2] I: _ | — | disabled | GI M |
| R21 | GPIO | dramc_ADD[3] | A0: siul_GPIO[161] A1: dramc_ADD[3] A2: ebi_ADD11 A3: ebi_TEA | I: _ I: _ I: _ | — | disabled | D |
| R22 | GPIO | dramc_CKE | A0: siul_GPIO[147] A1: dramc_CKE A2: ebi_OE A3: flexpwm0_A[0] | I: _ I: _ I: _ | — | disabled | D |
| T1 | GPIO | flexpwm0_B[3] | A0: siul_GPIO[103] A1: flexpwm0_B[3] A2: _ A3: _ | I: _ I: _ I: _ | — | disabled | GI M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------|--|---|---------------|------------------------|---------|
| T2 | GPIO | flexpwm1_A[0] | A0: siul_GPIO[117] A1: flexpwm1_A[0] A2: _ A3: can2_TXD | l: _ l: _ l: _ | — | disabled | Gl M |
| T3 | GPIO | flexpwm1_A[1] | A0: siul_GPIO[120] A1: flexpwm1_A[1] A2: _ A3: can3_TXD | l: _ l: _ l: _ | — | disabled | Gl M |
| T20 | GPIO | dramc_ADD[8] | A0: siul_GPIO[166] A1: dramc_ADD[8] A2: ebi_AD0 A3: ebi_ADD16 | l: _ l: _ l: _ | — | disabled | D |
| T21 | GPIO | dramc_ADD[9] | A0: siul_GPIO[167] A1: dramc_ADD[9] A2: ebi_AD1 A3: ebi_ADD17 | l: _ l: _ l: _ | — | disabled | D |
| T22 | GPIO | dramc_ADD[1] | A0: siul_GPIO[159] A1: dramc_ADD[1] A2: ebi_ADD9 A3: ebi_CS3 | l: _ l: _ l: _ | — | disabled | D |
| U1 | GPIO | flexpwm1_B[0] | A0: siul_GPIO[118] A1: flexpwm1_B[0] A2: _ A3: _ | l: can2_RXD l: can3_RXD l: _ | — | disabled | Gl M |
| U2 | GPIO | flexpwm1_B[1] | A0: siul_GPIO[121] A1: flexpwm1_B[1] A2: _ A3: _ | l: can3_RXD l: can2_RXD l: _ | — | disabled | Gl M |
| U3 | GPIO | flexpwm1_A[2] | A0: siul_GPIO[123] A1: flexpwm1_A[2] A2: _ A3: _ | l: _ l: _ l: _ | — | disabled | Gl M |
| U4 | GPIO | dspi2_SCK | A0: siul_GPIO[11] A1: dspi2_SCK A2: _ A3: _ | l: can3_RXD l: _ l: siul_EIRQ[10] | — | disabled | Gl M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------|--|---|---------------|------------------------|---------|
| U20 | GPIO | dramc ADD[6] | A0: siul_GPIO[164] A1: dramc_ADD[6] A2: ebi_ADD14 A3: flexpwm1_A[2] | I: _ I: _ I: _ | — | disabled | D |
| U21 | GPIO | dramc ADD[12] | A0: siul_GPIO[170] A1: dramc_ADD[12] A2: ebi_AD4 A3: ebi_ADD20 | I: _ I: _ I: _ | — | disabled | D |
| U23 | GPIO | dramc ADD[0] | A0: siul_GPIO[158] A1: dramc_ADD[0] A2: ebi_ADD8 A3: ebi_CS2 | I: _ I: _ I: _ | — | disabled | D |
| V3 | GPIO | flexpwm1 B[2] | A0: siul_GPIO[124] A1: flexpwm1_B[2] A2: _ A3: _ | I: _ I: _ I: _ | — | disabled | GL M |
| V4 | GPIO | dspi1 CS2 | A0: siul_GPIO[56] A1: dspi1_CS2 A2: _ A3: dspi0_CS5 | I: flexpwm0_FAULT[3] I: lin2_RXD I: _ | — | disabled | GL M |
| V20 | GPIO | lin0 TXD | A0: siul_GPIO[18] A1: lin0_TXD A2: i2c0_clock A3: sscm_DEBUG[2] | I: _ I: _ I: siul_EIRQ[17] | — | disabled | GL M |
| V21 | GPIO | dramc ADD[13] | A0: siul_GPIO[171] A1: dramc_ADD[13] A2: ebi_AD5 A3: ebi_ADD21 | I: _ I: _ I: _ | — | disabled | D |
| V23 | GPIO | dramc ADD[2] | A0: siul_GPIO[160] A1: dramc_ADD[2] A2: ebi_ADD10 A3: ebi_TA | I: _ I: _ I: _ | — | disabled | D |
| W3 | GPIO | dspi0 CS3 | A0: siul_GPIO[53] A1: dspi0_CS3 A2: i2c2_clock A3: _ | I: flexpwm0_FAULT[2] I: _ I: _ | — | disabled | GL M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------------|--|--|----------------------|------------------------|---------|
| W20 | GPIO | lin0 RXD | A0: siul_GPIO[19] A1: _ A2: i2c0_data A3: sscm_DEBUG[3] | l: lin0_RXD l: _ l: _ | — | disabled | Gl M |
| W21 | GPIO | dramc ADD[14] | A0: siul_GPIO[172] A1: dramc_ADD[14] A2: ebi_AD6 A3: ebi_ADD22 | l: _ l: _ l: _ | — | disabled | D |
| W22 | GPIO | dramc ADD[7] | A0: siul_GPIO[165] A1: dramc_ADD[7] A2: ebi_ADD15 A3: flexpwm1_B[2] | l: _ l: _ l: _ | — | disabled | D |
| W23 | GPIO | dramc ADD[4] | A0: siul_GPIO[162] A1: dramc_ADD[4] A2: ebi_ADD12 A3: ebi_ALE | l: _ l: _ l: _ | — | disabled | D |
| Y3 | GPIO | dspi0 CS2 | A0: siul_GPIO[54] A1: dspio_CS2 A2: i2c2_data A3: _ | l: flexpwm0_FAULT[1] l: _ l: _ | — | disabled | Gl M |
| Y5 | GPIO | flexpwm1 X[0] | A0: siul_GPIO[116] A1: flexpwm1_X[0] A2: etimer2_ETC[0] A3: dspio_CS1 | l: ctu0_EXT_IN l: ctu1_EXT_IN l: _ | — | disabled | Gl M |
| Y6 | ANA | adc3 AN[0] | — | siul_GPI[229] | AN: adc3_AN[0] | — | A |
| Y7 | ANA | adc2_adc3 AN[11] | — | siul_GPI[225] | AN: adc2_adc3_AN[11] | — | A S |
| Y8 | ANA | adc2_adc3 AN[14] | — | siul_GPI[228] | AN: adc2_adc3_AN[14] | — | A S |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------------|---|--|----------------------|------------------------|---------|
| Y9 | GPIO | etimer1 ETC[1] | A0: siul_GPIO[45] A1: etimer1_ETC[1] A2: _ A3: _ | l: ctu0_EXT_IN l: flexpwm0_EXT_SYNC l: ctu1_EXT_IN | — | disabled | Gl M |
| Y10 | GPIO | etimer1 ETC[2] | A0: siul_GPIO[46] A1: etimer1_ETC[2] A2: ctu0_EXT_TGR A3: _ | l: _ l: _ l: _ | — | disabled | Gl M |
| Y11 | GPIO | etimer1 ETC[3] | A0: siul_GPIO[92] A1: etimer1_ETC[3] A2: _ A3: _ | l: ctu1_EXT_IN l: mc_rgm_FAB l: siul_EIRQ[30] | — | pulldown | Gl M |
| Y14 | ANA | adc0_adc1 AN[11] | — | siul_GPI[25] | AN: adc0_adc1_AN[11] | — | A S |
| Y15 | GPIO | etimer1 ETC[5] | A0: siul_GPIO[78] A1: etimer1_ETC[5] A2: _ A3: _ | l: _ l: _ l: siul_EIRQ[26] | — | disabled | Gl M |
| Y16 | GPIO | etimer1 ETC[4] | A0: siul_GPIO[93] A1: etimer1_ETC[4] A2: ctu1_EXT_TGR A3: _ | l: _ l: _ l: siul_EIRQ[31] | — | disabled | Gl M |
| Y17 | ANA | adc1 AN[8] | — | siul_GPI[74] | AN: adc1_AN[8] | — | A |
| Y18 | ANA | adc1 AN[6] | — | siul_GPI[76] | AN: adc1_AN[6] | — | A |
| Y21 | GPIO | dramc ADD[15] | A0: siul_GPIO[173] A1: dramc_ADD[15] A2: ebi_AD7 A3: ebi_ADD23 | l: _ l: _ l: _ | — | disabled | D |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------------|--|----------------------|----------------------|------------------------|---------|
| Y22 | GPIO | dramc ADD[11] | A0: siul_GPIO[169] A1: dramc_ADD[11] A2: ebi_AD3 A3: ebi_ADD19 | I: _ I: _ I: _ | — | disabled | D |
| Y23 | GPIO | dramc ADD[5] | A0: siul_GPIO[163] A1: dramc_ADD[5] A2: ebi_ADD13 A3: flexpwm1_B[1] | I: _ I: _ I: _ | — | disabled | D |
| AA4 | GPIO | dspi1 CS3 | A0: siul_GPIO[55] A1: dspi1_CS3 A2: lin2_TXD A3: dspi0_CS4 | I: _ I: _ I: _ | — | disabled | GL M |
| AA5 | GPIO | flexpwm1 X[1] | A0: siul_GPIO[119] A1: flexpwm1_X[1] A2: etimer2_ETC[1] A3: dspi0_CS4 | I: _ I: _ I: _ | — | disabled | GL M |
| AA6 | ANA | adc3 AN[1] | — | siul_GPI[230] | AN: adc3_AN[1] | — | A |
| AA7 | ANA | adc2_adc3 AN[12] | — | siul_GPI[226] | AN: adc2_adc3_AN[12] | — | A S |
| AA8 | ANA | adc2 AN[0] | — | siul_GPI[221] | AN: adc2_AN[0] | — | A |
| AA11 | ANA | adc0 AN[2] | — | siul_GPI[33] | AN: adc0_AN[2] | — | A |
| AA12 | ANA | adc0 AN[5] | — | siul_GPI[66] | AN: adc0_AN[5] | — | A |
| AA13 | ANA | adc0 AN[8] | — | siul_GPI[69] | AN: adc0_AN[8] | — | A |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|---------------------|---|-----------------------------------|----------------------|------------------------|---------|
| AA14 | ANA | adc0_adc1 AN[12] | — | siul_GPI[26] | AN: adc0_adc1_AN[12] | — | A S |
| AA15 | ANA | adc1 AN[0] | — | siul_GPI[29] lin1_RXD | AN: adc1_AN[0] | — | A |
| AA16 | ANA | adc1 AN[2] | — | siul_GPI[31] siul_EIRQ[20] | AN: adc1_AN[2] | — | A |
| AA17 | ANA | adc1 AN[5] | — | siul_GPI[64] | AN: adc1_AN[5] | — | A |
| AA18 | ANA | adc1 AN[7] | — | siul_GPI[73] | AN: adc1_AN[7] | — | A |
| AA19 | GPIO | TDI | A0: siul_GPIO[21] A1: _ A2: _ A3: _ | l: jtagc_TDI l: _ l: _ | — | pullup | Gl M |
| AA20 | GPIO | etimer1 ETC[0] | A0: siul_GPIO[4] A1: etimer1_ETC[0] A2: _ A3: _ | l: _ l: _ l: siul_EIRQ[4] | — | disabled | Gl M |
| AA22 | GPIO | lin1 TXD | A0: siul_GPIO[94] A1: lin1_TXD A2: i2c1_clock A3: _ | l: _ l: _ l: _ | — | disabled | Gl M |
| AA23 | GPIO | dramc ADD[10] | A0: siul_GPIO[168] A1: dramc_ADD[10] A2: ebi_AD2 A3: ebi_ADD18 | l: _ l: _ l: _ | — | disabled | D |
| AB3 | GPIO | dspl2 SOUT | A0: siul_GPIO[12] A1: dspl2_SOUT A2: _ A3: _ | l: _ l: _ l: siul_EIRQ[11] | — | disabled | Gl M |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------|--|--------------------------|----------------------|------------------------|---------|
| AB4 | GPIO | flexpwm1_X[2] | A0: siul_GPIO[122] A1: flexpwm1_X[2] A2: etimer2_ETC[2] A3: dspio_CS5 | l: _ l: _ l: _ | — | disabled | Gl M |
| AB5 | GPIO | flexpwm1_X[3] | A0: siul_GPIO[125] A1: flexpwm1_X[3] A2: etimer2_ETC[3] A3: dspio_CS6 | l: _ l: _ l: _ | — | disabled | Gl M |
| AB6 | ANA | adc3_AN[2] | — | siul_GPI[231] | AN: adc3_AN[2] | — | A |
| AB7 | ANA | adc2_adc3_AN[13] | — | siul_GPI[227] | AN: adc2_adc3_AN[13] | — | A S |
| AB8 | ANA | adc2_AN[1] | — | siul_GPI[222] | AN: adc2_AN[1] | — | A |
| AB9 | ANA | adc2_AN[2] | — | siul_GPI[223] | AN: adc2_AN[2] | — | A |
| AB10 | ANA | adc0_AN[0] | — | siul_GPI[23] lin0_RXD | AN: adc0_AN[0] | — | A |
| AB11 | ANA | adc0_AN[4] | — | siul_GPI[70] | AN: adc0_AN[4] | — | A |
| AB12 | ANA | adc0_AN[6] | — | siul_GPI[71] | AN: adc0_AN[6] | — | A |
| AB13 | ANA | adc0_AN[7] | — | siul_GPI[68] | AN: adc0_AN[7] | — | A |
| AB14 | ANA | adc0_adc1_AN[13] | — | siul_GPI[27] | AN: adc0_adc1_AN[13] | — | A S |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|-------------|-----------|------------------|--|--|----------------|------------------------|---------|
| AB15 | ANA | adc1 AN[1] | — | siul_GPI[30] etimer0_ETC[4] siul_EIRQ[19] | AN: adc1_AN[1] | — | A |
| AB16 | ANA | adc1 AN[3] | — | siul_GPI[32] | AN: adc1_AN[3] | — | A |
| AB17 | ANA | adc1 AN[4] | — | siul_GPI[75] | AN: adc1_AN[4] | — | A |
| AB18 | GPIO | TDO | A0: siul_GPIO[20] A1: jtagc_TDO A2: _ A3: _ | I: _ I: _ I: _ | — | disabled | GI |
| AB21 | GPIO | lin1 RXD | A0: siul_GPIO[95] A1: _ A2: i2c1_data A3: _ | I: lin1_RXD I: _ I: _ | — | disabled | GI M |
| AC3 | GPIO | dspi2 SIN | A0: siul_GPIO[13] A1: _ A2: _ A3: _ | I: dspi2_SIN I: flexpwm0_FAULT[0] I: siul_EIRQ[12] | — | disabled | GI M |
| AC4 | GPIO | flexpwm1 A[3] | A0: siul_GPIO[126] A1: flexpwm1_A[3] A2: etimer2_ETC[4] A3: dspi0_CS7 | I: _ I: _ I: _ | — | disabled | GI M |
| AC5 | GPIO | flexpwm1 B[3] | A0: siul_GPIO[127] A1: flexpwm1_B[3] A2: etimer2_ETC[5] A3: _ | I: _ I: _ I: _ | — | disabled | GI M |
| AC6 | ANA | adc3 AN[3] | — | siul_GPI[232] | AN: adc3_AN[3] | — | GI M |
| AC9 | ANA | adc2 AN[3] | — | siul_GPI[224] | AN: adc2_AN[3] | — | A |

Table 10. 473 MAPBGA pin multiplexing (continued)

| Ball number | Ball type | Ball name | Alternate I/O | Additional Inputs | Analog Inputs | Weak pull during reset | Pa |
|---|-----------|---------------------|---------------|--------------------------------|----------------------|------------------------|--------|
| AC10 | ANA | adc0 AN[1] | — | siul_GPI[24] etimer0_ETC[5] | AN: adc0_AN[1] | — | A |
| AC11 | ANA | adc0 AN[3] | — | siul_GPI[34] | AN: adc0_AN[3] | — | A |
| AC14 | ANA | adc0_adc1 AN[14] | — | siul_GPI[28] | AN: adc0_adc1_AN[14] | — | A S |
| END OF 473 MAPBGA PIN MULTIPLEXING TABLE | | | | | | | |

¹ Do not connect pin directly to a power supply or ground.

3 Electrical characteristics

3.1 Introduction

This section contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications for this device.

The “Symbol” column of the electrical parameter and timings tables may contain an additional column containing “SR”, “CC”, “P”, “C”, “T”, or “D”.

- “SR” identifies system requirements—conditions that must be provided to ensure normal device operation. An example is the *input* voltage of a voltage regulator.
- “CC” identifies specifications that define normal device operation. Where available, the letters “P”, “C”, “T”, or “D” replace the letter “CC” and apply to these controller characteristics. They specify how each characteristic is guaranteed.
 - P: parameter is guaranteed by production testing of each individual device.
 - C: parameter is guaranteed by design characterization. Measurements are taken from a statistically relevant sample size across process variations.
 - T: parameter is guaranteed by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values are shown in the typical (“typ”) column are within this category.
 - D: parameters are derived mainly from simulations.

3.2 Absolute maximum ratings

Table 11. Absolute maximum ratings¹

| No. | Symbol | | Parameter | Conditions | Min | Max | Unit |
|-----|--------------------------------------|----|---|------------|------|---------------------|------|
| 1 | V _{DD_HV_PMU} | SR | Voltage regulator supply voltage | — | -0.3 | 5.5 ² | V |
| 2 | V _{SS_HV_PMU} | SR | Voltage regulator supply ground | — | -0.1 | 0.1 | V |
| 3 | V _{DD_HV_IO} | SR | Input/output supply voltage | — | -0.3 | 3.63 ^{3,4} | V |
| 4 | V _{SS_HV_IO} | SR | Input/output supply ground | — | -0.1 | 0.1 | V |
| 5 | V _{DD_HV_FL} | SR | Flash supply voltage | — | -0.3 | 3.63 ⁴ | V |
| 6 | V _{SS_HV_FL} | SR | Flash supply ground | — | -0.1 | 0.1 | V |
| 7 | V _{DD_HV_OSC} | SR | Crystal oscillator amplifier supply voltage | — | -0.3 | 3.63 ⁴ | V |
| 8 | V _{SS_HV_OSC} | SR | Crystal oscillator amplifier supply ground | — | -0.1 | 0.1 | V |
| 9 | V _{DD_HV_PDI} | SR | PDI interface supply voltage | — | -0.3 | 3.63 ⁴ | V |
| 10 | V _{SS_HV_PDI} | SR | PDI interface supply ground | — | -0.1 | 0.1 | V |
| 11 | V _{DD_HV_DRAM} ⁵ | SR | DRAM interface supply voltage | — | -0.3 | 3.63 ⁴ | V |
| 12 | V _{SS_HV_DRAM} | SR | DRAM interface supply ground | — | -0.1 | 0.1 | V |
| 13 | V _{DD_HV_ADRx} ⁶ | SR | ADCx high reference voltage | — | -0.3 | 6.0 | V |
| 14 | V _{SS_HV_ADRx} | SR | ADCx low reference voltage | — | -0.1 | 0.1 | V |
| 15 | V _{DD_HV_ADV} | SR | ADC supply voltage | — | -0.3 | 3.63 ^{3,4} | V |
| 16 | V _{SS_HV_ADV} | SR | ADC supply ground | — | -0.1 | 0.1 | V |
| 17 | V _{DD_LV_COR} | SR | Core supply voltage digital logic | — | -0.3 | 1.32 ⁷ | V |

Table 11. Absolute maximum ratings¹ (continued)

| No. | Symbol | | Parameter | Conditions | Min | Max | Unit |
|-----|------------------------|----|---|------------------------------------|------------------|---|-------|
| 18 | V _{SS_LV_COR} | SR | Core supply voltage ground digital logic | — | -0.1 | 0.1 | V |
| 19 | V _{DD_LV_PLL} | SR | PLL supply voltage | — | -0.3 | 1.32 | V |
| 20 | V _{SS_LV_PLL} | SR | PLL reference voltage | — | -0.1 | 0.1 | V |
| 21 | TV _{DD} | SR | Slope characteristics on all V _{DD} during power up | — | — | 25 | mV/μs |
| 22 | V _{IN} | SR | Voltage on any pin with respect to its supply rail V _{DD_HV_XXX} | Relative to V _{DD_HV_XXX} | -0.3 | V _{DD_HV_XXX} + 0.3 ⁸ | V |
| 23 | I _{INJPAD} | SR | Injected input current on any pin during overload condition | — | -10 | 10 | mA |
| 24 | I _{INJPADA} | SR | Injected input current on any analog pin during overload condition | — | -3 | 3 | mA |
| 25 | I _{INJSUM} | SR | Absolute sum of all injected input currents during overload condition | — | -50 | 50 | mA |
| 26 | T _{STG} | SR | Storage temperature | — | -55 ⁹ | 150 | °C |
| 27 | T _{SDR} | SR | Maximum Solder Temperature ¹⁰ Pb-free package SnPb package | — | — | 260 245 | °C |
| 28 | MSL | SR | Moisture Sensitivity Level ¹¹ | — | — | 3 | — |

¹ Functional operating conditions are given in the DC electrical characteristics. Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the listed maxima may affect device reliability or cause permanent damage to the device.

² 6.5 V for 10 hours cumulative time, 5.0 V + 10% for time remaining.

³ 5.3 V for 10 hours cumulative over lifetime of device, 3.63 V for time remaining.

⁴ Voltage overshoots during a high-to-low or low-to-high transition must not exceed 10 seconds per instance.

⁵ As the V_{DD_HV_DRAM_VREF} supply should always be constrained by the V_{DD_HV_DRAM} supply for example through a voltage divider network per the JEDEC specification, the maximum ratings for the V_{DD_HV_DRAM} supply should be used for the V_{DD_HV_DRAM_VREF} reference as well.

⁶ All V_{DD_HV_ADRx} rails must be operated at the same supply voltage.

⁷ 2.0 V for 10 hours cumulative time, 1.2 V + 10% for time remaining.

⁸ Only when V_{DD_HV_XXX} < 5.2 V.

⁹ If the ambient temperature is at or above the minimum storage temperature and below the recommended minimum operating temperature, power may be applied to the device safely. However, functionality is not guaranteed and a power cycle must be administered if in internal regulation mode or an assertion of RESET_SUP_B must be administered if in external regulation mode once device enters into the recommended operating temperature range.

¹⁰ Solder profile per CDF-AEC-Q100.

¹¹ Moisture sensitivity per JEDEC test method A112.

3.3 Recommended operating conditions

Table 12. Recommended operating conditions

| No. | Symbol | | Parameter | Conditions | Min | Max | Unit |
|-----|------------------------|----|----------------------------------|------------|-----|-----|------|
| 1 | V _{DD_HV_PMU} | SR | Voltage regulator supply voltage | — | 3.0 | 5.5 | V |

Table 12. Recommended operating conditions (continued)

| No. | Symbol | | Parameter | Conditions | Min | Max | Unit |
|-----|-------------------------|----|--|-------------------------|------|------|------|
| 2 | V _{SS_HV_PMU} | SR | Voltage regulator supply ground | — | 0 | 0 | V |
| 3 | V _{DD_HV_IO} | SR | Input/output supply voltage | — | 3.0 | 3.63 | V |
| 4 | V _{SS_HV_IO} | SR | Input/output supply ground | — | 0 | 0 | V |
| 5 | V _{DD_HV_FLA} | SR | Flash supply voltage | — | 3.0 | 3.63 | V |
| 6 | V _{SS_HV_FLA} | SR | Flash supply ground | — | 0 | 0 | V |
| 7 | V _{DD_HV_OSC} | SR | Crystal oscillator amplifier supply voltage | — | 3.0 | 3.63 | V |
| 8 | V _{SS_HV_OSC} | SR | Crystal oscillator amplifier supply ground | — | 0 | 0 | V |
| 9 | V _{DD_HV_PDI} | SR | PDI interface supply voltage | — | 1.62 | 3.63 | V |
| 10 | V _{SS_HV_PDI} | SR | PDI interface supply ground | — | 0 | 0 | V |
| 11 | V _{DD_HV_DRAM} | SR | DRAM interface supply voltage | — | 1.62 | 3.63 | V |
| 12 | V _{SS_HV_DRAM} | SR | DRAM interface supply ground | — | 0 | 0 | V |
| 13 | V _{DD_HV_ADRx} | SR | ADCx high reference voltage ¹ | — | 3.0 | 3.63 | V |
| | | | | Alternate input voltage | 4.5 | 5.5 | |
| 14 | V _{SS_HV_ADRx} | SR | ADCx low reference voltage | — | 0 | 0 | V |
| 15 | V _{DD_HV_ADV} | SR | ADC supply voltage | — | 3.0 | 3.63 | V |
| 16 | V _{SS_HV_ADV} | SR | ADC supply ground | — | 0 | 0 | V |
| 17 | V _{DD_LV_COR} | SR | Core supply voltage digital logic ² | External VREG mode | 1.14 | 1.32 | V |
| 17a | | CC | | Internal VREG Mode | 1.14 | 1.32 | V |
| 18 | V _{SS_LV_COR} | SR | Core supply voltage ground digital logic | — | 0 | 0 | V |
| 19 | V _{DD_LV_PLL} | SR | PLL supply voltage ² | External VREG mode | 1.14 | 1.32 | V |
| 19a | | CC | | Internal VREG Mode | 1.14 | 1.32 | V |
| 20 | V _{SS_LV_PLL} | SR | PLL reference voltage | — | 0 | 0 | V |
| 21 | T _A | SR | Ambient temperature under bias ^{3,4} | 257 MAPBGA | -40 | 125 | °C |
| | | | | 473 MAPBGA | -40 | 125 | |
| 22 | T _J | SR | Junction temperature under bias ⁴ | 257 MAPBGA | -40 | 150 | °C |
| | | | | 473 MAPBGA | -40 | 150 | |

¹ If this supply is not above its absolute minimum recommended operating level, LBIST operations can fail.

² The jitter specifications for both PLLs holds true only up to 50 mV noise (peak to peak) on V_{DD_LV_COR} and V_{DD_LV_PLL}.

³ See Table 1 for available frequency and package options.

⁴ When determining if the operating temperature specifications are met, either the ambient temperature or junction temperature specification can be used. It is not necessary that both specifications be met at all times. However, it is critical that the junction temperature specification is not exceeded under any condition.

3.4 Thermal characteristics

Table 13. Thermal characteristics for package options

| No. | Symbol | | Parameter | Conditions | Value | | Unit |
|-----|-------------------|----|--|---|---------|---------|------|
| | | | | | BGA 257 | BGA 473 | |
| 1 | R _{θJA} | CC | Thermal resistance junction-to-ambient natural convection ¹ | Single layer board – 1s | ≤ 40 | ≤ 34 | °C/W |
| 2 | R _{θJA} | CC | Thermal resistance junction-to-ambient natural convection ¹ | Four layer board – 2s2p | ≤ 22 | ≤ 20 | °C/W |
| 3 | R _{θJMA} | CC | Thermal resistance junction-to-moving-air ambient ¹ | @ 200 ft./min., single layer board – 1s | ≤ 32 | ≤ 26 | °C/W |
| 4 | R _{θJMA} | CC | Thermal resistance junction-to-moving-air ambient ¹ | @ 200 ft./min., four layer board – 2s2p | ≤ 18 | ≤ 17 | °C/W |
| 5 | R _{θJB} | CC | Thermal resistance junction-to-board ² | — | ≤ 10 | ≤ 10 | °C/W |
| 6 | R _{θJC} | CC | Thermal resistance junction-to-case ³ | — | ≤ 6 | ≤ 6 | °C/W |
| 7 | Ψ _{JT} | CC | Junction-to-package-top natural convection ⁴ | — | ≤ 2 | ≤ 2 | °C/W |

¹ Junction-to-Ambient thermal resistance determined per JEDEC JESD51-3 and JESD51-6. Thermal test board meets JEDEC specification for this package.

² Junction-to-Board thermal resistance determined per JEDEC JESD51-8. Thermal test board meets JEDEC specification for the specified package.

³ Junction-to-Case at the top of the package determined using MIL-STD 883 Method 1012.1. The cold plate temperature is used for the case temperature. Reported value includes the thermal resistance of the interface layer.

⁴ Thermal characterization parameter indicating the temperature difference between the package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written as Psi-JT.

3.4.1 General notes for specifications at maximum junction temperature

An estimation of the chip junction temperature, T_J, can be obtained from Equation 1:

$$T_J = T_A + (R_{\theta JA} \times P_D) \quad \text{Eqn. 1}$$

where:

T_A = ambient temperature for the package (°C)

R_{θJA} = junction to ambient thermal resistance (°C/W)

P_D = power dissipation in the package (W)

The junction to ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. Unfortunately, there are two values in common usage: the value determined on a single layer board and the value obtained on a board with two planes. For packages such as the PBGA, these values can be different by a factor of two. Which value is closer to the application depends on the power dissipated by other components on the board. The value obtained on a single layer board is appropriate for the tightly packed printed circuit board. The value obtained on the board with the internal planes is usually appropriate if the board has low power dissipation and the components are well separated.

When a heat sink is used, the thermal resistance is expressed in Equation 2 as the sum of a junction to case thermal resistance and a case to ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA} \quad \text{Eqn. 2}$$

where:

$R_{\theta JA}$ = junction to ambient thermal resistance ($^{\circ}\text{C}/\text{W}$)

$R_{\theta JC}$ = junction to case thermal resistance ($^{\circ}\text{C}/\text{W}$)

$R_{\theta CA}$ = case to ambient thermal resistance ($^{\circ}\text{C}/\text{W}$)

$R_{\theta JC}$ is device related and cannot be influenced by the user. The user controls the thermal environment to change the case to ambient thermal resistance, $R_{\theta CA}$. For instance, the user can change the size of the heat sink, the air flow around the device, the interface material, the mounting arrangement on printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device.

To determine the junction temperature of the device in the application when heat sinks are not used, the Thermal Characterization Parameter (Ψ_{JT}) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using Equation 3:

$$T_J = T_T + (\Psi_{JT} \times P_D) \quad \text{Eqn. 3}$$

where:

T_T = thermocouple temperature on top of the package ($^{\circ}\text{C}$)

Ψ_{JT} = thermal characterization parameter ($^{\circ}\text{C}/\text{W}$)

P_D = power dissipation in the package (W)

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

See [6] to [10] in Section 6, Reference documents, for more information.

3.5 Electromagnetic interference (EMI) characteristics

3.5.1 Test Setup

Electromagnetic emission tests are performed by TEM cell [2] and via direct coupling [3] (150 Ω) measurements.

Electromagnetic immunity is measured by DPI [4].

See Section 6, Reference documents, for more information.

3.5.2 Test parameters

The following test parameters shall be used:

Table 14. EMC test parameters

| Method | Frequency Range | Receiver | |
|--------------|-------------------|----------|-----------|
| | | BW | Step Size |
| 150 Ω | 1 MHz to 1000 MHz | 1 MHz | 500 kHz |
| TEM | | | |

Electrical characteristics

In case of only narrow band disturbances the maximum of the results will not change. In case of broadband signals the emission has to be below the limits.

3.6 Electrostatic discharge (ESD) characteristics

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts \times ($n + 1$) supply pin). This test conforms to the AEC-Q100-002/-003/-011 standard.

Table 15. ESD ratings^{1, 2}

| No. | Symbol | | Parameter | Conditions | Class | Max value ³ | Unit |
|-----|----------------|----|--|--|-------|------------------------|------|
| 1 | $V_{ESD(HBM)}$ | SR | Electrostatic discharge (Human Body Model) | $T_A = 25\text{ }^\circ\text{C}$ conforming to AEC-Q100-002 | H1C | 2000 | V |
| 2 | $V_{ESD(MM)}$ | SR | Electrostatic discharge (Machine Model) | $T_A = 25\text{ }^\circ\text{C}$ conforming to AEC-Q100-003 | M2 | 200 | V |
| 3 | $V_{ESD(CDM)}$ | SR | Electrostatic discharge (Charged Device Model) | $T_A = 25\text{ }^\circ\text{C}$ conforming to AEC-Q100-011 | C3A | 750 (corners) | V |
| | | | | | | 500 | |

¹ All ESD testing is in conformity with CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.

² A device will be defined as a failure if after exposure to ESD pulses the device no longer meets the device specification requirements. Complete DC parametric and functional testing shall be performed per applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

³ Data based on characterization results, not tested in production.

3.7 Static latch-up (LU)

Two complementary static tests are required on six parts to assess the latch-up performance:

- A supply over voltage is applied to each power supply pin.
- A current injection is applied to each input, output and configurable I/O pin.

These tests are compliant with the EIA/JESD 78 IC latch-up standard.

Table 16. Latch-up results

| No. | Symbol | | Parameter | Conditions | Class |
|-----|--------|----|-----------------------|---|------------|
| 1 | LU | CC | Static latch-up class | $T_A = 125\text{ }^\circ\text{C}$ conforming to JESD 78 | II level A |

3.8 Power Management Controller (PMC) electrical characteristics

3.8.1 PMC electrical specifications

This section contains electrical characteristics for the PMC.

Table 17. PMC electrical specifications

| No. | Symbol | | Parameter | Min | Typ | Max | Unit |
|-----|------------------------|----|---|---|---|---|---|
| 1 | V _{DD_LV_COR} | CC | Nominal V _{RC} regulated 1.2 V output V _{DD_LV_COR} V _{rc} after reset 1.2V output with DC load | — 1.178 | 1.24 1.240 | — 1.302 | V |
| 2 | PorC | CC | POR rising V _{DD} 1.2 V • POR V _{DD} variation • POR 1.2 V hysteresis | — PorC – 30% — | 0.7 PorC 75 | — PorC + 30% — | V V mV |
| 3 | LvdC | CC | Nominal LVD 1.2 V • LVD rising supply 1.2V after reset • LVD rising supply 1.2V at reset • LVD falling supply 1.2V after reset • LVD falling supply 1.2V at reset | — 1.125 1.17 1.110 1.155 | 1.16 1.16 1.215 1.145 1.2 | — 1.195 1.26 1.18 1.245 | V V V V V |
| 4 | HvdC | CC | Nominal HVD 1.2 V • HVD rising supply 1.2V after reset • HVD rising supply 1.2V at reset • HVD falling supply 1.2V after reset • HVD falling supply 1.2V at reset | — 1.32 1.38 1.29 1.35 | 1.36 1.36 1.44 1.33 1.41 | — 1.4 1.5 1.37 1.47 | V V V V V |
| 5 | PorReg | CC | POR rising on V _{DDREG} • POR V _{DDREG} variation • POR V _{DDREG} hysteresis | — PorReg – 30% — | 2.00 PorReg 250 | — PorReg + 30% — | V V mV |
| 6 | LvdReg | CC | Nominal rising LVD 3.3 V on V _{DDREG} , V _{DDIO} , V _{DDFLASH} , and V _{DDADC} • LVD 3.3 V rising supply after reset • LVD 3.3 V rising supply at reset • LVD 3.3 V falling supply after reset • LVD 3.3 V falling supply at reset • Minimum slew rate • Maximum slew rate | — 2.78 2.765 2.75 2.735 — — | 2.865 2.865 2.865 2.835 2.835 50 25 | — 2.95 2.965 2.92 2.935 — — | V V V V V mV/ms mV/μs |
| 7 | LvdStepReg | CC | Trimming step LVD 3.3 V | — | 30 | — | mV |
| 8 | V _{adctol} | CC | Voltage tolerance of PMC channels ¹ | -20 | — | +20 | mV |

¹ This tolerance can only be achieved when adhering to the PMC internal channel sample time requirements listed in the ADC specifications section.

3.8.2 PMC board schematic and components

Figure 7 shows a sample application for the PMC.

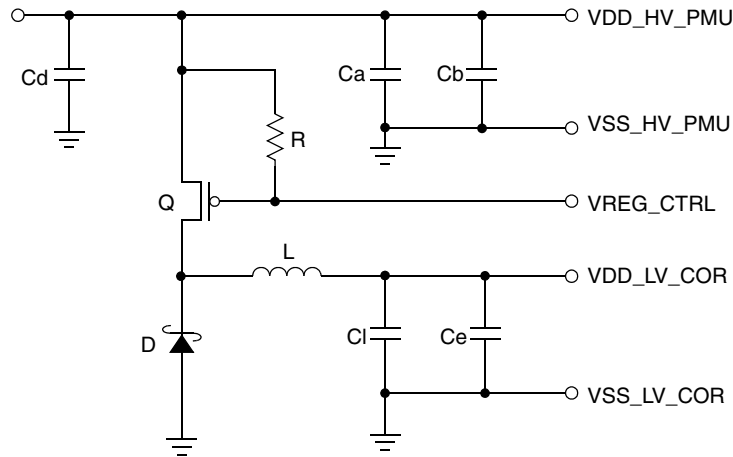


Figure 7. PMU mandatory external components

Table 18. VRC SMPS recommended external devices

| Reference designator | Part description | Part type | Nominal | Description |
|----------------------|---------------------------------|-----------|-------------------|---|
| Ca | — | capacitor | 20 μ F, 20 V | Filter capacitor |
| Cb | — | capacitor | 0.1 μ F, 20 V | Filter capacitor |
| Cd | — | capacitor | 20 μ F, 20 V | Supply decoupling cap, ESR < 50 m Ω , as close to PMOS source as possible |
| Ce | — | capacitor | 0.1 μ F, 16 V | Ceramic |
| Cl | — | capacitor | 20 μ F, 16 V | Buck capacitor, total ESR < 100 m Ω , as close to the coil as possible |
| D | SS8P3L | Schottky | — | Vishay low Vf Schottky diode |
| L | — | inductor | 4 μ H, 1.5 A | Buck shielded coil low ESR |
| Q | FDC642P or SQ2301ES or SI3443DV | pMOS | 2 A, 10 V | Low threshold PMOS $V_{th} < 1.5$ V, $R_{dson}@4.5\text{ V} < 120$ m Ω , $Q_g < 16$ nC |
| R | — | resistor | 50–100 k Ω | Pullup for power PMOS gate |

3.9 Supply current characteristics

Table 19. Current consumption characteristics¹

| No. | Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----|-------------------|--|--|-----|-----|-----|------|
| 1 | I_{DD_LV} | CC Maximum run I_{DD} (incl. digital core logic and analog block of the LV rail) | $V_{DD_LV} = 1.36$ V, $f_{Core} = 180$ MHz, 1:2 mode, DPM, both cores executing EMC test code, internal VREG mode, all caches enabled, code execution of core 0 from code flash 0, code execution of core 1 from code flash 1, FMPLL_1 active at 120 MHz. | — | 600 | 900 | mA |
| 2 | $I_{DD_LV_PLL}$ | CC Maximum run I_{DD} for each PLL ² | $V_{DD_LV_PLL} = 1.36$ V, f_{VCO} running at maximum frequency. | — | 1.5 | 2 | mA |

Table 19. Current consumption characteristics¹ (continued)

| No. | Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----|---------------------------------------|--|--|-----|-----|-----|------|
| 3 | I _{DD_HV_FLA} ³ | CC Maximum run I _{DD} Flash | V _{DD_HV_FLA} = 3.6 V, DPM, both cores executing EMC test code, code execution of core 0 from code flash 0, code execution of core 1 from code flash 1. | — | 20 | 30 | mA |
| 4 | I _{DD_HV_OSC} | CC Maximum run I _{DD} OSC | f _{OSC} 4 MHz to 40 MHz, V _{DD_HV_OSC} 3.6 V | — | 1 | 3 | mA |
| 5 | I _{DD_HV_ADV} | CC Maximum run I _{DD} for each ADC ⁴ | V _{DD_HV_ADV} = 3.6 V | — | 2 | 4 | mA |
| 6 | I _{DD_HV_ADR02} ⁵ | CC Maximum reference I _{DD} ⁶ | ADC0 powered on ⁷ | — | — | 2 | mA |
| | | | ADC2 powered on | — | — | 1.2 | mA |
| 7 | I _{DD_HV_ADR13} ⁵ | CC Maximum reference I _{DD} ⁶ | ADC1 powered on | — | — | 1.2 | mA |
| | | | ADC3 powered on | — | — | 1.2 | mA |
| 8 | I _{DD_HV_ADR0} ⁸ | CC Maximum reference I _{DD} | ADC0 powered on ⁷ | — | — | 2 | mA |
| 9 | I _{DD_HV_ADR1} ⁸ | CC Maximum reference I _{DD} | ADC1 powered on | — | — | 1.2 | mA |
| 10 | I _{DD_HV_ADR23} ⁸ | CC Maximum reference I _{DD} ⁶ | ADC2 powered on | — | — | 1.2 | mA |
| | | | ADC3 powered on | — | — | 1.2 | mA |

¹ Applies to T_J = -40 °C to 150 °C.

² Total current on I_{DD_LV_PLL} needs to be multiplied with the number of active PLLs.

³ The current specified for I_{DD_HV_FLA} includes current consumed during programming and erase operations.

⁴ Total current on I_{DD_HV_ADV} needs to be multiplied with the number of active ADCs.

⁵ 257 MAPBGA only.

⁶ Total current on I_{DD_HV_ADRxx} is the sum of both references if both ADCs are powered on.

⁷ ADC0 includes 0.7 mA dissipation for the temperature sensor (TSENS).

⁸ 473 MAPBGA only.

3.10 Temperature sensor electrical characteristics

Table 20. Temperature sensor electrical characteristics

| | Symbol | Parameter | Conditions | Min | Max | Unit |
|---|----------------|---------------------------|--|-----|-----|------|
| 1 | — | P Accuracy | T _J = -40 °C to T _A = 125 °C | -10 | 10 | °C |
| 2 | T _S | D Minimum sampling period | — | 4 | — | μs |

3.11 Main oscillator electrical characteristics

The MPC5675K provides an oscillator/resonator driver.

Table 21. Main oscillator electrical characteristics

| No. | Symbol | Parameter | Conditions ¹ | Value | | | Unit | |
|-----|-----------------------|-----------|---------------------------------------|-------------------------------------|------------------------|-----|------------------------|----|
| | | | | Min | Typ | Max | | |
| 1 | F _{XOSCHS} | SR | Oscillator frequency | — | — | — | MHz | |
| 2a | T _{XOSCHSSU} | CC | Oscillator start-up time | f _{OSC} < 16 MHz | — | 6 | 10 | ms |
| 2b | | | | f _{OSC} = 16 MHz to 40 MHz | — | 2 | 4 | |
| 3 | V _{IH} | SR | Input high level CMOS Schmitt Trigger | Oscillator bypass mode | 0.65 × V _{DD} | — | V _{DD} + 0.4 | V |
| 4 | V _{IL} | SR | Input low level CMOS Schmitt Trigger | Oscillator bypass mode | −0.4 | — | 0.35 × V _{DD} | V |

¹ V_{DD} = 3.0 V to 3.6 V, T_J = −40 to 150 °C, unless otherwise specified.

3.12 FMPLL electrical characteristics

Table 22. FMPLL electrical characteristics

| No. | Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|-----|--|-----------|--|---|-----|-----|----------------------|-----|
| 1 | f _{REF_CRYSTAL} f _{REF_EXT} | D | FMPLL reference frequency range ^{1, 2} | Crystal reference | 4 | — | 120 | MHz |
| 2 | f _{PLL_IN} | D | Phase detector input frequency range (after pre-divider) | — | 4 | — | 16 | MHz |
| 3 | f _{FMPLLOUT} | D | Clock frequency range in normal mode | See the FMPLL chapter in the chip reference manual for more details on PLL configuration. | 16 | — | 256 | MHz |
| 4 | f _{FREE} | P | Free running frequency | Measured using clock division (typically ±16) | 19 | — | 60 | MHz |
| 5 | f _{sys} | D | On-chip FMPLL frequency ² | — | — | — | 180 | MHz |
| 6 | t _{CYC} | D | System clock period | — | — | — | 1 / f _{sys} | ns |
| 7a | f _{LORL} | D | Loss of reference frequency window ³ | Lower limit | 1.6 | — | 3.7 | MHz |
| 7b | f _{LORH} | | | Upper limit | 24 | — | 56 | |
| 8 | f _{SCM} | D | Self-clocked mode frequency ^{4,5} | — | 20 | — | 150 | MHz |
| 9 | t _{LOCK} | P | Lock time | Stable oscillator (f _{PLLIN} = 4 MHz), stable V _{DD} | — | — | 200 | μs |
| 10 | t _{pll} | D | FMPLL lock time ^{6, 7} | — | — | — | 200 | μs |
| 11 | t _{dc} | D | Duty cycle of reference | — | 20 | — | 80 | % |
| 12a | C _{JITTER} | T | CLKOUT period jitter ^{8,9,10,11} | Peak-to-peak (clock edge to clock edge), f _{FMPLLOUT} maximum ¹² | — | — | 160 | ps |
| 12b | | | | Long-term jitter (avg. over 2 ms interval), f _{FMPLLOUT} maximum | — | — | 6 | |
| 13 | Δt _{PKJIT} | T | Single period jitter (peak to peak) | PHI @ 16 MHz, Input clock @ 4 MHz | — | — | ±500 | ps |

Table 22. FMPLL electrical characteristics (continued)

| No. | Symbol | | Parameter | Conditions | Min | Typ | Max | Unit |
|-----|--------------------|---|------------------------------------|--------------------------------------|------------|-----|------------------------|---------------------|
| 14 | Δt_{LTJIT} | T | Long term jitter | PHI @ 16 MHz, Input clock @ 4 MHz | — | — | ± 6 | ns |
| 15 | f_{LCK} | D | Frequency LOCK range | — | -4 | — | +4 | % $f_{FMPLLOUT}$ |
| 16 | f_{UL} | D | Frequency un-LOCK range | — | -16 | — | +16 | % $f_{FMPLLOUT}$ |
| 17a | f_{CS} | D | Modulation Depth | Center spread | ± 0.25 | — | ± 4 | % $f_{FMPLLOUT}$ |
| 17b | f_{DS} | | | Down Spread | -0.5 | — | -8 | |
| 18 | f_{MOD} | D | Modulation frequency ¹³ | $31 < LDF^{14} < 63$ $LDF > 63$ | — | — | $(2240/LD$ F) 35 | kHz |

¹ Considering operation with FMPLL not bypassed.

² PFD clock range is 4– 16 MHz. An appropriate PLL Input division factor (IDF) should be chosen to divide the reference frequency to this range.

³ “Loss of Reference Frequency” window is the reference frequency range outside of which the FMPLL is in self clocked mode.

⁴ Self clocked mode frequency is the frequency that the FMPLL operates at when the reference frequency falls outside the f_{LOR} window.

⁵ f_{VCO} is the frequency at the output of the VCO; its range is 256–512 MHz.

f_{SCM} is the self-clocked mode frequency (free running frequency); its range is 20–150 MHz.

$f_{sys} = f_{VCO} \div ODF$

⁶ This value is determined by the crystal manufacturer and board design. For 4 MHz to 20 MHz crystals specified for this FMPLL, load capacitors should not exceed these limits.

⁷ This specification applies to the period required for the FMPLL to relock after changing the MFD frequency control bits in the synthesizer control register (SYNCR).

⁸ This value is determined by the crystal manufacturer and board design.

⁹ Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum $f_{FMPLLOUT}$. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the FMPLL circuitry via V_{DDPLL} and V_{SSPLL} and variation in crystal oscillator frequency increase the C_{JITTER} percentage for a given interval.

¹⁰ Proper PC board layout procedures must be followed to achieve specifications.

¹¹ Values are with frequency modulation disabled. If frequency modulation is enabled, jitter is the sum of C_{JITTER} and either f_{CS} or f_{DS} (depending on whether center spread or down spread modulation is enabled).

¹² Core operating at 180 MHz.

¹³ Modulation depth is attenuated from depth setting when operating at modulation frequencies above 50 kHz.

¹⁴ PLL Loop Division Factor (LDF).

3.13 16 MHz RC oscillator electrical characteristics

Table 23. RC oscillator electrical characteristics

| No. | Symbol | | Parameter | Conditions | Min | Typ | Max | Unit |
|-----|-------------------|----|---|----------------------|-----|-----|---------|------|
| 1 | f_{RC} | CC | RC oscillator frequency | 25 °C, 1.2 V trimmed | — | 16 | — | MHz |
| 2 | Δ_{RCMVAR} | CC | Frequency spread: The variation in output frequency from PTF ¹ across temperature and supply voltage range | — | — | — | ± 5 | % |

Table 23. RC oscillator electrical characteristics (continued)

| No. | Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----|-----------------------|--------------------------------------|----------------------------------|-----|-----|-----|------|
| 3 | $\Delta_{IRCTRIM}$ CC | Internal RC oscillator trimming step | $T_A = 25\text{ }^\circ\text{C}$ | — | 1.6 | — | % |

¹ PTF = Post Trimming Frequency: The frequency of the output clock after trimming at typical supply voltage and temperature.

3.14 ADC electrical characteristics

The MPC5675K provides a 12-bit Successive Approximation Register (SAR) Analog-to-Digital Converter.

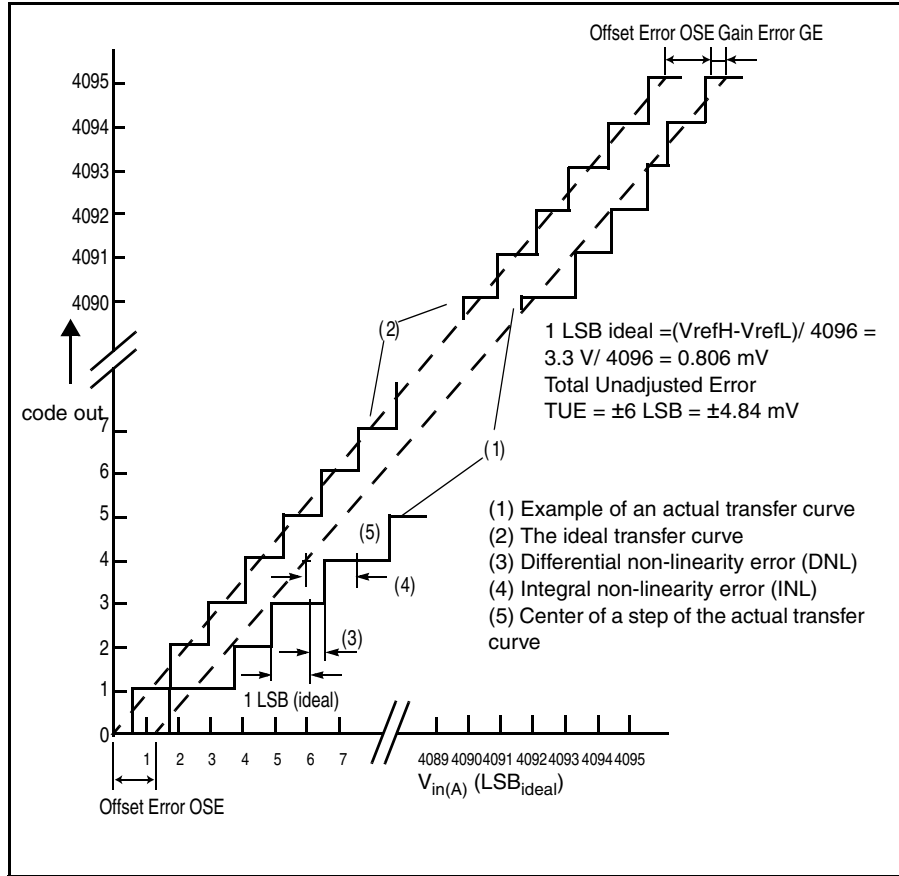


Figure 8. ADC characteristics and error definitions

3.14.1 Input impedance and ADC accuracy

To preserve the accuracy of the A/D converter, it is necessary that analog input pins have low AC impedance. Placing a capacitor with good high frequency characteristics at the input pin of the device can be effective: the capacitor should be as large as possible, ideally infinite. This capacitor contributes to attenuating the noise present on the input pin; further, it sources charge during the sampling phase, when the analog signal source is a high-impedance source.

A real filter can typically be obtained by using a series resistance with a capacitor on the input pin (simple RC filter). The RC filtering may be limited according to the value of source impedance of the transducer or circuit supplying the analog signal to be measured. The filter at the input pins must be designed taking into account the dynamic characteristics of the input signal (bandwidth) and the equivalent input impedance of the ADC itself.

In fact a current sink contributor is represented by the charge sharing effects with the sampling capacitance: C_S and C_{P2} being substantially a switched capacitance, with a frequency equal to the conversion rate of the ADC, it can be seen as a resistive path to ground. For instance, assuming a conversion rate of 1 MHz, with C_S equal to 3 pF, a resistance of 330 k Ω is obtained ($R_{EQ} = 1 / (f_C \times C_S)$, where f_C represents the conversion rate at the considered channel). To minimize the error induced by the voltage partitioning between this resistance (sampled voltage on C_S) and the sum of $R_S + R_F$, the external circuit must be designed to respect Equation 4:

$$V_A \cdot \frac{R_S + R_F}{R_{EQ}} < \frac{1}{2} \text{LSB} \tag{Eqn. 4}$$

Equation 4 generates a constraint for external network design, in particular on resistive path. Internal switch resistances (R_{SW} and R_{AD}) can be neglected with respect to external resistances.

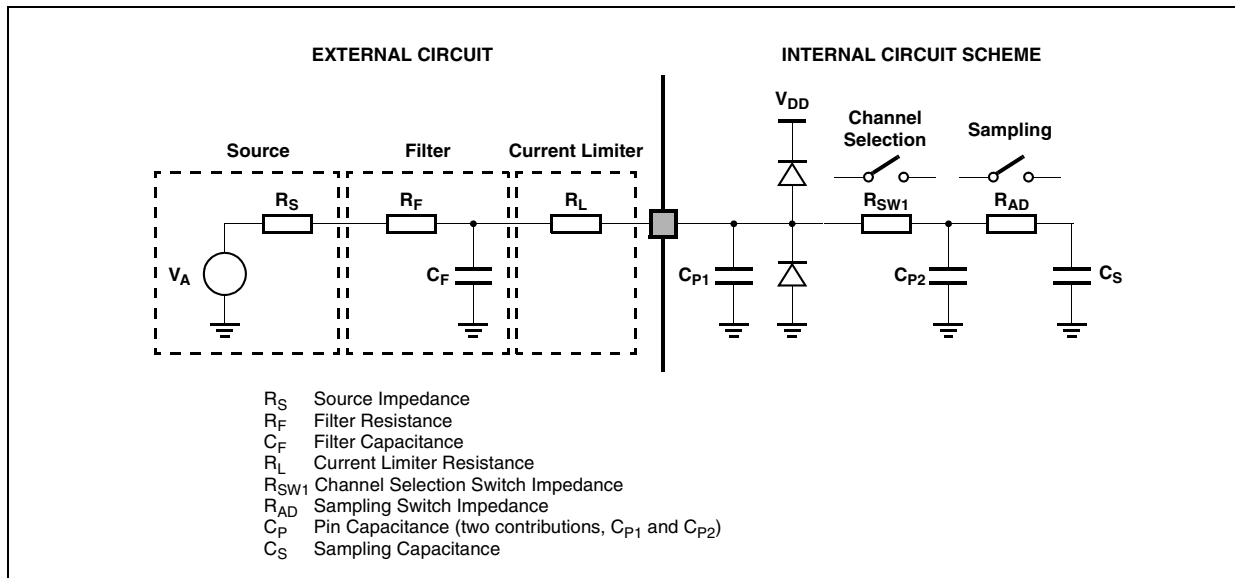


Figure 9. Input equivalent circuit

A second aspect involving the capacitance network shall be considered. Assuming the three capacitances C_F , C_{P1} , and C_{P2} are initially charged at the source voltage V_A (please see the equivalent circuit in Figure 9): A charge sharing phenomenon is installed when the sampling phase is started (A/D switch is closed).

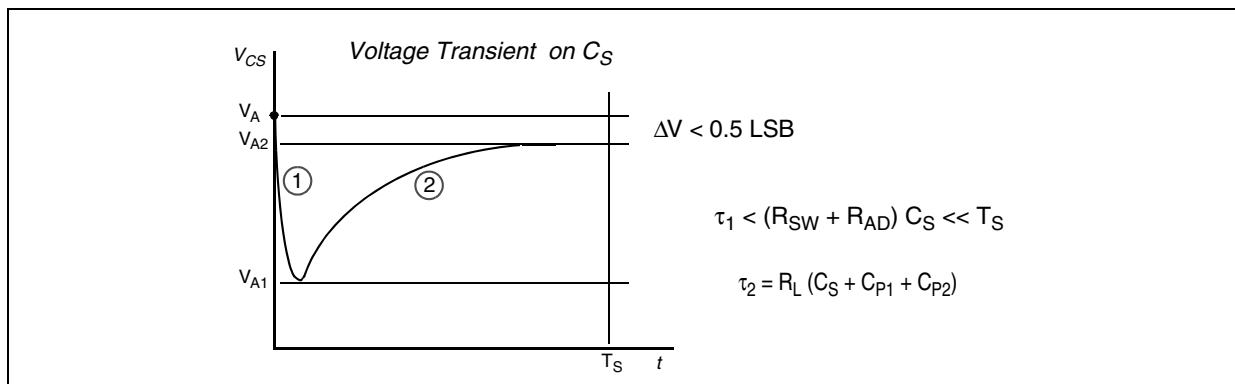


Figure 10. Transient behavior during sampling phase

In particular two different transient periods can be distinguished:

Electrical characteristics

- A first and quick charge transfer from the internal capacitance C_{P1} and C_{P2} to the sampling capacitance C_S occurs (C_S is supposed initially completely discharged): considering a worst case (since the time constant in reality would be faster) in which C_{P2} is reported in parallel to C_{P1} (call $C_P = C_{P1} + C_{P2}$), the two capacitances C_P and C_S are in series, and the time constant is:

$$\tau_1 = (R_{SW} + R_{AD}) \cdot \frac{C_P \cdot C_S}{C_P + C_S} \quad \text{Eqn. 5}$$

Equation 5 can again be simplified considering only C_S as an additional worst condition. In reality, the transient is faster, but the A/D converter circuitry has been designed to be robust also in the very worst case: the sampling time T_S is always much longer than the internal time constant:

$$\tau_1 < (R_{SW} + R_{AD}) \cdot C_S \ll T_S \quad \text{Eqn. 6}$$

The charge of C_{P1} and C_{P2} is redistributed also on C_S , determining a new value of the voltage V_{A1} on the capacitance according to Equation 7:

$$V_{A1} \cdot (C_S + C_{P1} + C_{P2}) = V_A \cdot (C_{P1} + C_{P2}) \quad \text{Eqn. 7}$$

- A second charge transfer involves also C_F (that is typically bigger than the on-chip capacitance) through the resistance R_L : again considering the worst case in which C_{P2} and C_S were in parallel to C_{P1} (since the time constant in reality would be faster), the time constant is:

$$\tau_2 < R_L \cdot (C_S + C_{P1} + C_{P2}) \quad \text{Eqn. 8}$$

In this case, the time constant depends on the external circuit: in particular imposing that the transient is completed well before the end of sampling time T_S , a constraints on R_L sizing is obtained:

$$10 \cdot \tau_2 = 10 \cdot R_L \cdot (C_S + C_{P1} + C_{P2}) < T_S \quad \text{Eqn. 9}$$

Of course, R_L shall be sized also according to the current limitation constraints, in combination with R_S (source impedance) and R_F (filter resistance). Being C_F definitively bigger than C_{P1} , C_{P2} and C_S , then the final voltage V_{A2} (at the end of the charge transfer transient) will be much higher than V_{A1} . Equation 10 must be respected (charge balance assuming now C_S already charged at V_{A1}):

$$V_{A2} \cdot (C_S + C_{P1} + C_{P2} + C_F) = V_A \cdot C_F + V_{A1} \cdot (C_{P1} + C_{P2} + C_S) \quad \text{Eqn. 10}$$

The two transients above are not influenced by the voltage source that, due to the presence of the $R_F C_F$ filter, is not able to provide the extra charge to compensate the voltage drop on C_S with respect to the ideal source V_A ; the time constant $R_F C_F$ of the filter is very high with respect to the sampling time (T_S). The filter is typically designed to act as anti-aliasing.

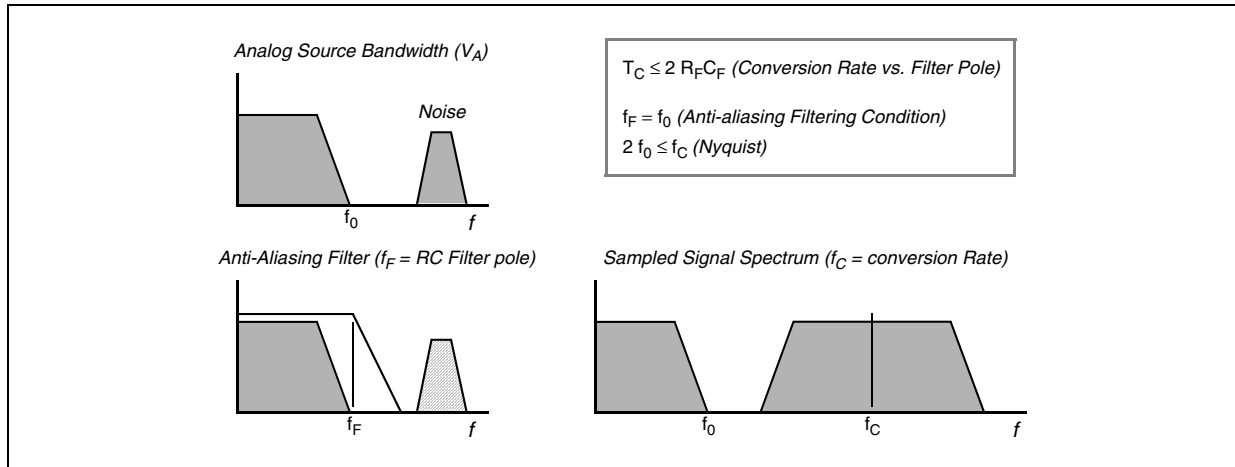


Figure 11. Spectral representation of input signal

Calling f_0 the bandwidth of the source signal (and as a consequence the cut-off frequency of the anti-aliasing filter, f_F), according to the Nyquist theorem the conversion rate f_C must be at least $2f_0$; it means that the constant time of the filter is greater than or at least equal to twice the conversion period (T_C). Again the conversion period T_C is longer than the sampling time T_S , which is just a portion of it, even when fixed channel continuous conversion mode is selected (fastest conversion rate at a specific channel): in conclusion it is evident that the time constant of the filter $R_F C_F$ is definitively much higher than the sampling time T_S , so the charge level on C_S cannot be modified by the analog signal source during the time in which the sampling switch is closed.

The considerations above lead to impose new constraints on the external circuit, to reduce the accuracy error due to the voltage drop on C_S ; from the two charge balance equations above, it is simple to derive Equation 11 between the ideal and real sampled voltage on C_S :

Eqn. 11

$$\frac{V_{A2}}{V_A} = \frac{C_{P1} + C_{P2} + C_F}{C_{P1} + C_{P2} + C_F + C_S}$$

From this formula, in the worst case (when V_A is maximum, that is for instance 5 V), assuming to accept a maximum error of half a count, a constraint is evident on C_F value:

$$C_F > 8192 \cdot C_S$$

Eqn. 12

Table 24. ADC conversion characteristics

| No. | Symbol | | Parameter | Conditions ¹ | Min | Typ | Max | Unit |
|-----|-------------------|----|--|-------------------------|-----|-----|-----|------|
| 1 | f_{CK} | SR | ADC clock frequency (depends on ADC configuration) (The duty cycle depends on AD_CK ² frequency) | — | 3 | — | 60 | MHz |
| 2 | f_s | SR | Sampling frequency | — | — | — | 959 | kHz |
| 3 | t_{ADC_S} | D | Sample time ³ | 60 MHz | 383 | — | — | ns |
| 4 | $t_{ADC_S_PMC}$ | C | Sample time of internal PMC channels. | — | 717 | — | — | ns |
| 5 | t_{ADC_E} | P | Evaluation time ⁴ | 60 MHz | 600 | — | — | ns |

Table 24. ADC conversion characteristics (continued)

| No. | Symbol | | Parameter | Conditions ¹ | Min | Typ | Max | Unit |
|-----|------------------------|---|---|---|------|-----|------|------------|
| 6 | C_S ⁵ | D | ADC input sampling capacitance | — | — | — | 7.32 | pF |
| 7 | C_{P1} ⁵ | D | ADC input pin capacitance 1 | — | — | — | 2.5 | pF |
| 8 | C_{P2} ⁵ | D | ADC input pin capacitance 2 | — | — | — | 0.8 | pF |
| 9 | R_{SW1} ⁵ | D | Channel selection switch resistance | V_{REF} range = 4.5 to 5.5 V | — | — | 1.0 | k Ω |
| 10 | | | | V_{REF} range = 3.0 to 3.6 V | — | — | 1.2 | k Ω |
| 11 | R_{AD} ⁵ | D | Sample switching resistance | — | — | — | 825 | Ω |
| 12 | I_{INJ} | T | Current injection | Current injection on one ADC input channel, different from the converted one. Other parameters stay within specified limits as long as the ADC supply stays within its specified limits due to the current injection. | -3 | — | 3 | mA |
| 13 | INL | P | Integral non linearity | — | -3 | — | 3 | LSB |
| 14 | DNL | P | Differential non linearity ⁶ | — | -1.0 | — | 2 | LSB |
| 15 | OFS | T | Offset error | — | -4 | — | 4 | LSB |
| 16 | GNE | T | Gain error | — | -4 | — | 4 | LSB |
| 17 | TUE ⁷ | P | Total unadjusted error | — | -6 | — | 6 | LSB |
| 18 | TUE ⁷ | T | Total unadjusted error with current injection | — | -6 | — | 6 | LSB |
| 19 | SNR | T | Signal-to-noise ratio | — | 69 | — | — | dB |
| 20 | THD | T | Total harmonic distortion | — | -72 | — | — | dB |
| 21 | SINAD | T | Signal-to-noise and distortion | — | 65 | — | — | dB |
| 22 | ENOB | T | Effective number of bits | — | 10.5 | — | — | bits |

¹ $V_{DD} = 3.3$ V, $T_J = -40$ to $+150$ °C, unless otherwise specified and analog input voltage from V_{AGND} to V_{AREF}

² AD_CK clock is always half of the ADC module input clock defined via the auxiliary clock divider for the ADC.

³ During the sample time the input capacitance C_S can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within t_{ADC_S} . After the end of the sample time t_{ADC_S} , changes of the analog input voltage have no effect on the conversion result. Values for the sample clock t_{ADC_S} depend on programming.

⁴ This parameter does not include the sample time t_{ADC_S} , but only the time for determining the digital result and the time to load the result register with the conversion result.

⁵ See Figure 9.

⁶ No missing codes.

⁷ When operating the MPC5675K in a switched mode power supply configuration, the specifications for the ADCs under worst case conditions can be upheld only through the use of averaging back-to-back samples. In the 257 package, 10 samples must be averaged when using ADC 0, 2, or 3. In the 473 package, 5 samples must be averaged. For ADC 1, due to its close proximity to the PMC, the TUE spec must be increased to +/-10 counts, 10 samples of averaging must be used in both packages, and the $V_{DD_HV_PMU}$ supply must be below 3.6 V. Better performance can be obtained with lower $V_{DD_HV_PMU}$ supplies and higher $V_{DD_HV_ADRx}$ supplies. The ADC1 self test limit for the S2 algorithm needs to be modified by the user to accommodate for the increased TUE limit of +/-10 counts when operating the device in internal regulation mode. This can be accomplished by reading the current value from the test flash and subtracting 4 counts before storing the value to the ADC1 Self Test Analog Watchdog Register 2 (STAW2R).

3.15 Flash memory electrical characteristics

3.15.1 Program/erase characteristics

Table 25 shows the code flash memory program and erase characteristics.

Table 25. Code flash memory program and erase electrical specifications

| No. | Symbol | | Parameter | Min | Typ ¹ | Initial max ² | Lifetime max ³ | Unit |
|-----|--------------------------|----|--|-----|------------------|--------------------------|---------------------------|------|
| 1 | T _{DWPROGRAM} | CC | Doubleword (64 bits) program time ⁴ | — | 18 | 50 | 500 | μs |
| 2 | T _{16KPPERASE} | CC | 16 KB block pre-program and erase time | — | 200 | 500 | 5000 | ms |
| 3 | T _{32KPPERASE} | CC | 32 KB block pre-program and erase time | — | 300 | 600 | 5000 | ms |
| 4 | T _{64KPPERASE} | CC | 64 KB block pre-program and erase time | — | 400 | 900 | 5000 | ms |
| 5 | T _{128KPPERASE} | CC | 128 KB block pre-program and erase time | — | 600 | 1300 | 7500 | ms |

¹ Typical program and erase times assume nominal supply values and operation at 25 °C.

² Initial Max program and erase times provide guidance for time-out limits used in the factory and apply for < 100 program/erase cycles, nominal supply values and operation at T_J = 25 °C. These values are verified at production test.

³ Lifetime Max program and erase times apply across the voltage, temperature, and cycling range of product life. These values are characterized, but not tested.

⁴ Actual hardware programming times. This does not include software overhead.

Table 26 shows the data flash memory program and erase characteristics.

Table 26. Data flash memory program and erase electrical specifications

| No. | Symbol | | Parameter | Min | Typ ¹ | Initial max ² | Lifetime max ³ | Unit |
|-----|-------------------------|----|--|-----|------------------|--------------------------|---------------------------|------|
| 1 | T _{DWPROGRAM} | CC | Singleword (32 bits) program time ⁴ | — | 30 | 70 | 300 | μs |
| 2 | T _{16KPPERASE} | CC | 16 KB block pre-program and erase time | — | 700 | 800 | 1500 | ms |

¹ Typical program and erase times assume nominal supply values and operation at 25 °C.

² Initial Max program and erase times provide guidance for time-out limits used in the factory and apply for < 100 program/erase cycles, nominal supply values and operation at T_J = 25 °C. These values are verified at production test.

³ Lifetime Max program and erase times apply across the voltage, temperature, and cycling range of product life. These values are characterized, but not tested.

⁴ Actual hardware programming times. This does not include software overhead.

Table 27. Flash memory module life

| No. | Symbol | | Parameter | Condition | Value | | | Unit |
|-----|--------|----|---|------------------------|---------|------------------|-----|--------|
| | | | | | Min | Typ ¹ | Max | |
| 1a | P/E | CC | Number of program/erase cycles per block for over the operating temperature range (T _J) | 16 KB blocks | 100,000 | — | — | cycles |
| 1b | | | | 32 KB and 64 KB blocks | 10,000 | 100,000 | — | cycles |
| 1c | | | | 128 KB blocks | 1,000 | 100,000 | — | cycles |

Table 27. Flash memory module life (continued)

| No. | Symbol | | Parameter | Condition | Value | | | Unit |
|-----|-----------|----|--|---------------------------------------|-------|------------------|-----|-------|
| | | | | | Min | Typ ¹ | Max | |
| 2 | Retention | CC | Minimum data retention at 85 °C average ambient temperature ² | Blocks with 0–1,000 P/E cycles | 20 | — | — | years |
| | | | | Blocks with 1,001–10,000 P/E cycles | 10 | — | — | years |
| | | | | Blocks with 10,001–100,000 P/E cycles | 5 | — | — | years |

¹ Typical endurance is evaluated at 25 °C. Product qualification is performed to the minimum specification. For additional information on the NXP definition of Typical Endurance, please refer to Engineering Bulletin EB619, *Typical Endurance for Nonvolatile Memory*.

² Ambient temperature averaged over duration of application, not to exceed product operating temperature range.

3.15.2 Read access timing

Table 28. Code flash read access timing

| No. | Symbol | | Parameter | Condition | Value | Unit |
|-----|-------------------|----|--|---------------|-------|------|
| | | | | | Max | |
| 1 | f _{READ} | CC | Maximum frequency for Flash reading (system clock frequency SYS_CLK) | 4 wait states | 90 | MHz |
| 2 | | | | 3 wait states | 60 | MHz |

Table 29. Data flash read access timing

| No. | Symbol | | Parameter | Condition | Value | Unit |
|-----|-------------------|----|--|----------------|-------|------|
| | | | | | Max | |
| 1 | f _{READ} | CC | Maximum frequency for Flash reading (system clock frequency SYS_CLK) | 12 wait states | 90 | MHz |
| 2 | | | | 8 wait states | 60 | MHz |

3.15.3 Write access timing

Table 30. Code flash write access timing

| No. | Symbol | | Parameter | Condition | Value | Unit |
|-----|--------------------|----|--|-----------|-------|------|
| | | | | | Max | |
| 1 | f _{WRITE} | CC | Maximum frequency for Flash writing (system clock frequency SYS_CLK) | — | 90 | MHz |

Table 31. Data flash write access timing

| No. | Symbol | | Parameter | Condition | Value | Unit |
|-----|--------------------|----|--|-----------|-------|------|
| | | | | | Max | |
| 1 | f_{WRITE} | CC | Maximum frequency for Flash writing (system clock frequency SYS_CLK) | — | 90 | MHz |

3.16 SRAM memory electrical characteristics

Table 32. System SRAM memory read/write access timing

| No. | Symbol | | Parameter | Condition | Value | Unit |
|-----|-------------------------|----|--|--------------|-------|------|
| | | | | | Max | |
| 1 | $f_{\text{READ/WRITE}}$ | CC | Maximum frequency for system SRAM reading/writing (system clock frequency SYS_CLK) | 1 wait state | 90 | MHz |

3.17 GP pads specifications

This section specifies the electrical characteristics of the GP pads. Please refer to the tables in [Section 2.2, Pin descriptions](#), for a cross reference between package pins and pad types.

3.17.1 GP pads DC specifications

Table 33 gives the DC electrical characteristics at 3.3 V ($3.0 \text{ V} < V_{\text{DD_HV_IO}} < 3.6 \text{ V}$).

Table 33. GP pads DC electrical characteristics¹

| No. | Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----|----------------------|-----------|--------------------------------------|-----------------------------------|-------------------------------|---------------------------------|------|
| 1 | V_{IL} | SR | Low level input voltage | — | — | $0.35 V_{\text{DD_HV_IO}}$ | V |
| 2 | V_{IH} | SR | High level input voltage | — | — | $V_{\text{DD_HV_IO}} + 0.1^2$ | V |
| 3 | V_{HYS} | CC | Schmitt trigger hysteresis | — | — | — | V |
| 4 | $V_{\text{OL_S}}$ | CC | Slow, low level output voltage | $I_{\text{OL}} = 1.5 \text{ mA}$ | — | 0.5 | V |
| 5 | $V_{\text{OH_S}}$ | CC | Slow, high level output voltage | $I_{\text{OH}} = -1.5 \text{ mA}$ | $V_{\text{DD_HV_IO}} - 0.8$ | — | V |
| 6 | $V_{\text{OL_M}}$ | CC | Medium, low level output voltage | $I_{\text{OL}} = 2 \text{ mA}$ | — | 0.5 | V |
| 7 | $V_{\text{OH_M}}$ | CC | Medium, high level output voltage | $I_{\text{OH}} = -2 \text{ mA}$ | $V_{\text{DD_HV_IO}} - 0.8$ | — | V |
| 8 | $V_{\text{OL_F}}$ | CC | Fast, high level output voltage | $I_{\text{OL}} = 11 \text{ mA}$ | — | 0.5 | V |
| 9 | $V_{\text{OH_F}}$ | CC | Fast, high level output voltage | $I_{\text{OH}} = -11 \text{ mA}$ | $V_{\text{DD_HV_IO}} - 0.8$ | — | V |
| 10 | $V_{\text{OL_SYM}}$ | CC | Symmetric, high level output voltage | $I_{\text{OL}} = 5 \text{ mA}$ | — | 0.5 | V |
| 11 | $V_{\text{OH_SYM}}$ | CC | Symmetric, high level output voltage | $I_{\text{OH}} = -5 \text{ mA}$ | $V_{\text{DD_HV_IO}} - 0.8$ | — | V |

Table 33. GP pads DC electrical characteristics¹ (continued)

| No. | Symbol | | Parameter | Conditions | Min | Typ | Max | Unit |
|-----|--------------------|----|--|-----------------------------------|----------------------------|-----|--|------|
| 12 | I _{PU} | CC | Equivalent pullup current | V _{IN} = V _{IL} | -130 | — | — | μA |
| | | | | V _{IN} = V _{IH} | — | — | -10 | |
| 13 | I _{PD} | CC | Equivalent pulldown current | V _{IN} = V _{IL} | 10 | — | — | μA |
| | | | | V _{IN} = V _{IH} | — | — | 130 | |
| 14 | I _{IL} | P | Input leakage current (all bidirectional ports) | T _A = -40 to 150 °C | -1 | — | 1 | μA |
| | | P | Input leakage current (All single ADC channels) ³ | T _A = -40 to 150 °C | -0.25 | — | 0.25 | μA |
| | | P | Input leakage current (All shared ADC channels) | T _A = -40 to 150 °C | -0.3 | — | 0.3 | μA |
| 16 | V _{ILR} | SR | $\overline{\text{RESET}}$, low level input voltage | — | -0.4 ² | — | 0.35 V _{DD_HV_IO} | V |
| 17 | V _{IHR} | SR | $\overline{\text{RESET}}$, high level input voltage | — | 0.65 V _{DD_HV_IO} | — | V _{DD_HV_IO} +0.4 ² | V |
| 18 | V _{HYSR} | CC | $\overline{\text{RESET}}$, Schmitt trigger hysteresis | — | 0.1 V _{DD_HV_IO} | — | — | V |
| 19 | V _{OLR} | CC | $\overline{\text{RESET}}$, low level output voltage | I _{OL} = 2 mA | — | — | 0.5 | V |
| 20 | I _{PD} | CC | $\overline{\text{RESET}}$, equivalent pulldown current | V _{IN} = V _{IL} | 10 | — | — | μA |
| | | | | V _{IN} = V _{IH} | — | — | 130 | |
| 21 | C _{IN} | D | Input pad capacitance | — | — | — | 3 | pF |
| 22 | V _{ILRSB} | SR | Reset Sup B, Low level input voltage | — | -0.1 ² | — | 0.30 V _{DD_HV_IO} | V |
| 23 | V _{IHRSB} | SR | Reset Sup B, High level input voltage | — | 0.65 V _{DD_HV_IO} | — | V _{DD_HV_IO} + 0.1 ² | V |

¹ The values provided in this table are not applicable for PDI and EBI/DRAM interface.

² "SR" parameter values must not exceed the absolute maximum ratings shown in Table 11.

³ Specified values are applicable to all modes of the pad, i.e., IBE = 0/1 and/or APC = 0/1.

3.17.2 GP pads AC specifications

Table 34. GP pads AC electrical characteristics¹

| No. | Pad | T _{switchon} ¹ (ns) | | | Rise/Fall ² (ns) | | | Frequency (MHz) | | | Current slew ³ (mA/ns) | | | Load drive (pF) |
|-----|------|---|-----|-----|-----------------------------|-----|-----|-----------------|-----|-----|-----------------------------------|-----|-----|-----------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| 1 | Slow | 3 | — | 40 | 4 | — | 40 | — | — | 4 | 0.01 | — | 2 | 25 |
| | | 3 | — | 40 | 6 | — | 50 | — | — | 2 | 0.01 | — | 2 | 50 |
| | | 3 | — | 40 | 10 | — | 75 | — | — | 2 | 0.01 | — | 2 | 100 |
| | | 3 | — | 40 | 14 | — | 100 | — | — | 2 | 0.01 | — | 2 | 200 |

Table 34. GP pads AC electrical characteristics¹ (continued)

| No. | Pad | Tswitchon ¹ (ns) | | | Rise/Fall ² (ns) | | | Frequency (MHz) | | | Current slew ³ (mA/ns) | | | Load drive (pF) |
|-----|----------------------------|--------------------------------|-----|-----|--------------------------------|-----|------|--------------------|-----|-----|--------------------------------------|-----|-----|--------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| 2 | Medium | 1 | — | 15 | 2 | — | 12 | — | — | 40 | 2.5 | — | 7 | 25 |
| | | 1 | — | 15 | 4 | — | 25 | — | — | 20 | 2.5 | — | 7 | 50 |
| | | 1 | — | 15 | 8 | — | 40 | — | — | 13 | 2.5 | — | 7 | 100 |
| | | 1 | — | 15 | 14 | — | 70 | — | — | 7 | 2.5 | — | 7 | 200 |
| 3 | Fast | 1 | — | 6 | 1 | — | 4 | — | — | 72 | 3 | — | 40 | 25 |
| | | 1 | — | 6 | 1.5 | — | 7 | — | — | 55 | 7 | — | 40 | 50 |
| | | 1 | — | 6 | 3 | — | 12 | — | — | 40 | 7 | — | 40 | 100 |
| | | 1 | — | 6 | 5 | — | 18 | — | — | 25 | 7 | — | 40 | 200 |
| 4 | Symmetric | 1 | — | 8 | 1 | — | 5 | — | — | 50 | 3 | — | 25 | 25 |
| 5 | Pullup/down (3.6 V max) | — | — | — | — | — | 7500 | — | — | — | — | — | — | 50 |

¹ The values provided in this table are not applicable for PDI and EBI/DRAM interface.

² Slope at rising/falling edge.

³ Data based on characterization results, not tested in production.

3.17.3 I/O pad current specifications

The power consumption of an I/O segment is dependent on the usage of the pins on a particular segment. The power consumption is the sum of all output pin currents for a particular segment. The output pin current can be calculated based on the voltage, frequency, and load on the pin.

Table 35. I/O pad current specifications

| Pad Type | Load (pF) | Frequency (MHz) | VDD_HV_IO (V) | Current (mA) |
|-------------------|--------------|--------------------|------------------|-----------------|
| GP Slow/Medium | 20 | 4 | 3.6 | 0.30 |
| GP Slow/Symmetric | 20 | 10 | 3.6 | 0.76 |
| GP Slow/Fast | 20 | 45 | 3.6 | 3.40 |
| GP Slow | 20 | 0.5 | 3.6 | 0.04 |

3.17.4 Power Sequence Pin States for GPIO Pads

Table 36. Power sequence pin states for GPIO pads

| VDD_LV_COR | VDD_HV_IO | Pad Function |
|------------|-----------|------------------|
| Low | Low | Outputs Disabled |
| Low | High | Outputs Disabled |
| High | Low | Outputs Disabled |

Table 36. Power sequence pin states for GPIO pads

| VDD_LV_COR | VDD_HV_IO | Pad Function |
|------------|-----------|------------------|
| High | High | Normal Operation |

3.18 PDI pads specifications

This section specifies the electrical characteristics of the PDI pads. Please refer to the tables in [Section 2.2, Pin descriptions](#), for a cross reference between package pins and pad types.

PDI pads feature list:

- Direction
 - Input
 - Output
 - Bidirectional
- Driver
 - Push/Pull/Open Drain
 - Configurable Four Drive Strengths on Fast driver pads
 - Configurable No Slew-Rate, Slow Slew-Rate, and Fast Slew-Rate on Slow, Medium, and SLR driver pads
 - VDD_HV_PDI NOTE: All pads are NOT 5 V TOLERANT. Pads are not capable of driving to or from voltages above their respective VDD_HV_PDI. In other words, you cannot connect a 3.3V external device to a pad supplied with 2.5 V. If a pad must be connected to a 3.3V device, its local VDD_HV_PDI must be 3.3 V. Injection current is then handled by the intrinsic diodes from the pad transistors and by the ESD diodes.
 - VDD_HV_PDI range 1.8 V to 3.3 V, as specified in the following tables
- Receiver
 - Selectable hysteresis input buffer
 - CMOS Input Buffer

The electrical data provided in this section applies:

- To the pads listed in [Table 37](#)
- Over the voltage range 1.62–3.6 V

Table 37. PDI I/O pads

| No. | Name | Voltage | Used for | Notes |
|-----|------------|------------|----------|--|
| 1 | PDI Fast | 1.62–3.6 V | I/O | Enhanced operating voltage range fast slew-rate output with four selectable slew-rates. Contains an input buffer and weak pullup/pulldown. |
| 2 | PDI Medium | | | Enhanced operating voltage range medium slew-rate output with four selectable slew-rates. Contains an input buffer and weak pullup/pulldown. |

Table 38. PDI pads DC electrical characteristics¹

| No. | Symbol | Parameter | Min | Max | Unit |
|-----|------------------------|---|-------------------------------|------------------------------|------|
| 1 | V _{DD_HV_PDI} | SR I/O supply voltage | 1.62 | 3.6 | V |
| 2 | V _{IH_C} | CC CMOS input buffer high voltage (hysteresis enabled) | 0.65 × V _{DD_HV_PDI} | V _{DD_HV_PDI} + 0.3 | V |
| 3 | V _{IH_C} | CC CMOS input buffer high voltage (hysteresis disabled) | 0.58 × V _{DD_HV_PDI} | V _{DD_HV_PDI} + 0.3 | V |

Table 38. PDI pads DC electrical characteristics¹ (continued)

| No. | Symbol | | Parameter | Min | Max | Unit |
|-----|--------------------|----|---|------------------------------|-------------------------------|------|
| 4 | V _{IL_C} | CC | CMOS input buffer low voltage (hysteresis enabled) | V _{SS} - 0.3 | 0.35 × V _{DD_HV_PDI} | V |
| 5 | V _{IL_C} | CC | CMOS input buffer low voltage (hysteresis disabled) | V _{SS} - 0.3 | 0.42 × V _{DD_HV_PDI} | V |
| 6 | V _{HYS_C} | CC | CMOS input buffer hysteresis | 0.1 × V _{DD_HV_PDI} | — | V |
| 7 | I _{ACT_S} | CC | Selectable weak pullup/pulldown current | 25 | 150 | μA |
| 8 | V _{OH} | CC | Output high voltage | 0.8 × V _{DD_HV_PDI} | — | V |
| 9 | V _{OL} | CC | Output low voltage | — | 0.2 × V _{DD_HV_PDI} | V |

¹ Over- and undershoots occurring due to impedance mismatch of the external driver and the transmission line at PDI pads in input mode can be allowed up to 0.7 V repeatedly throughout the product expected lifetime and will not cause any long term reliability issue.

Table 39. Drive current

| Pad | Drive Mode | Minimum I _{OH} (mA) ¹ | Minimum I _{OL} (mA) ² |
|------------|------------|---|---|
| PDI Fast | All | 26.2 | 84.8 |
| PDI Medium | All | 19.2 | 52.1 |

¹ I_{OH} is defined as the current sourced by the pad to drive the output to V_{OH}.

² I_{OL} is defined as the current sunk by the pad to drive the output to V_{OL}.

Table 40. PDI pads AC electrical characteristics

| No. | Name | Prop. Delay (ns) L → H/H → L ¹ | | Rise/Fall Edge (ns) | | Drive Load (pF) | Drive/Slew Rate Select |
|-----|------------|--|---------|---------------------|-----|-----------------|------------------------|
| | | Min | Max | Min | Max | | MSB, LSB |
| 1 | PDI Medium | 0.8/0.7 ----- 1.1/1.08 | 5.5/4.5 | 1.02/1 | — | 50 | 11 |
| | | | 12/8.3 | 3.5/2.3 | | 200 | |
| | | 49/22 | 9.1/6 | 50 | | 10 | |
| | | 60/31 | 14/9.2 | 200 | | | |
| | | 102/44 | 18/12 | 50 | | 01 | |
| | | 119/53 | 24/16 | 200 | | | |
| | | 722/302 | 126/85 | 50 | | 00 | |
| | | 772/325 | 136/90 | 200 | | | |

Table 40. PDI pads AC electrical characteristics (continued)

| No. | Name | Prop. Delay (ns) L → H/H → L ¹ | | Rise/Fall Edge (ns) | | Drive Load (pF) | Drive/Slew Rate Select |
|-----|----------|--|-------|---------------------|-----|-----------------|------------------------|
| | | Min | Max | Min | Max | | MSB, LSB |
| 2 | PDI Fast | 0.8/0.7 | 10/10 | 1.1/1.1 | — | 50 | 11 |
| | | ----- 1.1/1.08 | 15/15 | 2.6/2.6 | | 200 | |
| | | | 15/15 | 2.4/2.4 | | 50 | 10 |
| | | | 22/22 | 5/5 | | 200 | |
| | | | 24/24 | 5/5 | | 50 | 01 |
| | | | 33/33 | 8/8 | | 200 | |
| | | | 66/66 | 16/16 | | 50 | 00 |
| | | | 84/84 | 21/21 | | 200 | |

¹ L → H signifies low-to-high propagation delay and H → L signifies high-to-low propagation delay.

3.18.1 PDI pad current specifications

The power consumption of an I/O segment is dependent on the usage of the pins on a particular segment. The power consumption is the sum of all output pin currents for a particular segment. The output pin current can be calculated based on the voltage, frequency, and load on the pin.

Table 41. PDI pad current specifications

| Pad Type | Frequency (MHz) | Load (pF) | Voltage (V) | Drive/Slew Rate Select | Current (mA) |
|------------|-----------------|-----------|-------------|------------------------|--------------|
| PDI Medium | 66 | 50 | 3.6 | 11 | 8.7 |
| | 33 | 50 | 3.6 | 10 | 3.8 |
| | 20 | 50 | 3.6 | 01 | 2.3 |
| | 3 | 50 | 3.6 | 00 | 0.38 |
| | 3 | 200 | 3.6 | 00 | 1.5 |
| PDI Fast | 66 | 50 | 3.6 | 11 | 12 |
| | 50 | 50 | 3.6 | 10 | 6.2 |
| | 33 | 50 | 3.6 | 01 | 4.0 |
| | 20 | 50 | 3.6 | 00 | 2.4 |
| | 20 | 200 | 3.6 | 00 | 8.9 |

3.18.2 Power Sequence Pin States for PDI Pads

Table 42. Power sequence pin states for PDI pads

| VDD_LV_COR | VDD_HV_IO | VDD_HV_PDI | Pad Function |
|------------|-----------|------------|--------------------|
| Low | Low | High | Outputs drive high |

Table 42. Power sequence pin states for PDI pads

| VDD_LV_COR | VDD_HV_IO | VDD_HV_PDI | Pad Function |
|------------|-----------|------------|-------------------------------|
| Low | High | x | Outputs Disabled |
| High | Low | Low | Outputs Disabled |
| High | Low | High | Outputs drive high |
| High | High | Low | Normal Operation ¹ |
| High | High | High | Normal Operation |

¹ Normal operation except no drive current and input buffer output is unknown. The pad pre-drive circuitry will function normally but since VDD_HV_PDI is unpowered the outputs will not drive high even though the output PMOS can be enabled.

3.19 DRAM pad specifications

This section specifies the electrical characteristics of the DRAM pads. Please refer to the tables in [Section 2.2, Pin descriptions](#), for a cross reference between package pins and pad types.

DRAM pads feature list:

- Driver
 - Configurable to support LPDDR half strength, LPDDR full strength, DDR1, DDR2 half strength, DDR2 full strength, and SDR modes.
 - VDD_HV_DRAM range of
 - 1.8 V nominal
 - 2.5 V nominal
 - 3.3 V nominal
- Receiver
 - Differential or pseudo-differential input buffer in all DRAM pads
 - All inputs are tolerant up to their VDD_HV_DRAM absolute maximum rating
 - Data and strobe pads can be configured to support four signal termination options
 - Infinite/no termination
 - 50 Ω
 - 75 Ω
 - 150 Ω

The electrical data provided in [Section 3.19, DRAM pad specifications](#), applies to the pads listed in [Table 43](#).

Table 43. DRAM pads

| Name | Voltage | Used For | Notes ¹ |
|----------|--------------|----------|---|
| DRAM ACC | 1.62 V–3.6 V | I/O | Bidirectional DDR pad |
| DRAM CLK | 1.62 V–3.6 V | O | Output only differential clock driver pad |
| DRAM DQ | 1.62 V–3.6 V | I/O | Bidirectional DDR pad with integrated ODT |

¹ All pads can be configured to support LPDDR half strength, LPDDR full strength, DDR1, DDR2 half strength, DDR2 full strength, and SDR.

All three pad types can be configured to support SDR, DDR, DDR2 half and full strength, and LPDDR half and full strength modes, according to [Table 44](#).

Table 44. Mode configuration for DRAM pads

| Configuration ¹ | Mode |
|----------------------------|---------------------------|
| 000 | 1.8 V LPDDR Half Strength |
| 001 | 1.8 V LPDDR Full Strength |
| 010 | 1.8 V DDR2 Half Strength |
| 011 | 2.5 V DDR |
| 100 | Not supported |
| 101 | Not supported |
| 110 | 1.8 V DDR2 Full Strength |
| 111 | SDR |

¹ Configuration is selected in the corresponding PCR registers of the SIUL.

NOTE

0.7 V overshoot/undershoot can be allowed to occur repeatedly throughout the product expected lifetime and will not cause any long term reliability issue.

3.19.1 DRAM pads electrical specifications ($V_{DD_HV_DRAM} = 3.3\text{ V}$)

Table 45. DRAM pads DC electrical specifications ($V_{DD_HV_DRAM} = 3.3\text{ V}$)

| No. | Symbol | Parameter | Condition | Min | Max | Unit |
|-----|--------------------------|----------------------------------|-----------|---------------------------------|---------------------------------|------|
| 1 | $V_{DD_HV_DRAM}$ | I/O supply voltage | — | 3.0 | 3.6 | V |
| 2 | $V_{DD_HV_DRAM_VREF}$ | Input reference voltage | — | 1.3 | 1.7 | V |
| 3 | $V_{DD_HV_DRAM_VTT}$ | Termination voltage ¹ | — | $V_{DD_HV_DRAM_VREF} - 0.05$ | $V_{DD_HV_DRAM_VREF} + 0.05$ | V |
| 4 | V_{IH} | Input high voltage | — | $V_{DD_HV_DRAM_VREF} + 0.20$ | — | V |
| 5 | V_{IL} | Input low voltage | — | — | $V_{DD_HV_DRAM_VREF} - 0.2$ | V |
| 6 | V_{OH} | Output high voltage | — | $V_{DD_HV_DRAM_VTT} + 0.8$ | — | V |
| 7 | V_{OL} | Output low voltage | — | — | $V_{DD_HV_DRAM_VTT} - 0.8$ | V |

¹ BGA473: Termination voltage can be supplied via package pins. BGA257 termination voltage internally tied as the BGA257 does not provide DRAM interface. Disable ODT.

Table 46. Output drive current @ $V_{DDE} = 3.3 \text{ V} (\pm 10\%)$

| No. | Pad Name | Drive Mode | Minimum I_{OH} (mA) ¹ | Minimum I_{OL} (mA) ² |
|-----|----------|------------|------------------------------------|------------------------------------|
| 1 | DRAM ACC | 111 | -16 | 16 |
| 2 | DRAM DQ | | | |
| 3 | DRAM CLK | | | |

¹ I_{OH} is defined as the current sourced by the pad to drive the output to V_{OH} .

² I_{OL} is defined as the current sunk by the pad to drive the output to V_{OL} .

Table 47. DRAM pads AC electrical specifications ($V_{DD_HV_DRAM} = 3.3 \text{ V}$)

| No. | Pad Name | Prop. Delay (ns) L → H/H → L ¹ | | Output Slew rate Rise/Fall (V/ns) | | Drive Load (pF) | Drive/Slew Rate Select |
|-----|----------|--|---------|--------------------------------------|---------|--------------------|---------------------------|
| | | Min | Max | Min | Max | | MSB, LSB |
| 1 | DRAM ACC | 1.4/1.4 | 2.4/2.4 | 3.1/2.5 | 5.6/5.4 | 5 | 111 |
| | | 1.7/1.7 | 2.7/2.7 | 0.9/1.1 | 1.7/2.0 | 20 | 111 |
| 2 | DRAM DQ | 1.4/1.4 | 2.4/2.4 | 3.1/2.5 | 5.6/5.4 | 5 | 111 |
| | | 1.7/1.7 | 2.7/2.7 | 0.9/1.1 | 1.7/2.0 | 20 | 111 |
| 3 | DRAM CLK | 1.4/1.4 | 2.4/2.4 | 3.1/2.5 | 5.7/5.7 | 5 | 111 |
| | | 1.6/1.6 | 2.6/2.6 | 1.1/1.3 | 2.3/2.3 | 20 | 111 |

¹ L → H signifies low-to-high propagation delay and H → L signifies high-to-low propagation delay.

3.19.2 DRAM pads electrical specification ($V_{DD_HV_DRAM} = 2.5 \text{ V}$)

Table 48. DRAM pads DC electrical specifications ($V_{DD_HV_DRAM} = 2.5 \text{ V}$)

| No. | Symbol | Parameter | Condition | Min | Max | Unit |
|-----|--------------------------|----------------------------------|-----------|---------------------------------|---------------------------------|------|
| 1 | $V_{DD_HV_DRAM}$ | I/O supply voltage | — | 2.3 | 2.7 | V |
| 2 | $V_{DD_HV_DRAM_VREF}$ | Input reference voltage | — | $0.49 \times V_{DD_HV_DRAM}$ | $0.51 \times V_{DD_HV_DRAM}$ | V |
| 3 | $V_{DD_HV_DRAM_VTT}$ | Termination voltage ¹ | — | $V_{DD_HV_DRAM_VREF} - 0.04$ | $V_{DD_HV_DRAM_VREF} + 0.04$ | V |
| 4 | V_{IH} | Input high voltage | — | $V_{DD_HV_DRAM_VREF} + 0.15$ | — | V |
| 5 | V_{IL} | Input low voltage | — | — | $V_{DD_HV_DRAM_VREF} - 0.15$ | V |
| 6 | V_{OH} | Output high voltage | — | $V_{DD_HV_DRAM_VTT} + 0.81$ | — | V |
| 7 | V_{OL} | Output low voltage | — | — | $V_{DD_HV_DRAM_VTT} - 0.81$ | V |

¹ 473 MAPBGA: Termination voltage can be supplied via package pins. 257 MAPBGA Termination voltage internally tied as the 257 MAPBGA does not provide DRAM interface. Disable ODT.

Table 49. Output drive current @ $V_{DDE} = 2.5\text{ V} (\pm 200\text{ mV})$

| Pad Name | Drive Mode | Minimum I_{OH} (mA) ¹ | Minimum I_{OL} (mA) ² |
|----------|------------|------------------------------------|------------------------------------|
| DRAM ACC | 011 | -16.2 | 16.2 |
| DRAM DQ | 011 | | |
| DRAM CLK | 011 | | |

¹ I_{OH} is defined as the current sourced by the pad to drive the output to V_{OH} .

² I_{OL} is defined as the current sunk by the pad to drive the output to V_{OL} .

Table 50. DRAM pads AC electrical specifications ($V_{DD_HV_DRAM} = 2.5\text{ V}$)

| No. | Pad Name | Prop. Delay (ns) L → H/H → L ¹ | | Rise/Fall Edge (ns) | | Drive Load (pF) | Drive/Slew Rate Select |
|-----|----------|--|---------|---------------------|---------|-----------------|------------------------|
| | | Min | Max | Min | Max | | MSB, LSB |
| 1 | DRAM ACC | 1.4/1.5 | 2.5/2.4 | 2.1/2.1 | 4.3/4.1 | 5 | 011 |
| | | 1.7/1.7 | 2.8/2.7 | 0.6/0.7 | 1.1/1.3 | 20 | |
| 2 | DRAM DQ | 1.4/1.5 | 2.5/2.4 | 2.1/2.1 | 4.3/4.1 | 5 | 011 |
| | | 1.7/1.7 | 2.8/2.7 | 0.6/0.7 | 1.1/1.3 | 20 | |
| 3 | DRAM CLK | 1.4/1.4 | 2.4/2.4 | 2.1/2.1 | 4.4/4.1 | 5 | 011 |
| | | 1.6/1.6 | 2.7/2.7 | 0.6/0.7 | 1.6/1.8 | 20 | |

¹ L → H signifies low-to-high propagation delay and H → L signifies high-to-low propagation delay.

3.19.3 DRAM pads electrical specification ($V_{DD_HV_DRAM} = 1.8\text{ V}$)

Table 51. DRAM pads DC electrical specifications ($V_{DD_HV_DRAM} = 1.8\text{ V}$)

| No. | Symbol | | Parameter | Condition | Min | Max | Unit |
|-----|--------------------------|----|----------------------------------|-----------|----------------------------------|----------------------------------|------|
| 1 | $V_{DD_HV_DRAM}$ | SR | I/O supply voltage | — | 1.62 | 1.9 | V |
| 2 | $V_{DD_HV_DRAM_VREF}$ | CC | Input reference voltage | — | $0.49 \times V_{DD_HV_DRAM}$ | $0.51 \times V_{DD_HV_DRAM}$ | V |
| 3 | $V_{DD_HV_DRAM_VTT}$ | CC | Termination voltage ¹ | — | $V_{DD_HV_DRAM_VREF} - 0.04$ | $V_{DD_HV_DRAM_VREF} + 0.04$ | V |
| 4 | V_{IH} | CC | Input high voltage | — | $V_{DD_HV_DRAM_VREF} + 0.125$ | — | V |
| 5 | V_{IL} | CC | Input low voltage | — | — | $V_{DD_HV_DRAM_VREF} - 0.125$ | V |
| 6 | V_{OH} | CC | Output high voltage | — | 1.42 | — | V |
| 7 | V_{OL} | CC | Output low voltage | — | — | 0.28 | V |

¹ BGA473: Termination voltage can be supplied via package pins. BGA257 Termination voltage internally tied as the BGA257 does not provide DRAM interface. Disable ODT.

Table 52. Output drive current @ $V_{DDE} = 1.8\text{ V} (\pm 100\text{ mV})$

| No. | Pad Name | Drive Mode | Minimum I_{OH} (mA) ¹ | Minimum I_{OL} (mA) ² |
|-----|----------|------------|------------------------------------|------------------------------------|
| 1 | DRAM ACC | 000 | -3.57 | 3.57 |
| | | 001 | -7.84 | 7.84 |
| | | 010 | -5.36 | 5.36 |
| | | 110 | -13.4 | 13.4 |
| 2 | DRAM DQ | 000 | -3.57 | 3.57 |
| | | 001 | -7.84 | 7.84 |
| | | 010 | -5.36 | 5.36 |
| | | 110 | -13.4 | 13.4 |
| 3 | DRAM CLK | 000 | -3.57 | 3.57 |
| | | 001 | -7.84 | 7.84 |
| | | 010 | -5.36 | 5.36 |
| | | 110 | -13.4 | 13.4 |

¹ I_{OH} is defined as the current sourced by the pad to drive the output to V_{OH} .

² I_{OL} is defined as the current sunk by the pad to drive the output to V_{OL} .

Table 53. DRAM pads AC electrical specifications ($V_{DD_HV_DRAM} = 1.8\text{ V}$)

| No. | Pad Name | Prop. Delay (ns) L → H/H → L ¹ | | Rise/Fall Edge (ns) | | Drive Load (pF) | Drive/Slew Rate Select |
|-----|----------|--|---------|------------------------|---------|--------------------|---------------------------|
| | | Min | Max | Min | Max | | MSB, LSB |
| 1 | DRAM ACC | 1.4/1.4 | 2.4/2.4 | 0.6/1.0 | 2.7/2.6 | 5 | 000 |
| | | 1.7/1.7 | 2.8/2.7 | 0.2/0.4 | 0.5/0.6 | 20 | |
| | | 1.4/1.5 | 2.4/2.5 | 1.1/1.1 | 3.0/2.7 | 5 | 001 |
| | | 1.7/1.7 | 2.8/2.8 | 0.4/0.4 | 0.7/0.7 | 20 | |
| | | 1.4/1.5 | 2.4/2.4 | 1.0/1.1 | 2.9/2.7 | 5 | 010 |
| | | 1.7/1.7 | 2.8/2.7 | 0.3/0.4 | 0.6/0.7 | 20 | |
| | | 1.4/1.5 | 2.5/2.5 | 1.5/1.1 | 3.1/2.6 | 5 | 110 |
| | | 1.7/1.8 | 2.8/2.8 | 0.4/0.4 | 0.7/0.6 | 20 | |
| 2 | DRAM DQ | 1.4/1.4 | 2.4/2.4 | 0.6/1.0 | 2.7/2.6 | 5 | 000 |
| | | 1.7/1.7 | 2.8/2.7 | 0.2/0.4 | 0.5/0.6 | 20 | |
| | | 1.4/1.5 | 2.4/2.5 | 1.1/1.1 | 3.0/2.7 | 5 | 001 |
| | | 1.7/1.7 | 2.8/2.8 | 0.4/0.4 | 0.7/0.7 | 20 | |
| | | 1.4/1.5 | 2.4/2.4 | 1.0/1.1 | 2.9/2.7 | 5 | 010 |
| | | 1.7/1.7 | 2.8/2.7 | 0.3/0.4 | 0.6/0.7 | 20 | |
| | | 1.4/1.5 | 2.5/2.5 | 1.5/1.1 | 3.1/2.6 | 5 | 110 |
| | | 1.7/1.8 | 2.8/2.8 | 0.4/0.4 | 0.7/0.6 | 20 | |

Table 53. DRAM pads AC electrical specifications ($V_{DD_HV_DRAM}$ (continued) = 1.8 V)

| No. | Pad Name | Prop. Delay (ns) L → H/H → L ¹ | | Rise/Fall Edge (ns) | | Drive Load (pF) | Drive/Slew Rate Select |
|-----|----------|--|---------|------------------------|---------|--------------------|---------------------------|
| | | Min | Max | Min | Max | | MSB, LSB |
| 3 | DRAM CLK | 1.4/1.4 | 2.4/2.4 | 0.4/0.6 | 2.7/2.7 | 5 | 000 |
| | | 1.6/1.6 | 2.7/2.7 | 0.7/0.9 | 1.8/3.4 | 20 | |
| | | 1.4/1.4 | 2.4/2.4 | 1.1/1.1 | 3.0/2.8 | 5 | 001 |
| | | 1.7/1.7 | 2.7/2.7 | 0.3/0.4 | 1.0/1.1 | 20 | |
| | | 1.4/1.4 | 2.4/2.4 | 0.9/1.1 | 3.0/2.8 | 5 | 010 |
| | | 1.6/1.6 | 2.7/2.7 | 0.3/0.4 | 0.9/1.0 | 20 | |
| | | 1.4/1.4 | 2.5/2.5 | 1.5/1.2 | 3.2/2.6 | 5 | 110 |
| | | 1.7/1.7 | 2.7/2.7 | 0.4/0.4 | 1.1/1.2 | 20 | |

¹ L → H signifies low-to-high propagation delay and H → L signifies high-to-low propagation delay.

3.19.4 DRAM Pad Current Specifications

The power consumption of an I/O segment is dependent on the usage of the pins on a particular segment. The power consumption is the sum of all output pin currents for a particular segment. The output pin current can be calculated based on the voltage, frequency, and load on the pin.

Table 54. DRAM pad current specifications

| Pad Type | Frequency (MHz) | Load (pF) | Voltage (V) | Drive/Slew Rate Select | Current (mA) |
|-----------------------|-----------------|-----------|-------------|-----------------------------|--------------|
| DRAM DQ / DRAM ACC | 45 | 5 | 1.8 | LPDDR_HS (010) ¹ | 0.74 |
| | 45 | 5 | 1.8 | LPDDR_FS (110) ¹ | 0.9 |
| | 45 | 5 | 1.8 | DDR2_HS (010) ¹ | 0.81 |
| | 45 | 5 | 1.8 | DDR2_FS (110) ¹ | 1.26 |
| | 45 | 10 | 1.8 | LPDDR_HS (010) ¹ | 1.14 |
| | 45 | 10 | 1.8 | LPDDR_FS (110) ¹ | 1.28 |
| | 45 | 10 | 1.8 | DDR2_HS (010) ¹ | 1.21 |
| | 45 | 10 | 1.8 | DDR2_FS (110) ¹ | 1.59 |
| | 45 | 20 | 1.8 | LPDDR_HS (010) ¹ | 1.97 |
| | 45 | 20 | 1.8 | LPDDR_FS (110) ¹ | 2.08 |
| | 45 | 20 | 1.8 | DDR2_HS (010) ¹ | 2.02 |
| | 45 | 20 | 1.8 | DDR2_FS (110) ¹ | 2.33 |
| | 90 | 5 | 1.8 | LPDDR_HS (010) ¹ | 1.41 |
| | 90 | 5 | 1.8 | LPDDR_FS (110) ¹ | 1.73 |
| | 90 | 5 | 1.8 | DDR2_HS (010) ¹ | 1.56 |
| | 90 | 5 | 1.8 | DDR2_FS (110) ¹ | 2.42 |
| | 90 | 10 | 1.8 | LPDDR_HS (010) ¹ | 2.19 |
| | 90 | 10 | 1.8 | LPDDR_FS (110) ¹ | 2.45 |
| | 90 | 10 | 1.8 | DDR2_HS (010) ¹ | 2.32 |
| | 90 | 10 | 1.8 | DDR2_FS (110) ¹ | 3.05 |
| | 90 | 20 | 1.8 | LPDDR_HS (010) ¹ | 3.77 |
| | 90 | 20 | 1.8 | LPDDR_FS (110) ¹ | 3.98 |
| | 90 | 20 | 1.8 | DDR2_HS (010) ¹ | 3.87 |
| | 90 | 20 | 1.8 | DDR2_FS (110) ¹ | 4.46 |

¹ LPDDR_HS = LPDDR half strength, LPDDR_FS = LPDDR full strength, DDR2_HS = DDR2 half strength, DDR2_FS = DDR2 half strength.

3.19.5 Power Sequence Pin States for DRAM Pads

Table 55. Power sequence pin states for DRAM pads

| VDD_LV_COR | VDD_HV_IO | VDD_HV_PDI | Pad Function |
|------------|-----------|------------|------------------|
| Low | Low | High | Outputs Disabled |
| Low | High | x | Outputs Disabled |
| High | Low | Low | Outputs Disabled |
| High | Low | High | Outputs Disabled |

Table 55. Power sequence pin states for DRAM pads

| VDD_LV_COR | VDD_HV_IO | VDD_HV_PDI | Pad Function |
|------------|-----------|------------|-------------------------------|
| High | High | Low | Normal Operation ¹ |
| High | High | High | Normal Operation |

¹ Normal operation except no drive current and input buffer output is unknown. The pad pre-drive circuitry will function normally but since VDD_HV_DRAM is unpowered, the outputs will not drive high even though the output PMOS can be enabled. DDR pad is only guaranteed to operate and be in compliance with Jedec standards, when all three power supplies, VDD_LV_COR, VDD_HV_IO and VDD_HV_DRAM are fully powered up.

3.20 $\overline{\text{RESET}}$ characteristics

3.20.1 $\overline{\text{RESET}}$ pin characteristics

Table 56. $\overline{\text{RESET}}$ pin characteristics

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|--------------------|---|------------|-----|-----|------|
| 1 | W_{FRST} | SR $\overline{\text{RESET}}$ pulse is sure to be filtered | — | — | 70 | ns |
| 2 | W_{NFRST} | SR $\overline{\text{RESET}}$ pulse is sure not to be filtered | — | 400 | — | ns |

3.20.2 $\overline{\text{RESET_SUP_B}}$ pin characteristics

Table 57. $\overline{\text{RESET_SUP_B}}$ pin characteristics

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|---------------------|---|------------|-----|-----|------|
| 1 | W_{FRST} | SR $\overline{\text{RESET_SUP_B}}$ pulse is sure to be filtered (there is no internal filter on this pin) | — | — | 0 | ns |
| 2 | T_{RSTSUP} | SR $\overline{\text{RESET_SUP_B}}$ release by an external delay/monitor circuit after all supplies are stable | — | 0 | — | ns |

3.21 Reset sequence

This section shows the duration for different reset sequences. It describes the different reset sequences and it specifies the start conditions and the end indication for the reset sequences depending on internal or external VREG mode.

3.21.1 Reset sequence duration

Table 58 specifies the minimum and the maximum reset sequence duration for the five different reset sequences described in Section 3.21.2, [Reset sequence description](#).

Table 58. RESET sequences

| No. | Symbol | | Parameter | T _{Reset} | | | Unit |
|-----|-------------------|----|--|--------------------|-----|------------------|------|
| | | | | Min | Typ | Max ¹ | |
| 1 | T _{DRB} | CC | Destructive Reset Sequence, BIST enabled | 50 | 60 | 70 | ms |
| 2 | T _{DR} | CC | Destructive Reset Sequence, BIST disabled | 40 | 400 | 1000 | μs |
| 3 | T _{ERLB} | CC | External Reset Sequence Long, BIST enabled | 50 | 60 | 70 | ms |
| 4 | T _{FRL} | CC | Functional Reset Sequence Long | 40 | 300 | 600 | μs |
| 5 | T _{FRS} | CC | Functional Reset Sequence Short | 1 | 3 | 10 | μs |

¹ The maximum value is applicable only if the reset sequence duration is not prolonged by an extended assertion of RESET by an external reset generator.

3.21.2 Reset sequence description

The figures in this section show the internal states of the MPC5675K during the five different reset sequences. The dotted lines in the figures indicate the starting point and the end point for which the duration is specified in Table 58. The start point and end point conditions as well as the reset trigger mapping to the different reset sequences is specified in Section 3.21.3, [Reset sequence trigger mapping](#).

With the beginning of DRUN mode, the first instruction is fetched and executed. At this point, application execution starts and the internal reset sequence is finished.

The following figures show the internal states of the MPC5675K during the execution of the reset sequence and the possible states of the $\overline{\text{RESET}}$ signal pin.

NOTE

$\overline{\text{RESET}}$ is a bidirectional pin. The voltage level on this pin can either be driven low by an external reset generator or by the MPC5675K internal reset circuitry. A high level on this pin can only be generated by an external pullup resistor which is strong enough to overdrive the weak internal pulldown resistor. The rising edge on $\overline{\text{RESET}}$ in the following figures indicates the time when the device stops driving it low. The reset sequence durations given in Table 58 are applicable only if the internal reset sequence is not prolonged by an external reset generator keeping $\overline{\text{RESET}}$ asserted low beyond the last PHASE3.

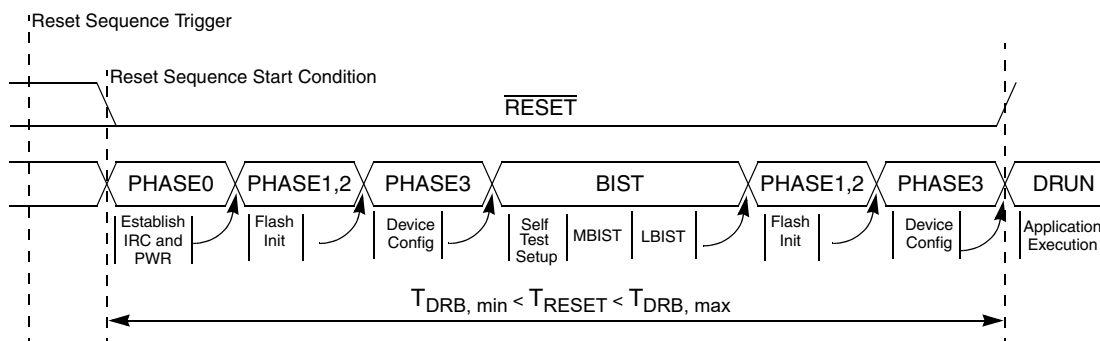


Figure 12. Destructive reset sequence, BIST enabled

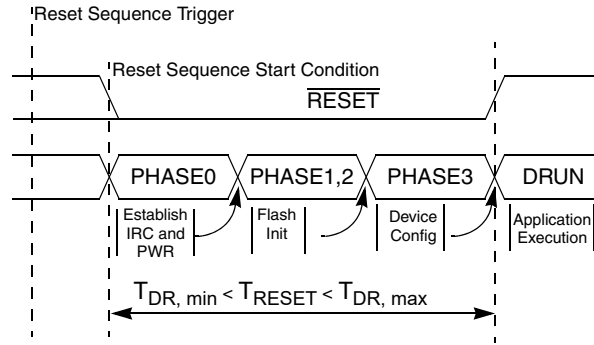


Figure 13. Destructive reset sequence, BIST disabled

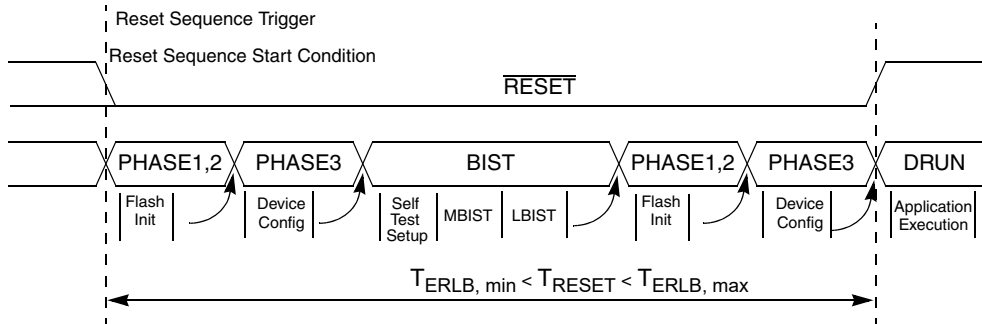


Figure 14. External reset sequence long, BIST enabled

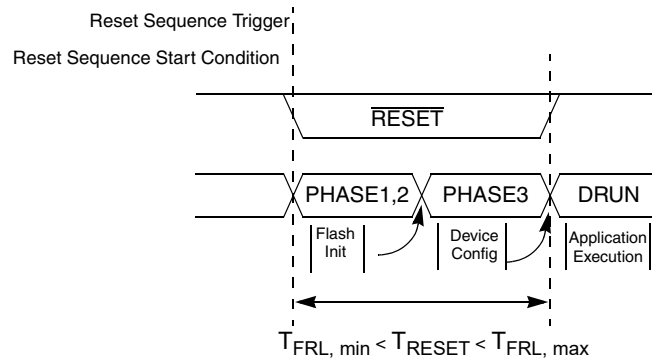


Figure 15. Functional reset sequence long

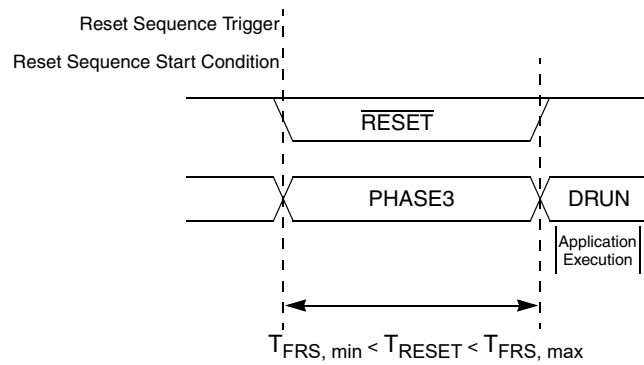


Figure 16. Functional reset sequence short

The reset sequences shown in [Figure 15](#) and [Figure 16](#) are triggered by functional reset events. $\overline{\text{RESET}}$ is driven low during these two reset sequences **only if** the corresponding functional reset source (which triggered the reset sequence) was enabled to drive $\overline{\text{RESET}}$ low for the duration of the internal reset sequence. See the RGM_FBRE register in the *MPC5675K Reference Manual* for more information.

3.21.3 Reset sequence trigger mapping

The following table shows the possible trigger events for the different reset sequences, depending on the VREG mode (external or internal). It specifies the reset sequence start conditions as well as the reset sequence end indications that are the basis for the timing data provided in [Table 58](#).

Table 59. Reset sequence trigger—reset sequence

| Reset Sequence Trigger | VREG Mode ¹ | Reset Sequence Start Condition | Reset Sequence End Indication | Reset Sequence | | | | |
|---|------------------------|---|---|---|--|--|--------------------------------|---------------------------------|
| | | | | Destructive Reset Sequence, BIST enabled ² | Destructive Reset Sequence, BIST disabled ² | External Reset Sequence Long, BIST enabled | Functional Reset Sequence Long | Functional Reset Sequence Short |
| All active internal destructive reset sources (LVDs or internal HVD during power-up and during operation) | I | Section 3. 21.4.1, Internal VREG mode | Release of $\overline{\text{RESET}}$ ³ | triggers | | cannot trigger | cannot trigger | cannot trigger |
| | E | Section 3. 21.4.2, External VREG mode | | cannot trigger | cannot trigger | cannot trigger | | |
| Assertion of $\overline{\text{RESET_SUP}}$ ⁴ | | | | | | | | |
| Assertion of $\overline{\text{RESET}}$ ⁵ | I/E | Section 3. 21.4.3, External reset via $\overline{\text{RESET}}$ | | cannot trigger | triggers ⁶ | triggers ⁷ | triggers ⁸ | |
| All internal functional reset sources configured for long reset | I/E | Sequence starts with internal reset trigger | Release of $\overline{\text{RESET}}$ ⁹ | cannot trigger | cannot trigger | triggers | cannot trigger | |
| All internal functional reset sources configured for short reset | I/E | | | cannot trigger | cannot trigger | cannot trigger | triggers | |

¹ VREG Mode: I = Internal VREG Mode, E = External VREG Mode.
² Whether BIST is executed or not depends on device configuration data stored in the shadow sector of the NVM.
³ End of the internal reset sequence (as specified in Table 58) can only be observed by release of $\overline{\text{RESET}}$ if it is not held low externally beyond the end of the internal sequence which would prolong the internal reset PHASE3 until $\overline{\text{RESET}}$ is released externally.
⁴ In external VREG mode only.
⁵ The assertion of $\overline{\text{RESET}}$ can only trigger a reset sequence if the device was running ($\overline{\text{RESET}}$ released) before. $\overline{\text{RESET}}$ does not gate a *Destructive Reset Sequence, BIST enabled* or a *Destructive Reset Sequence, BIST disabled*. However, it can prolong these sequences if $\overline{\text{RESET}}$ is held low externally beyond the end of the internal sequence (beyond PHASE3).
⁶ If $\overline{\text{RESET}}$ is configured for long reset (default) and if BIST is enabled via device configuration data stored in the shadow sector of the NVM.
⁷ If $\overline{\text{RESET}}$ is configured for long reset (default) and if BIST is disabled via device configuration data stored in the shadow sector of the NVM.

- ⁸ If $\overline{\text{RESET}}$ is configured for short reset.
- ⁹ Internal reset sequence can only be observed by state of $\overline{\text{RESET}}$ if bidirectional $\overline{\text{RESET}}$ functionality is enabled for the functional reset source which triggered the reset sequence.

3.21.4 Reset sequence—start condition

The impact of the voltage thresholds on the starting point of the internal reset sequence are becoming important if the voltage rails / signals ramp up with a very slow slew rate compared to the overall reset sequence duration.

3.21.4.1 Internal VREG mode

Figure 17 shows the voltage threshold that determines the start of the *Destructive Reset Sequence, BIST enabled* and the start for the *Destructive Reset Sequence, BIST disabled*. The last voltage rail crossing the levels shown in Figure 17 determines the start of the reset times specified in Table 58.

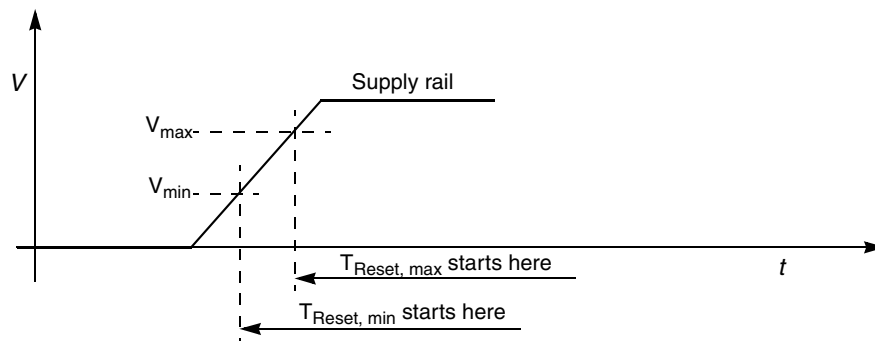


Figure 17. Reset sequence start in internal VREG mode

Table 60. Voltage thresholds

| Variable name | Value |
|---------------|---|
| V_{\min} | LvdReg – 3.5% |
| V_{\max} | LvdReg + 3.5% |
| Supply Rail | VDD_HV_PMU VDD_HV_IO VDD_HV_FLASH VDD_HV_ADV |

3.21.4.2 External VREG mode

Figure 18 and Figure 19 show the voltage thresholds that determine the start of the Destructive Reset Sequence, BIST enabled and the start for the Destructive Reset Sequence, BIST disabled.

NOTE

$\overline{\text{RESET_SUP}}$ must not be released unless $V_{\text{DD_LV_xxx}}$ is within its valid range of operation. $\overline{\text{RESET_SUP}}$ input circuitry needs a valid $V_{\text{DD_HV_IO}}$ rail in order to detect a high level on $\overline{\text{RESET_SUP}}$.

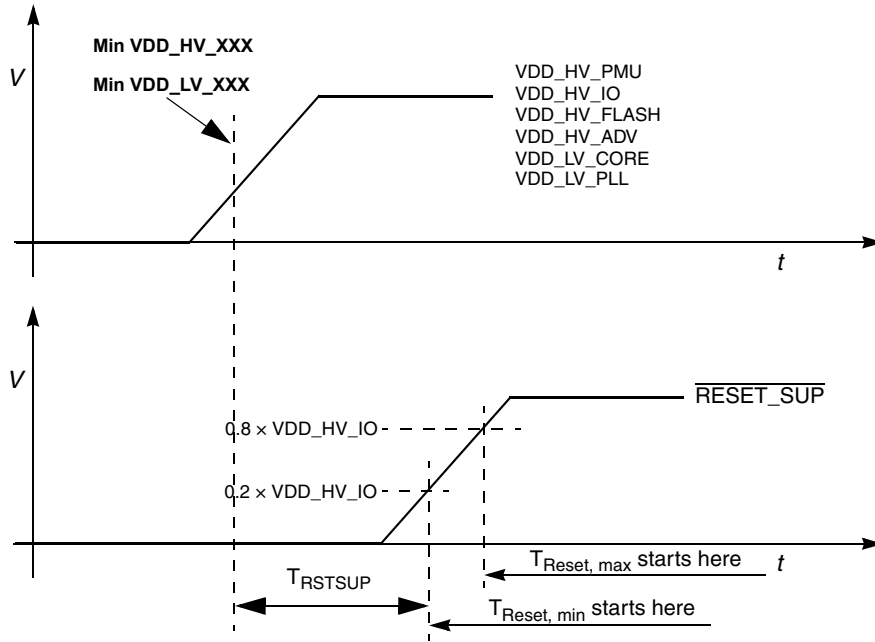


Figure 18. External VREG mode, $\overline{\text{RESET_SUP}}$ rises after $V_{\text{DD_HV_xxx}}$ are stable

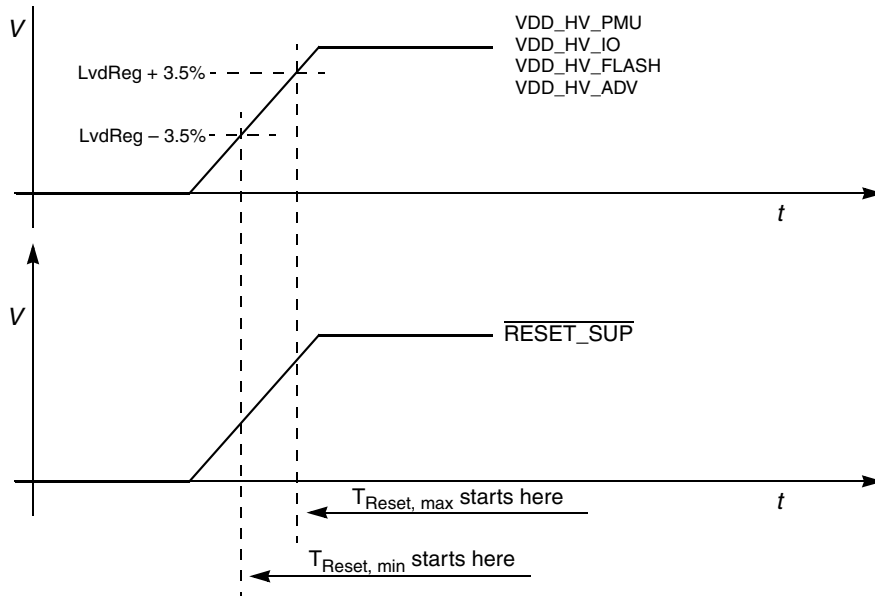


Figure 19. External VREG mode, $\overline{\text{RESET_SUP}}$ rises with $V_{\text{DD_HV_xxx}}$

NOTE

In case $\overline{\text{RESET_SUP}}$ has reached a valid high level before $V_{\text{DD_HV_IO}}$ is stable, the reset sequence will start as documented in Figure 19 as the $\overline{\text{RESET_SUP}}$ input circuitry needs a valid $V_{\text{DD_HV_IO}}$ rail in order to detect a high level on $\overline{\text{RESET_SUP}}$.

3.21.4.3 External reset via $\overline{\text{RESET}}$

Figure 20 shows the voltage thresholds that determine the start of the reset sequences initiated by the assertion of $\overline{\text{RESET}}$ as specified in Table 59.

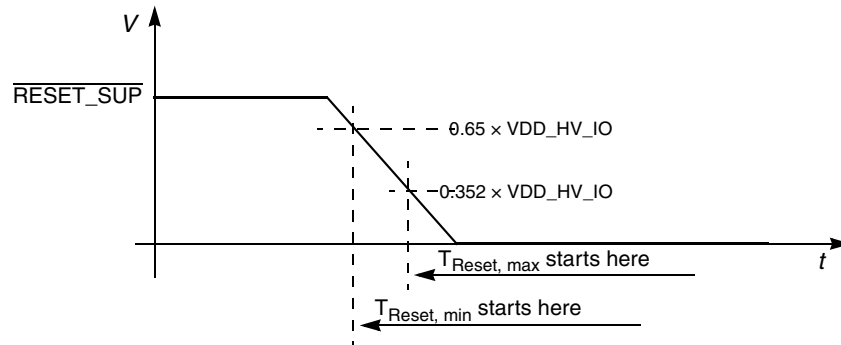


Figure 20. Reset sequence start via $\overline{\text{RESET}}$ assertion

3.21.5 External watchdog window

If the application design requires the use of an external watchdog the data provided in Section 3.21, Reset sequence can be used to determine the correct positioning of the trigger window for the external watchdog. Figure 21 shows the relationships between the minimum and the maximum duration of a given reset sequence and the position of an external watchdog trigger window.

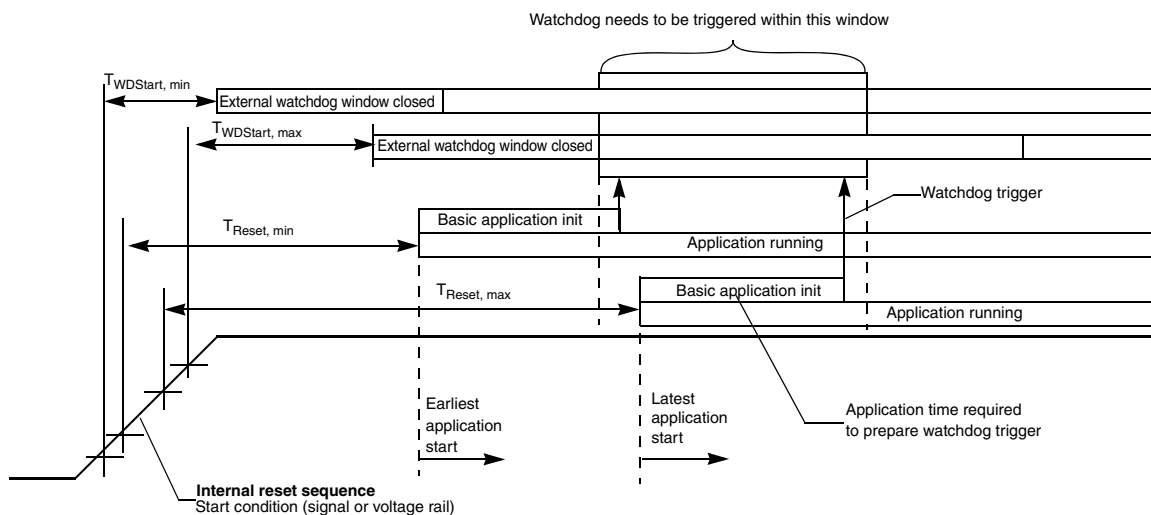


Figure 21. Reset sequence—external watchdog trigger window position

3.22 Peripheral timing characteristics

3.22.1 SDRAM (DDR)

The MPC5675K memory controller supports three types of DDR devices:

- DDR-1 (SSTL_2 class II interface)
- DDR-2 (SSTL_18 interface)
- LPDDR/Mobile-DDR (1.8V I/O supply voltage)

Electrical characteristics

JEDEC standards define the minimum set of requirements for compliant memory devices:

- JEDEC STANDARD, DDR2 SDRAM SPECIFICATION, JESD79-2C, MAY 2006
- JEDEC STANDARD, Double Data Rate (DDR) SDRAM Specification, JESD79E, May 2005
- JEDEC STANDARD, Low Power Double Data Rate (LPDDR) SDRAM Specification, JESD79-4, May 2006

The MPC5675K supports the configuration of two output drive strengths for DDR2 and LPDDR:

- Full drive strength
- Half drive strength (intended for lighter loads or point-to-point environments)

The MPC5675K memory controller supports dynamic on-die termination in the host device and in the DDR2 memory device.

This section includes AC specifications for all DDR SDRAM pins. The DC parameters are specified in the [Section 3.19, DRAM pad specifications](#).

3.22.1.1 DDR and DDR2 SDRAM AC timing specifications

Table 61. DDR and DDR2 (DDR2-400) SDRAM timing specifications
At recommended operating conditions with $V_{DD_MEM_IO}$ of $\pm 5\%$

| No. | Symbol | Parameter | Min | Max | Unit |
|-----|-----------------|--|------------------------------------|------------------------------------|----------|
| 1 | t_{CK} | CC Clock cycle time, $CL = x$ | — | 90 | MHz |
| 2 | V_{IX-AC} | CC MCK AC differential crosspoint voltage ¹ | $V_{DD_MEM_IO} \times 0.5 - 0.1$ | $V_{DD_MEM_IO} \times 0.5 + 0.1$ | V |
| 3 | t_{CH} | CC CK HIGH pulse width ^{1, 2} | 0.47 | 0.53 | t_{CK} |
| 4 | t_{CL} | CC CK LOW pulse width ^{1, 2} | 0.47 | 0.53 | t_{CK} |
| 5 | t_{DQSS} | CC Skew between MCK and DQS transitions ^{2, 3} | -0.25 | 0.25 | t_{CK} |
| 6 | $t_{OS(base)}$ | CC Address and control output setup time relative to MCK rising edge ^{2, 3} | $(t_{CK}/2 - 750)$ | — | ps |
| 7 | $t_{OH(base)}$ | CC Address and control output hold time relative to MCK rising edge ^{2, 3} | $(t_{CK}/2 - 750)$ | — | ps |
| 8 | $t_{DS1(base)}$ | CC DQ and DM output setup time relative to DQS ^{2, 3} | $(t_{CK}/4 - 500)$ | — | ps |
| 9 | $t_{DH1(base)}$ | CC DQ and DM output hold time relative to DQS ^{2, 3} | $(t_{CK}/4 - 500)$ | — | ps |
| 10 | t_{DQSQ} | CC DQS-DQ skew for DQS and associated DQ inputs ² | $-(t_{CK}/4 - 600)$ | $(t_{CK}/4 - 600)$ | ps |

¹ Measured with clock pin loaded with differential 100 Ω termination resistor.

² All transitions measured at mid-supply ($V_{DD_MEM_IO}/2$).

³ Measured with all outputs except the clock loaded with 50 Ω termination resistor to $V_{DD_MEM_IO}/2$.

Figure 22 shows the DDR SDRAM write timing.

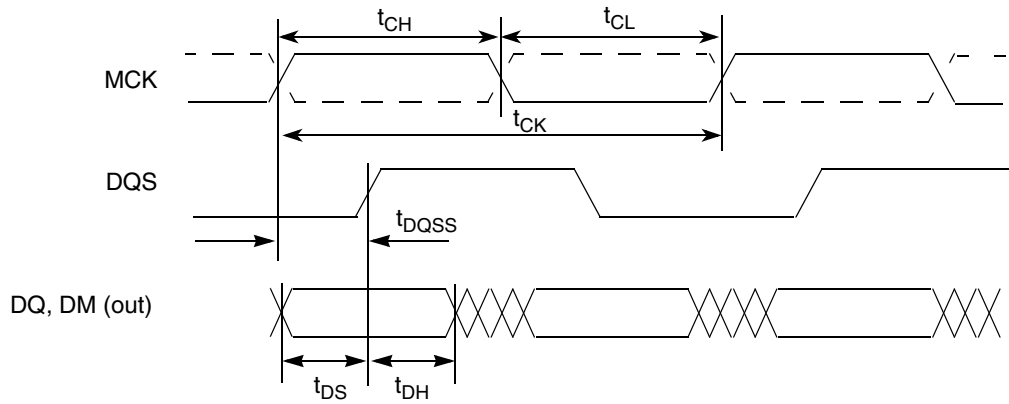


Figure 22. DDR write timing

Figure 23 and Figure 24 show the DDR SDRAM read timing.

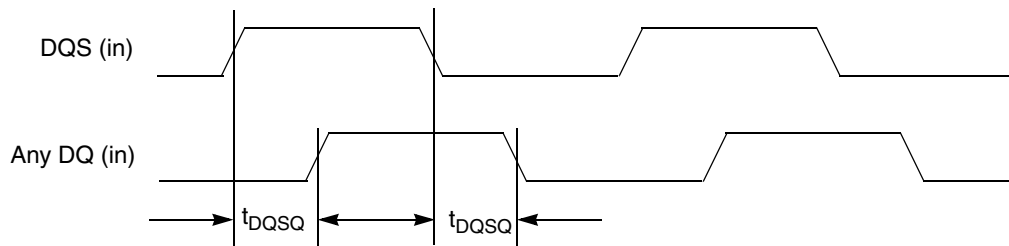


Figure 23. DDR read timing, DQ vs. DQS

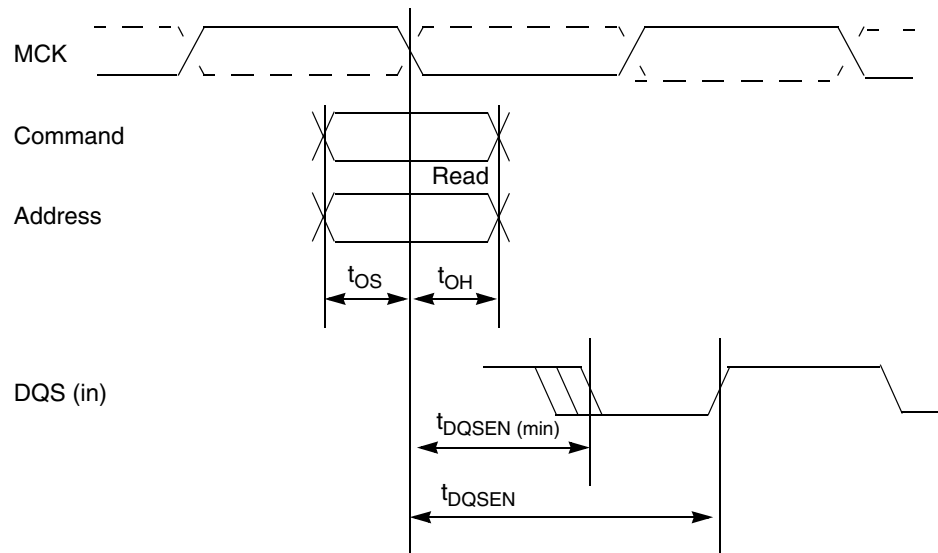


Figure 24. DDR read timing, DQSEN

Figure 25 provides the AC test load for the DDR bus.

Electrical characteristics

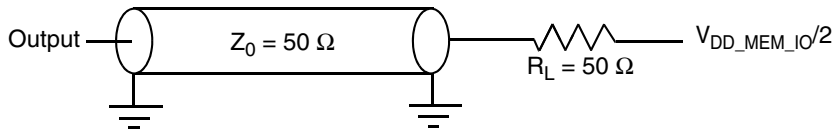


Figure 25. DDR AC test load

3.22.2 IEEE 1149.1 (JTAG) interface timing

3.22.2.1 Standard interface timing

Table 62. JTAG pin AC electrical characteristics

| No. | Symbol | | Parameter | Conditions | Min | Max | Unit |
|-----|----------------------|---|--|------------|-----|-----|------|
| 1 | t_{JCYC} | D | TCK cycle time ¹ | — | 60 | — | ns |
| 2 | t_{JDC} | D | TCK clock pulse width (measured at $V_{DDE}/2$) | — | 40 | 60 | % |
| 3 | $t_{TCKRISE}$ | D | TCK rise and fall times (40%–70%) | — | — | 3 | ns |
| 4 | t_{TMSS}, t_{TDIS} | D | TMS, TDI data setup time | — | 12 | — | ns |
| 5 | t_{TMSH}, t_{TDIH} | D | TMS, TDI data hold time | — | 6 | — | ns |
| 6 | t_{TDOV} | D | TCK low to TDO data valid | — | — | 18 | ns |
| 7 | t_{TDOI} | D | TCK low to TDO data invalid | — | 6 | — | ns |
| 8 | t_{TDOHZ} | D | TCK low to TDO high impedance | — | — | 18 | ns |
| 9 | t_{BSDV} | D | TCK falling edge to output valid (BSR) | — | — | 14 | ns |
| 10 | t_{BSDVZ} | D | TCK falling edge to output valid out of high impedance (BSR) | — | — | 15 | ns |
| 11 | t_{BSDHZ} | D | TCK falling edge to output high impedance (BSR) | — | — | 10 | ns |
| 12 | t_{BSDST} | D | Boundary scan input valid to TCK rising edge | — | 15 | — | ns |
| 13 | t_{BSDHT} | D | TCK rising edge to boundary scan input invalid | — | 2 | — | ns |

¹ $f_{TCK} = 1/t_{TCK}$. f_{TCK} must not exceed 1/4 the frequency of the system clock (SYS_CLK).

3.22.2.2 Interface timing for Full Cycle mode

Table 63. JTAG pin Full Cycle mode AC electrical characteristics

| No. | Symbol | | Parameter | Conditions | Min | Max | Unit |
|-----|----------------------|---|--|------------|-----|-----|------|
| 1 | t_{JCYC} | D | TCK cycle time ¹ | — | 40 | — | ns |
| 2 | t_{JDC} | D | TCK clock pulse width (measured at $V_{DDE}/2$) | — | 40 | 60 | % |
| 3 | $t_{TCKRISE}$ | D | TCK rise and fall times (40%–70%) | — | — | 3 | ns |
| 4 | t_{TMSS}, t_{TDIS} | D | TMS, TDI data setup time | — | 12 | — | ns |
| 5 | t_{TMSH}, t_{TDIH} | D | TMS, TDI data hold time | — | 6 | — | ns |
| 6 | t_{TDOV} | D | TCK low to TDO data valid | — | — | 18 | ns |
| 7 | t_{TDOI} | D | TCK low to TDO data invalid | — | 6 | — | ns |

¹ $f_{TCK} = 1/t_{TCK}$. f_{TCK} needs to be smaller than the system clock (SYS_CLK). This frequency is valid only in special modes where TDO is sampled at the next falling edge for Core0/1 Nexus TAPs and hence full cycle is given to TDO for settling before it is sampled.

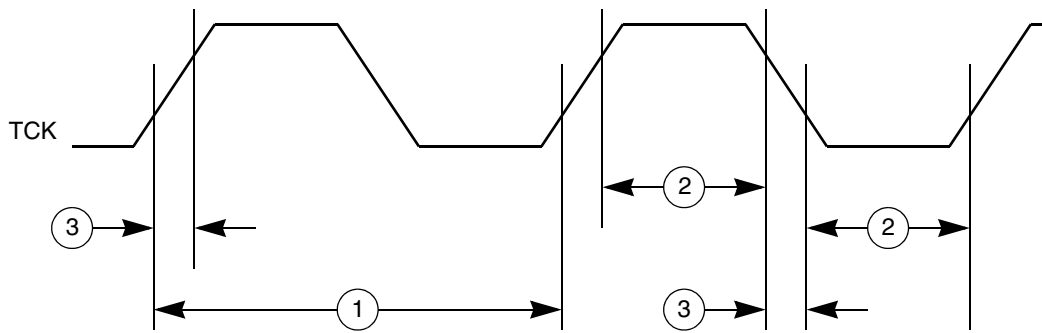


Figure 26. JTAG test clock input timing

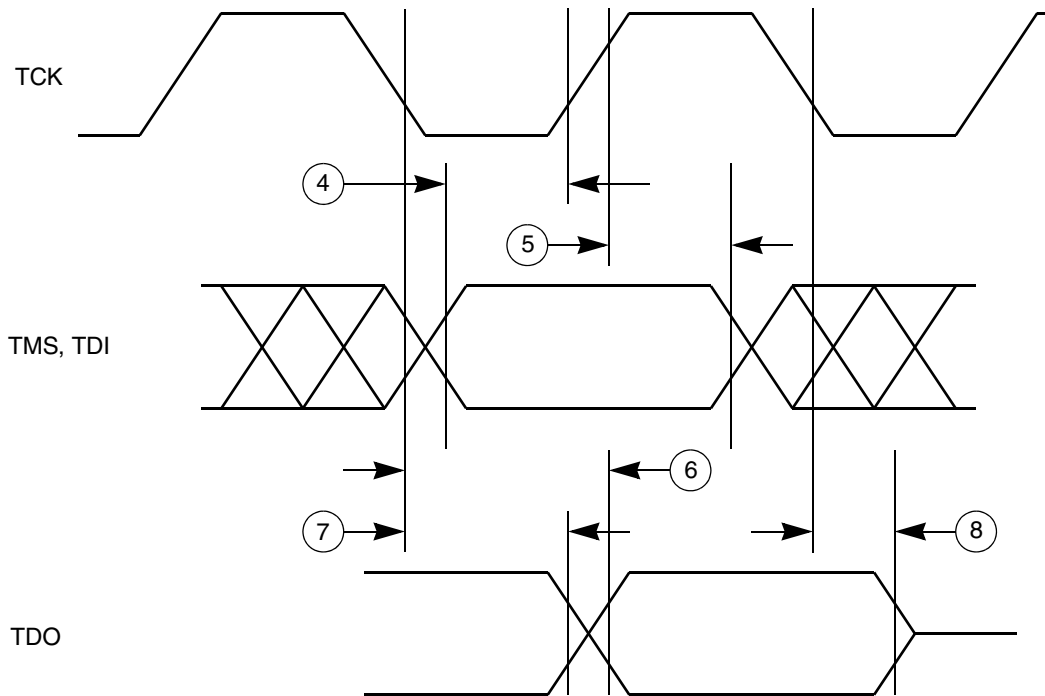


Figure 27. JTAG test access port timing

Electrical characteristics

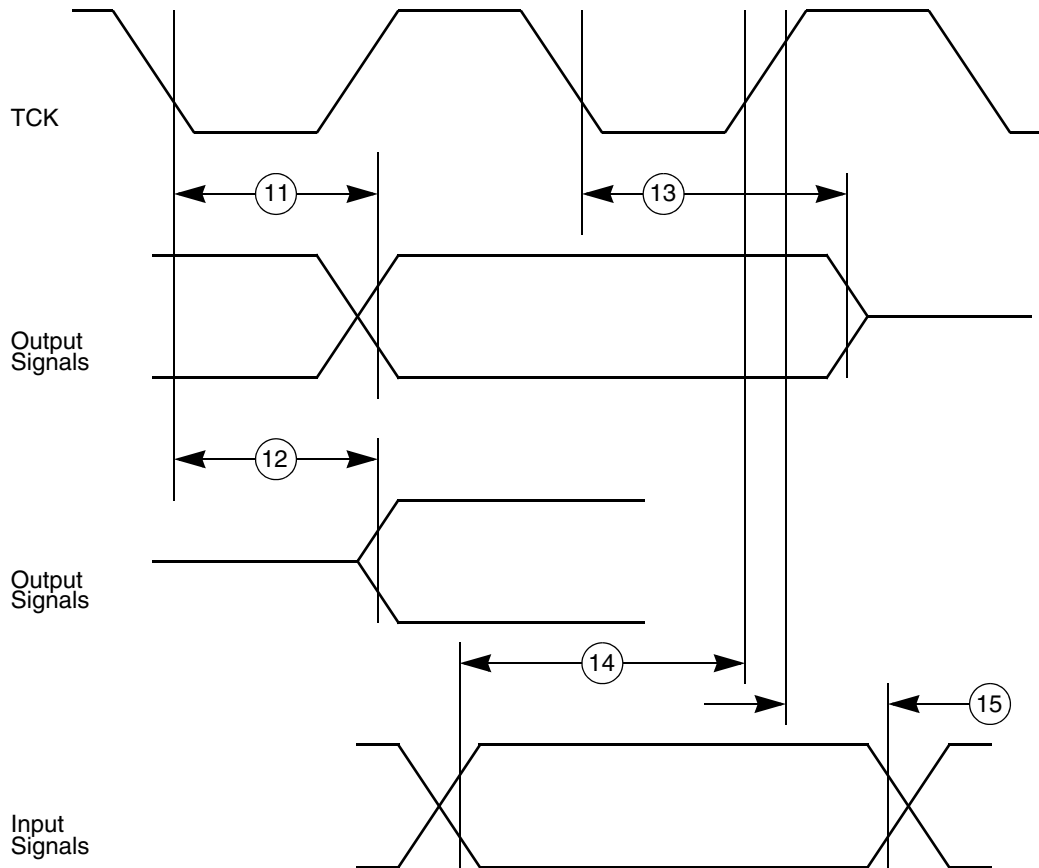


Figure 28. JTAG boundary scan timing

3.22.3 Nexus timing

Table 64. Nexus debug port timing Div mode = 2¹

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|--------------|--|------------|-------|------|------------|
| 1 | t_{MCKO} | MCKO cycle time | — | 16.67 | — | ns |
| 2 | t_{MDC} | MCKO duty cycle ² | — | 50 | 50 | % |
| 3 | t_{MDOV} | MCKO Low to MDO, \overline{MSEO} , $\overline{EVT0}$ data valid ³ | — | -1.67 | 3.34 | ns |
| 4 | t_{EVTIPW} | \overline{EVTI} pulse width. Captured on JTAG TCK. | — | 4.0 | — | t_{JCYC} |
| 5 | t_{PW} | MDO, \overline{MSEO} , $\overline{EVT0}$ pulse width in SDR mode | — | 1 | — | t_{MCKO} |

¹ All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal. Rise/Fall time for Nexus signals can be derived from Fast GPIO pad specification section.

² Jitter/tolerance for MCKO clock is derived from PLL. Please see PLL section for jitter specification.

³ MDO, \overline{MSEO} , and $\overline{EVT0}$ data is held valid until next MCKO low cycle in SDR mode. For DDR mode, this timing is same for both MCKO edges.

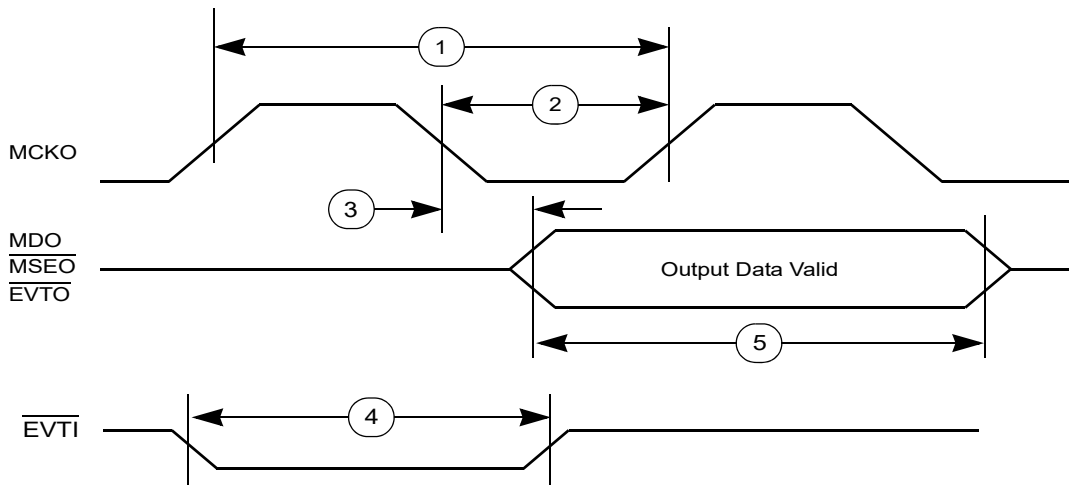


Figure 29. Nexus SDR (Even divisor) timing

Table 65. Nexus debug port timing Divide by 3 SDR mode¹

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|--------------|---|------------|-------|------|------------|
| 1 | t_{MCKO} | CC MCKO cycle time | — | 16.67 | — | ns |
| 2 | t_{MDC} | CC MCKO duty cycle ² | — | 33 | 66 | % |
| 3 | t_{MDOV} | CC MCKO Low to MDO, $\overline{MSE0}$, \overline{EVTO} data valid | — | -1.67 | 3.34 | ns |
| 4 | t_{EVTIPW} | CC \overline{EVTI} pulse width. Captured on JTAG TCK. | — | 4.0 | — | t_{JCYC} |
| 5 | t_{PW} | CC MDO, $\overline{MSE0}$, \overline{EVTO} pulse width in SDR mode | — | 1 | — | t_{MCKO} |

¹ MDO, $\overline{MSE0}$, and \overline{EVTO} data is held valid until next MCKO low cycle in SDR mode. Rise/Fall time for Nexus signals can be derived from Fast GPIO pad specification section.

² Jitter/tolerance for MCKO clock is derived from PLL. Please see PLL section for jitter specification.

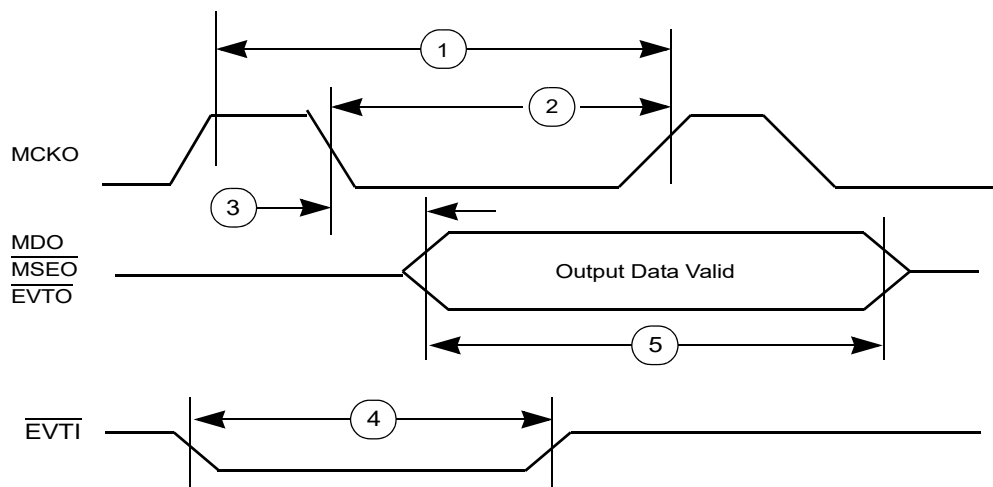


Figure 30. Nexus SDR output timing for DIV=3

Table 66. Nexus debug port timing DIVIDE by 4 DDR mode¹

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|--------------|---|------------|-------|------|------------|
| 1 | t_{MCKO} | CC MCKO cycle time | — | 22.22 | — | ns |
| 2 | t_{MDC} | CC MCKO duty cycle ² | — | 50 | 50 | % |
| 3 | t_{MDOV} | CC MCKO Low to MDO, \overline{MSEO} , $\overline{EVT0}$ data valid ³ | — | -2.23 | 4.45 | ns |
| 4 | t_{EVTIPW} | CC \overline{EVTI} pulse width | — | 4.0 | — | t_{CYC} |
| 5 | t_{PW} | CC MDO, \overline{MSEO} , $\overline{EVT0}$ pulse width in DDR mode | — | 0.5 | — | t_{MCKO} |

- ¹ All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal. Rise/Fall time for Nexus signals can be derived from Fast GPIO pad specification section.
- ² Jitter/tolerance for MCKO clock is derived from PLL. Please see PLL section for jitter specification.
- ³ MDO, \overline{MSEO} , and $\overline{EVT0}$ data is held valid for half of time period. Using this time period, Data valid window for these signals is between 0.2 t_{MCKO} to 0.4 t_{MCKO} starting from each MCKO edge.

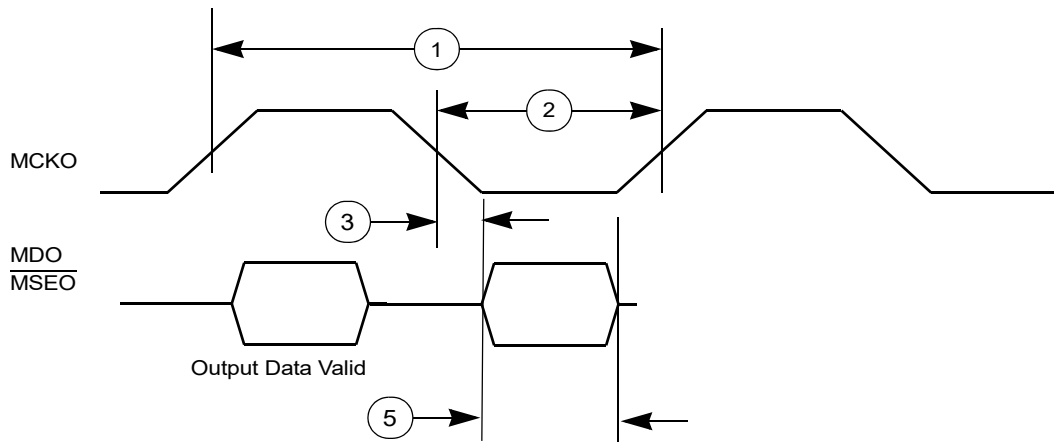


Figure 31. Nexus DDR mode timing

3.22.4 External interrupt timing (IRQ pins)

Table 67. External interrupt timing (NMI IRQ)

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|------------|---------------------------------------|------------|-----|-----|-----------|
| 1 | t_{IPWL} | SR IRQ pulse width low | — | 3 | — | t_{CYC} |
| 2 | t_{IPWH} | SR IRQ pulse width high | — | 3 | — | t_{CYC} |
| 3 | t_{ICYC} | SR IRQ edge to edge time ¹ | — | 6 | — | t_{CYC} |

¹ Applies when IRQ pins are configured for rising edge or falling edge events, but not both.

Table 68. External interrupt timing (GPIO IRQ)

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|------------|-------------------------|------------|-----|-----|-----------|
| 1 | t_{IPWL} | SR IRQ pulse width low | — | 3 | — | t_{CYC} |
| 2 | t_{IPWH} | SR IRQ pulse width high | — | 3 | — | t_{CYC} |

Table 68. External interrupt timing (GPIO IRQ) (continued)

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|-----------------------|------------------------------------|------------|-----|-----|------------------|
| 3 | t_{CYC} SR | IRQ edge to edge time ¹ | — | 6 | — | t_{CYC} |

¹ Applies when IRQ pins are configured for rising edge or falling edge events, but not both.

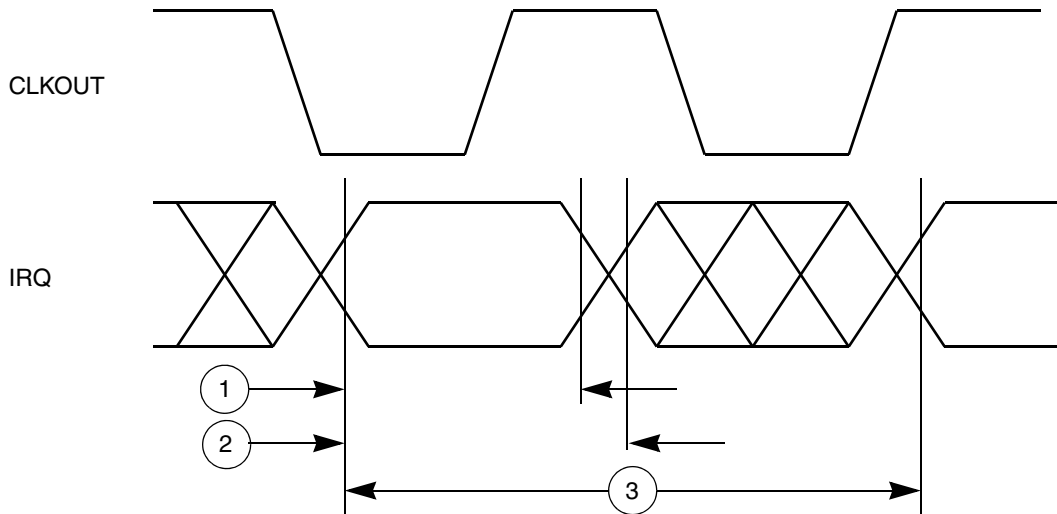


Figure 32. External interrupt timing

3.22.5 FlexCAN timing

Table 69. FlexCAN timing

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|---------------------------|--|------------|-----|-----|--------|
| 1 | $f_{\text{CAN_TX}}$ CC | FlexCAN design target transmit data rate | — | 10 | — | MBit/s |
| 2 | $f_{\text{CAN_RX}}$ CC | FlexCAN design target receive data rate | — | 10 | — | MBit/s |

3.22.6 DSPI timing

Table 70. DSPI timing

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|-----------------------|------------------|--------------------------------------|-----------------------------|-----------------------------|------|
| 1 | t_{SCK} CC | DSPI cycle time | Master (MTFE = 0) | 62 | — | ns |
| | | | Slave (MTFE = 0) | 62 | — | |
| | | | Slave receive only mode ¹ | 16 | — | |
| 2 | t_{CSC} CC | PCS to SCK delay | — | 16 | — | ns |
| 3 | t_{ASC} CC | After SCK delay | — | 16 | — | ns |
| 4 | t_{SDC} CC | SCK duty cycle | — | $0.4 \times t_{\text{SCK}}$ | $0.6 \times t_{\text{SCK}}$ | ns |

Table 70. DSPI timing (continued)

| No. | Symbol | | Parameter | Conditions | Min | Max | Unit |
|-----|------------|----|---|---|-----------|--------|------|
| 5 | t_A | CC | Slave access time | \overline{SS} active to SOUT valid | — | 40 | ns |
| 6 | t_{DIS} | CC | Slave SOUT disable time | \overline{SS} inactive to SOUT High-Z or invalid | — | 10 | ns |
| 7 | t_{PCSC} | CC | PCSx to \overline{PCSS} time | — | 13 | — | ns |
| 8 | t_{PASC} | CC | \overline{PCSS} to PCSx time | — | 13 | — | ns |
| 9 | t_{SUI} | CC | Data setup time for inputs | Master (MTFE = 0) | 20 | — | ns |
| | | | | Slave | 2 | — | |
| | | | | Master (MTFE = 1, CPHA = 0) | 5 | — | |
| | | | | Master (MTFE = 1, CPHA = 1) | 20 | — | |
| 10 | t_{HI} | CC | Data hold time for inputs | Master (MTFE = 0) | -5 | — | ns |
| | | | | Slave | 4 | — | |
| | | | | Master (MTFE = 1, CPHA = 0) | 11 | — | |
| | | | | Master (MTFE = 1, CPHA = 1) | -5 | — | |
| 11 | t_{SUO} | CC | Data valid (after SCK edge) | Master (MTFE = 0) | — | 4 | ns |
| | | | | Slave | — | 23 | |
| | | | | Master (MTFE = 1, CPHA = 0) | — | 11 | |
| | | | | Master (MTFE = 1, CPHA = 1) | — | 5 | |
| 12 | t_{HO} | CC | Data hold time for outputs | Master (MTFE = 0) | -2 | — | ns |
| | | | | Slave | 6 | — | |
| | | | | Master (MTFE = 1, CPHA = 0) | 6 | — | |
| | | | | Master (MTFE = 1, CPHA = 1) | -2 | — | |
| 13 | t_{DT} | CC | Delay after Transfer (minimum \overline{CS} negation time) | Continuous mode Non-continuous mode ² | 62 134 | — — | ns |

¹ Slave Receive Only Mode can operate at a maximum frequency of 60 MHz. Note that in this mode, the DSPI can receive data on SIN, but no valid data is transmitted on SOUT.

² In non-continuous mode, this value is always $t_{SCK} \times \text{DSPI_CTAR}[DT] \times \text{DSPI_CTAR}[PDT]$. The minimum permissible value of DT is 2 and the minimum permissible value of PDT is 1. See the DSPI chapter of the *MPC5675K Reference Manual* for more information.

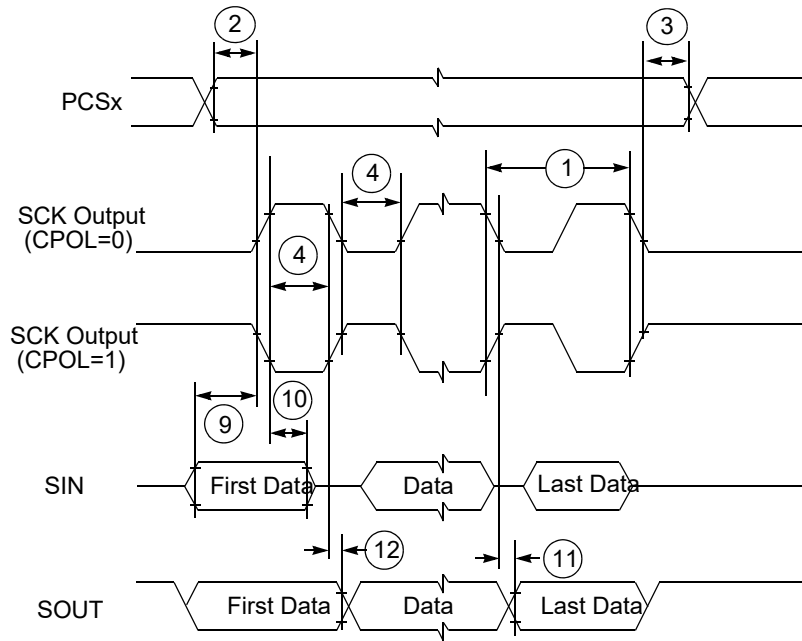


Figure 33. DSPI classic SPI timing—master, CPHA = 0

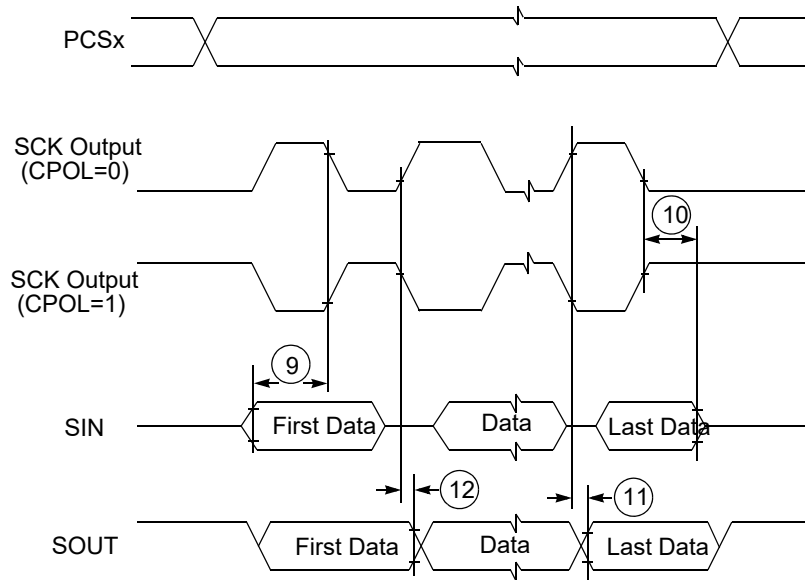


Figure 34. DSPI classic SPI timing—master, CPHA = 1

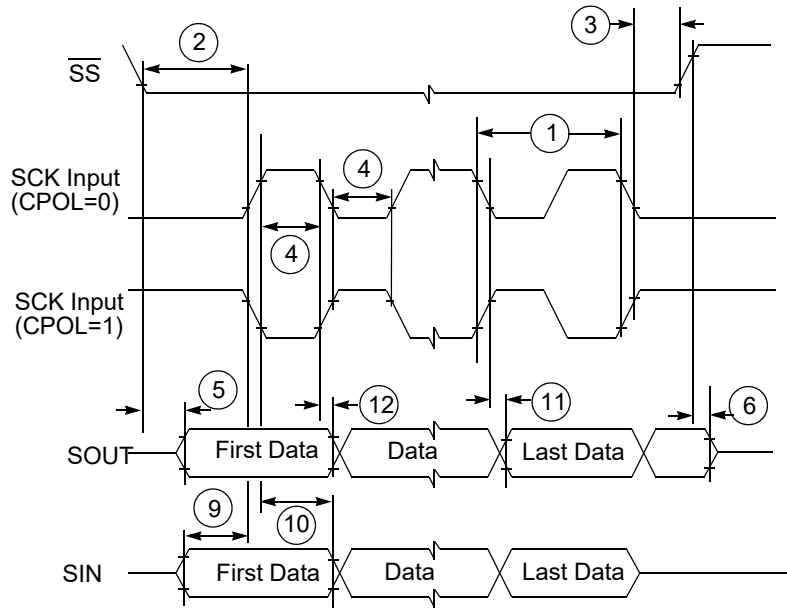


Figure 35. DSPI classic SPI timing—slave, CPHA = 0

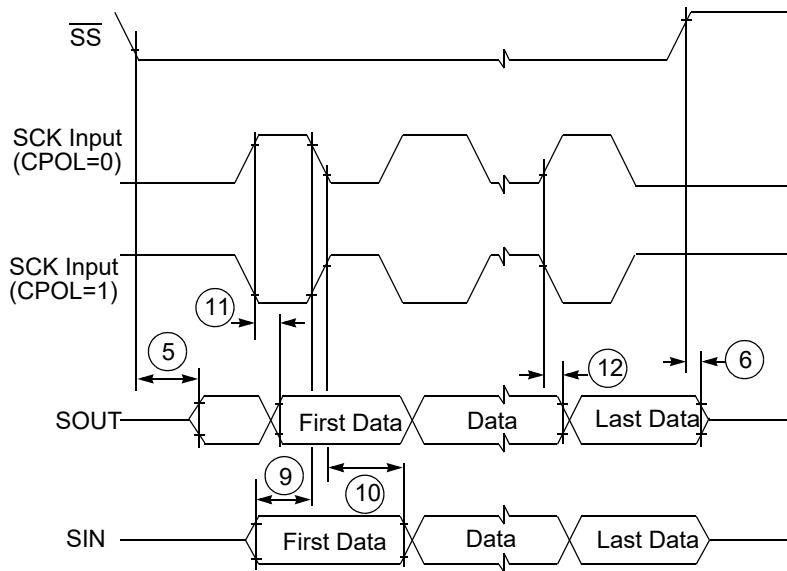


Figure 36. DSPI classic SPI timing—slave, CPHA = 1

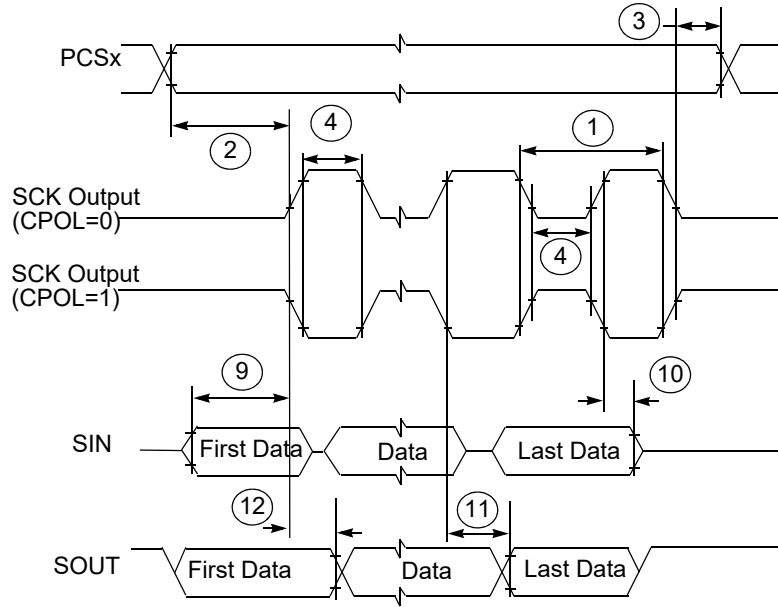


Figure 37. DSPI modified transfer format timing—master, CPHA = 0

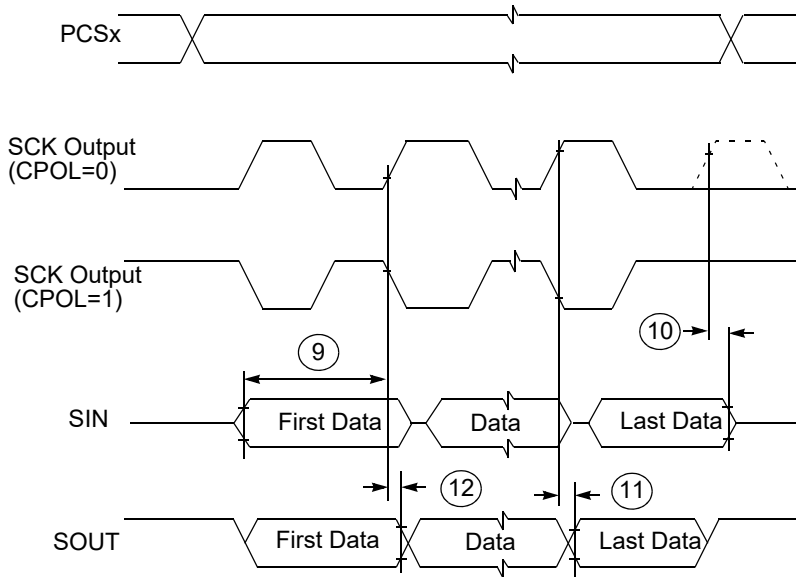


Figure 38. DSPI modified transfer format timing—master, CPHA = 1

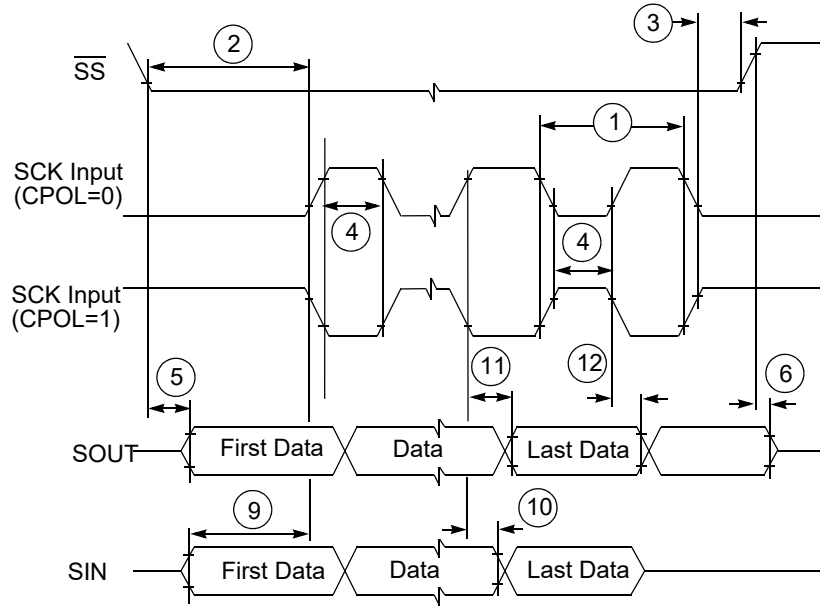


Figure 39. DSPI modified transfer format timing—slave, CPHA = 0

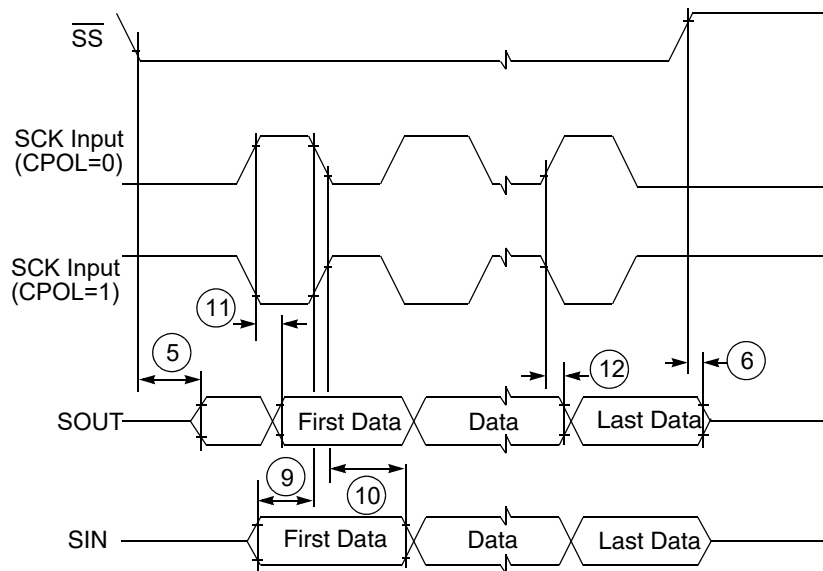


Figure 40. DSPI modified transfer format timing—slave, CPHA = 1

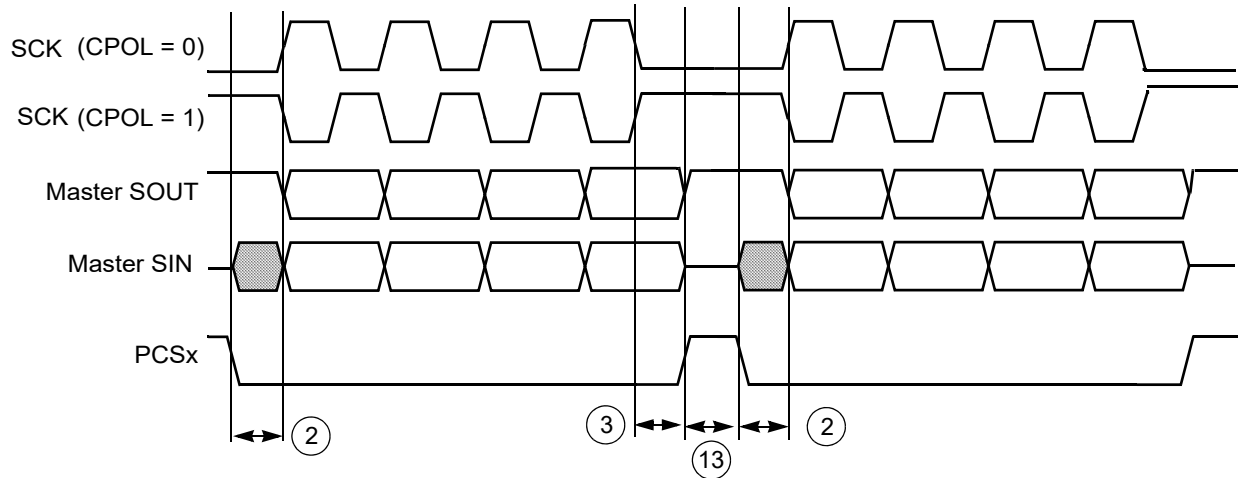


Figure 41. Example of non-continuous format (CPHA = 1, CONT = 0)

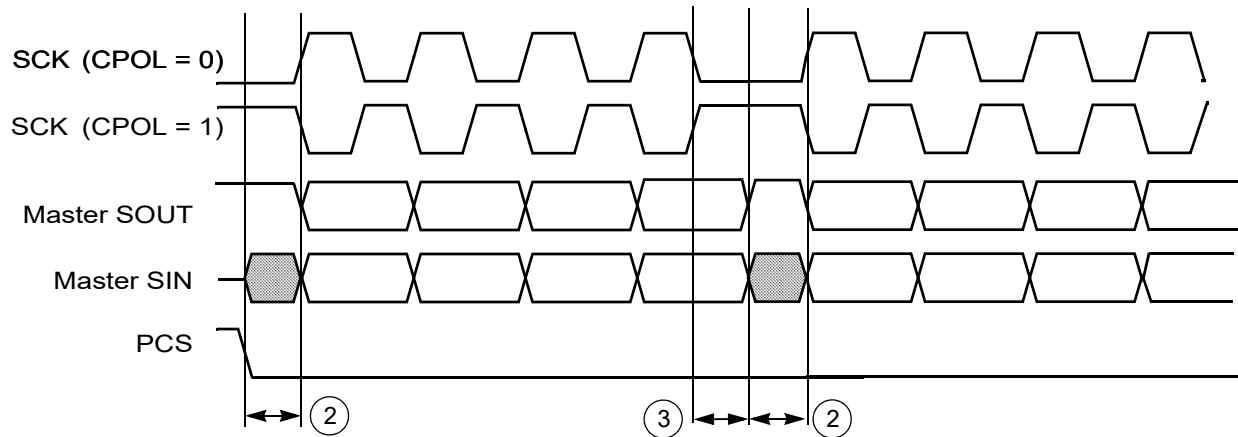


Figure 42. Example of continuous transfer (CPHA = 1, CONT = 1)

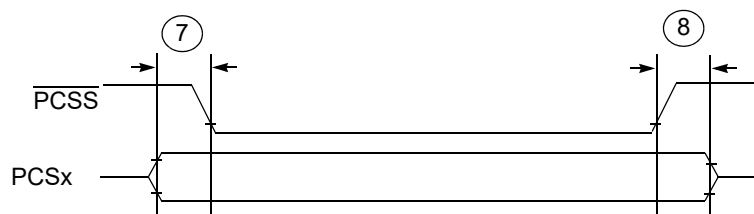


Figure 43. DSPI PCS strobe (\overline{PCSS}) timing

3.22.7 PDI timing

Table 71. PDI electrical characteristics

| No. | Symbol | Parameter | Conditions | Min | Max | Unit |
|-----|---------------------|------------------|------------|-----|-----|------|
| 1 | t_{PDI_CLOCK} SR | PDI clock period | — | 15 | — | ns |

Table 71. PDI electrical characteristics (continued)

| No. | Symbol | SR | Parameter | Conditions | Min | Max | Unit |
|-----|---------------|----|-------------------------------|------------|-----|-----|------|
| 2 | t_{PDI_IS} | SR | Input setup time ¹ | — | 3 | — | ns |
| 3 | t_{PDI_IH} | SR | Input hold time ¹ | — | 3 | — | ns |

¹ Data can be captured at both launching and capturing edge of PDI_CLK.

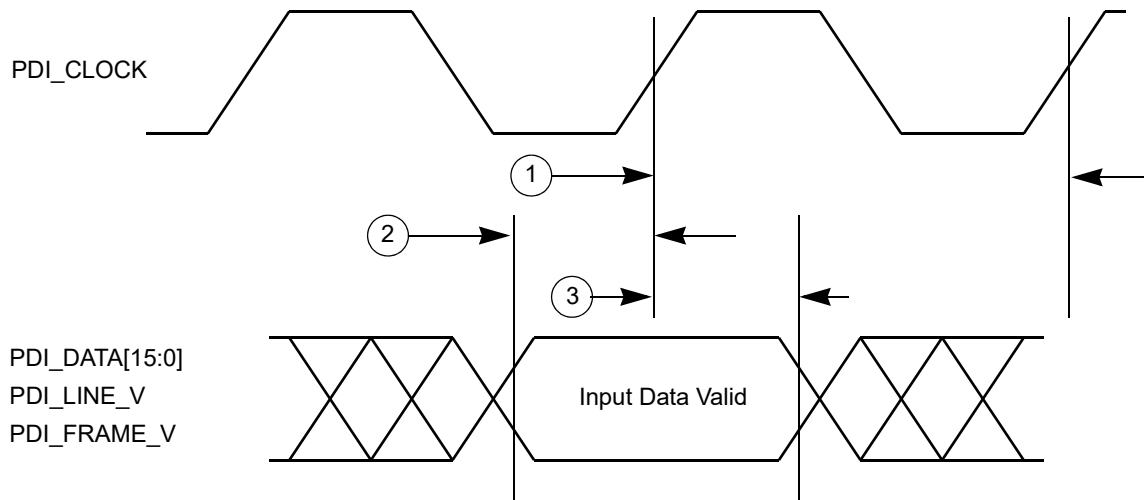


Figure 44. PDI timing

3.22.8 Fast Ethernet interface

MII signals use CMOS signal levels compatible with devices operating at either 5.0 V or 3.3 V. Signals are not TTL compatible. They follow the CMOS electrical characteristics.

3.22.8.1 MII receive signal timing (RXD[3:0], RX_DV, RX_ER, and RX_CLK)

The receiver functions correctly up to a RX_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. In addition, the system clock frequency must exceed two times the RX_CLK frequency.

Table 72. MII receive signal timing

| No. | Parameter | Min | Max | Unit |
|-----|--|-----|-----|---------------|
| 1 | RXD[3:0], RX_DV, RX_ER to RX_CLK setup | 5 | — | ns |
| 2 | RX_CLK to RXD[3:0], RX_DV, RX_ER hold | 5 | — | ns |
| 3 | RX_CLK pulse width high | 40% | 60% | RX_CLK period |
| 4 | RX_CLK pulse width low | 40% | 60% | RX_CLK period |

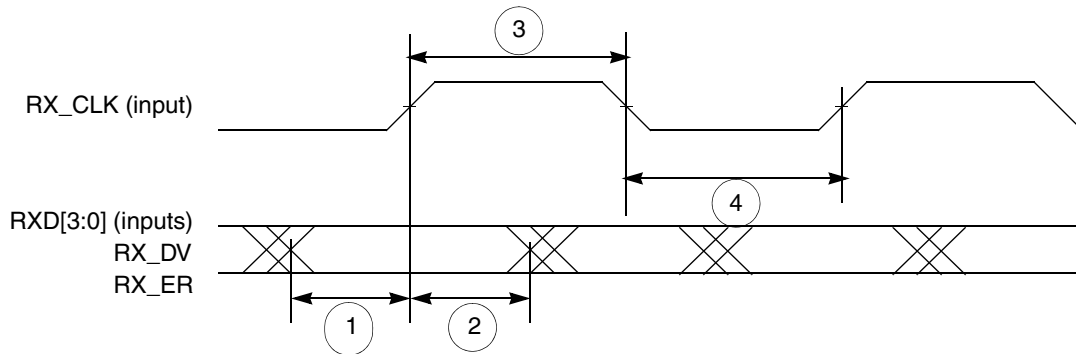


Figure 45. MII receive signal timing diagram

3.22.8.2 MII transmit signal timing (TXD[3:0], TX_EN, TX_ER, TX_CLK)

The transmitter functions correctly up to a TX_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. In addition, the system clock frequency must exceed two times the TX_CLK frequency.

The transmit outputs (TXD[3:0], TX_EN, TX_ER) can be programmed to transition from either the rising or falling edge of TX_CLK, and the timing is the same in either case. This options allows the use of non-compliant MII PHYs.

Refer to the Ethernet chapter for details of this option and how to enable it.

Table 73. MII transmit signal timing¹

| No. | Parameter | Min | Max | Unit |
|-----|--|-----|-----|---------------|
| 5 | TX_CLK to TXD[3:0], TX_EN, TX_ER invalid | 5 | — | ns |
| 6 | TX_CLK to TXD[3:0], TX_EN, TX_ER valid | — | 25 | ns |
| 7 | TX_CLK pulse width high | 40% | 60% | TX_CLK period |
| 8 | TX_CLK pulse width low | 40% | 60% | TX_CLK period |

¹ Output pads configured with SRC = 0b11.

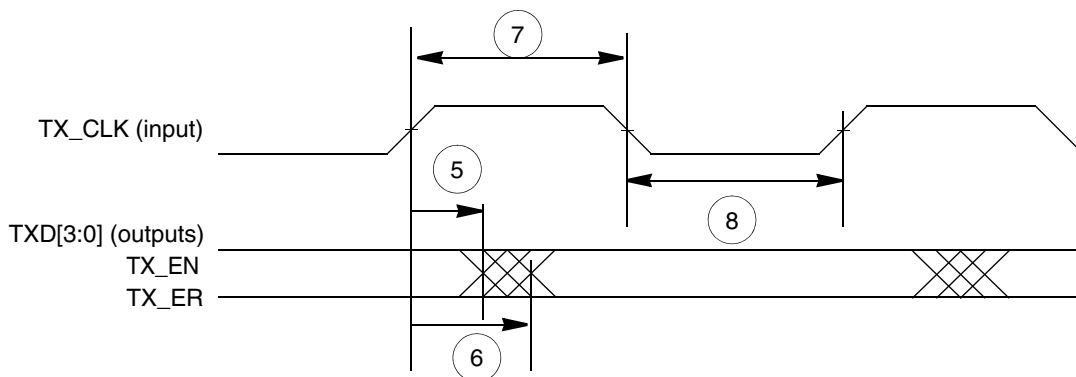


Figure 46. MII transmit signal timing diagram

3.22.8.3 MII async inputs signal timing (CRS and COL)

Table 74. MII async inputs signal timing¹

| No. | Parameter | Min | Max | Unit |
|-----|------------------------------|-----|-----|---------------|
| 9 | CRS, COL minimum pulse width | 1.5 | — | TX_CLK period |

¹ Output pads configured with SRC = 0b11.

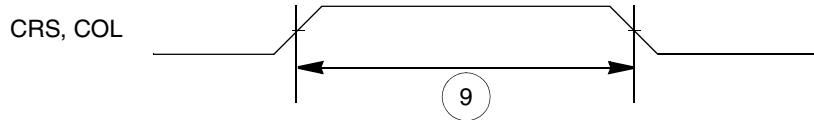


Figure 47. MII async inputs timing diagram

3.22.8.4 MII serial management channel timing (MDIO and MDC)

The FEC functions correctly with a maximum MDC frequency of 5 MHz.

Table 75. MII serial management channel timing¹

| No. | Parameter | Min | Max | Unit |
|-----|---|-----|-----|------------|
| 10 | MDC falling edge to MDIO output invalid (minimum propagation delay) | 0 | — | ns |
| 11 | MDC falling edge to MDIO output valid (max prop delay) | — | 25 | ns |
| 12 | MDIO (input) to MDC rising edge setup | 10 | — | ns |
| 13 | MDIO (input) to MDC rising edge hold | 0 | — | ns |
| 14 | MDC pulse width high | 40% | 60% | MDC period |
| 15 | MDC pulse width low | 40% | 60% | MDC period |

¹ Output pads configured with SRC = 0b11.

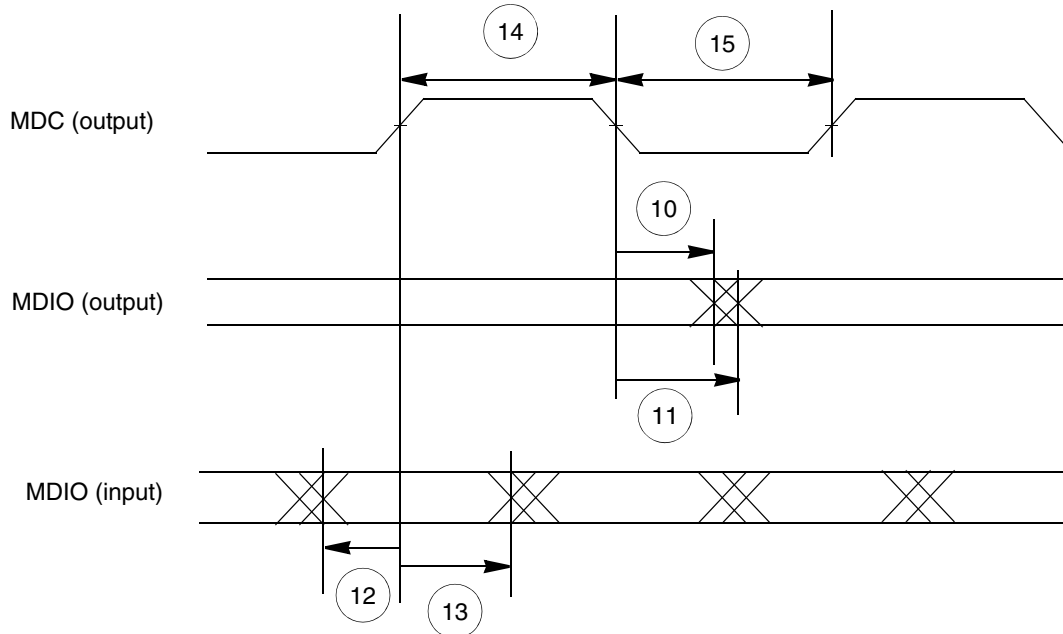


Figure 48. MII serial management channel timing diagram

3.22.9 External Bus Interface (EBI) timing

Table 76. EBI timing

| No. | Symbol | Parameter | 45 MHz (Ext. Bus Freq) ¹ | | Unit | Notes |
|-----|-----------|---|-------------------------------------|-----|-------|---|
| | | | Min | Max | | |
| 1 | t_C | CC D_CLKOUT period | 22.2 | — | ns | Signals are measured at 50% V_{DDE} . |
| 2 | t_{CDC} | CC D_CLKOUT duty cycle | 45% | 55% | t_C | — |
| 3 | t_{CRT} | CC D_CLKOUT rise time | — | — | ns | — |
| 4 | t_{CFT} | CC D_CLKOUT fall time | — | — | ns | — |
| 5 | t_{COH} | CC D_CLKOUT posedge to output signal invalid or high Z (hold time) D_ADD[9:30] D_BDIP D_CS[0:3] D_DAT[0:15] D_OE D_RD_WR D_TA D_TS D_WE[0:3]/D_BE[0:3] | 1.0 | — | ns | — |

Table 76. EBI timing (continued)

| No. | Symbol | Parameter | 45 MHz (Ext. Bus Freq) ¹ | | Unit | Notes |
|-----|------------------|---|-------------------------------------|-----|------|---|
| | | | Min | Max | | |
| 6 | t _{COV} | CC D_CLKOUT posedge to output signal valid (output delay) D_ADD[9:30] D_BDIP D_CS[0:3] D_DAT[0:15] D_OE D_RD_WR D_TA D_TS D_WE[0:3]/D_BE[0:3] | — | 10 | ns | — |
| 7 | t _{CIS} | CC Input signal valid to D_CLKOUT posedge (setup time) D_ADD[9:30] D_DAT[0:15] D_RD_WR D_TA D_TS | 7.5 | — | ns | — |
| 8 | t _{CIH} | CC D_CLKOUT posedge to input signal invalid (hold time) D_ADD[9:30] D_DAT[0:15] D_RD_WR D_TA D_TS | 1.0 | — | ns | — |
| 9 | t _{APW} | CC D_ALE pulse width | 6.5 | — | ns | The timing is for asynchronous external memory system. |
| 10 | t _{AAI} | CC D_ALE negated to address invalid | 1.5 | — | ns | <ul style="list-style-type: none"> The timing is for asynchronous external memory system. ALE is measured at 50% of VDDE. |

¹ Speed is the nominal maximum frequency. Maximum core speed allowed is 180 MHz plus frequency modulation (FM).

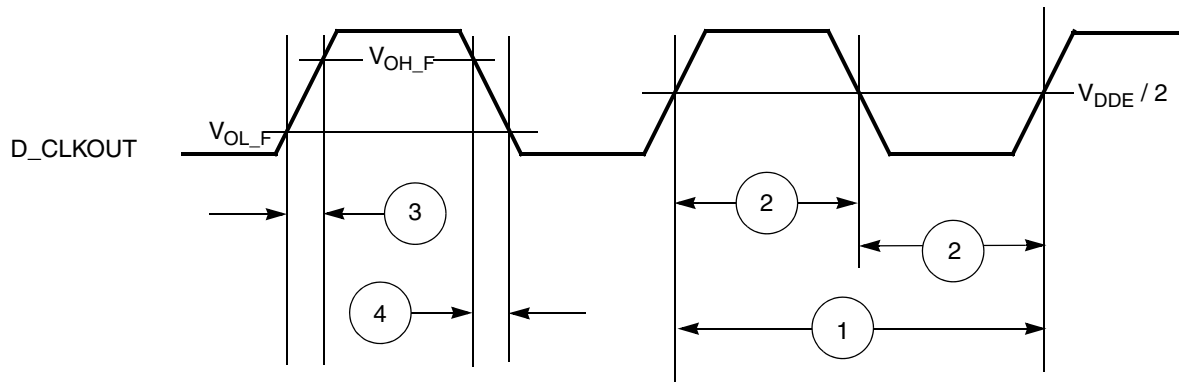


Figure 49. D_CLKOUT timing

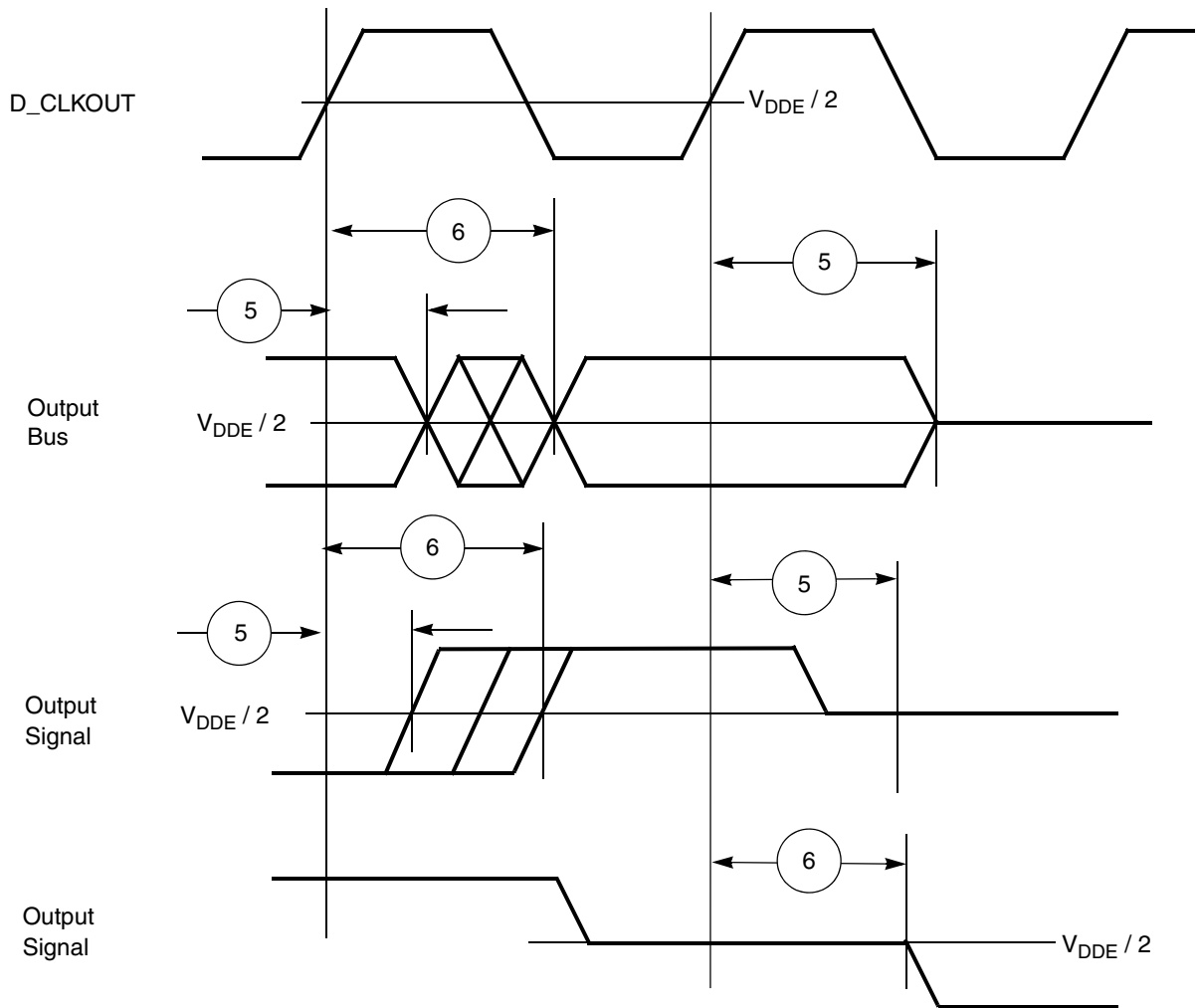


Figure 50. Synchronous output timing

Electrical characteristics

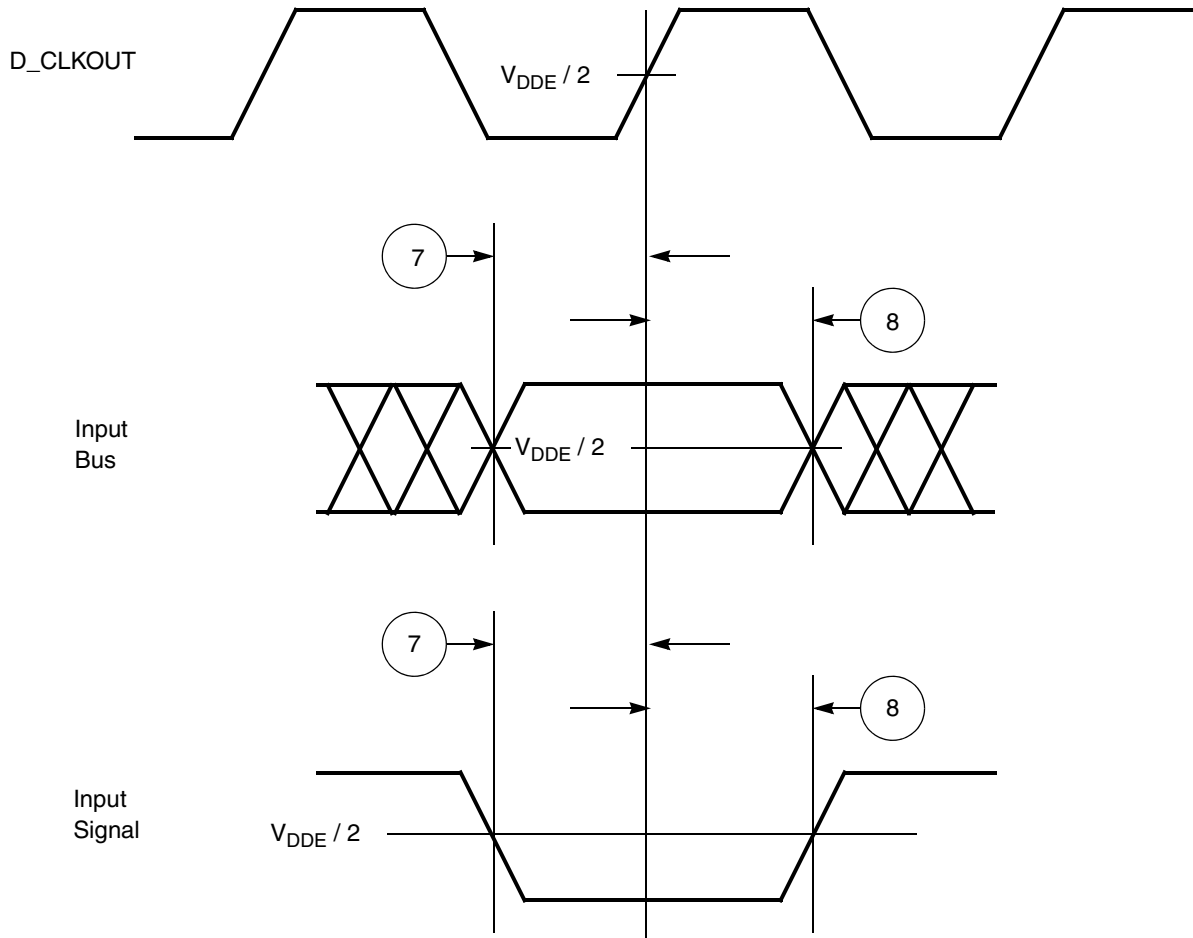


Figure 51. Synchronous input timing

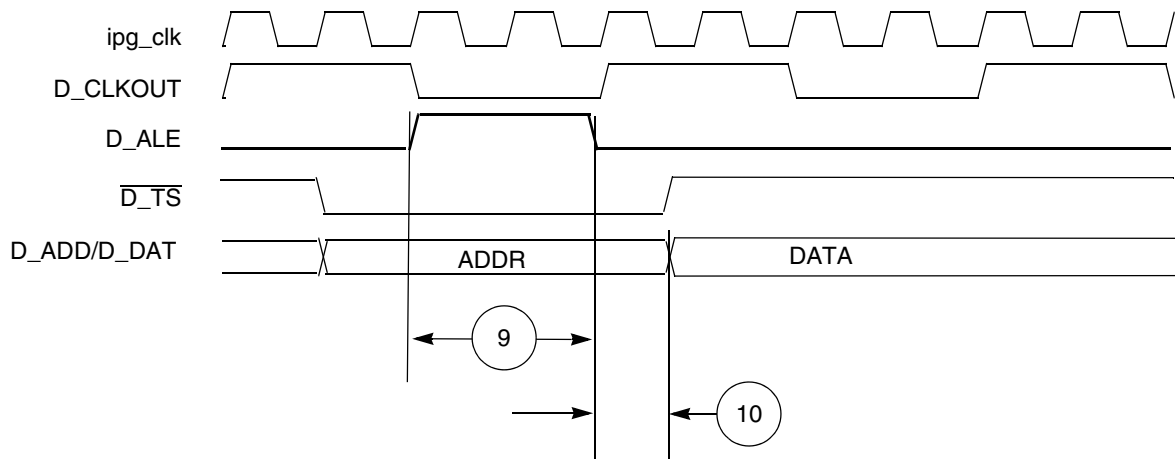


Figure 52. ALE signal timing

3.22.10 I²C timing

Table 77. I²C SCL and SDA input timing specifications

| No. | Symbol | Parameter | Value | | Unit |
|-----|--------|--|-------|-----|---------------------------|
| | | | Min | Max | |
| 1 | — | D Start condition hold time | 2 | — | IP bus cycle ¹ |
| 2 | — | D Clock low time | 8 | — | IP bus cycle ¹ |
| 3 | — | D Data hold time | 0.0 | — | ns |
| 4 | — | D Clock high time | 4 | — | IP bus cycle ¹ |
| 5 | — | D Data setup time | 0.0 | — | ns |
| 6 | — | D Start condition setup time (for repeated start condition only) | 2 | — | IP bus cycle ¹ |
| 7 | — | D Stop condition setup time | 2 | — | IP bus cycle ¹ |

¹ Inter Peripheral Clock is the clock at which the I²C peripheral is working in the device.

Table 78. I²C SCL and SDA output timing specifications

| No. | Symbol | Parameter | Value | | Unit |
|----------------|--------|--|-------|------|---------------------------|
| | | | Min | Max | |
| 1 ¹ | — | D Start condition hold time | 6 | — | IP bus cycle ² |
| 2 ¹ | — | D Clock low time | 10 | — | IP bus cycle ¹ |
| 3 ³ | — | D SCL/SDA rise time | — | 99.6 | ns |
| 4 ¹ | — | D Data hold time | 7 | — | IP bus cycle ¹ |
| 5 ¹ | — | D SCL/SDA fall time | — | 99.5 | ns |
| 6 ¹ | — | D Clock high time | 10 | — | IP bus cycle ¹ |
| 7 ¹ | — | D Data setup time | 2 | — | IP bus cycle ¹ |
| 8 ¹ | — | D Start condition setup time (for repeated start condition only) | 20 | — | IP bus cycle ¹ |
| 9 ¹ | — | D Stop condition setup time | 10 | — | IP bus cycle ¹ |

¹ Programming IBFD (I²C bus Frequency Divider) with the maximum frequency results in the minimum output timings listed. The I²C interface is designed to scale the data transition time, moving it to the middle of the SCL low period. The actual position is affected by the prescale and division values programmed in IFDR.

² Inter Peripheral Clock is the clock at which the I²C peripheral is working in the device.

³ Because SCL and SDA are open-drain-type outputs, which the processor can only actively drive low, the time SCL or SDA takes to reach a high level depends on external signal capacitance and pullup resistor values.

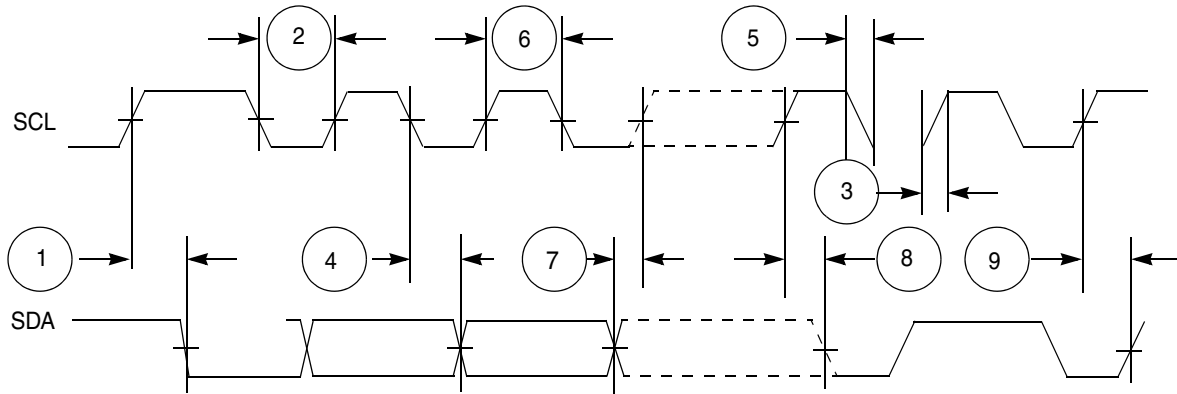


Figure 53. I²C input/output timing

3.22.11 LINFlex timing

The maximum bit rate is 1.875 MBit/s.

4 Package characteristics

4.1 Package mechanical data

4.1.1 257 MAPBGA

Package characteristics

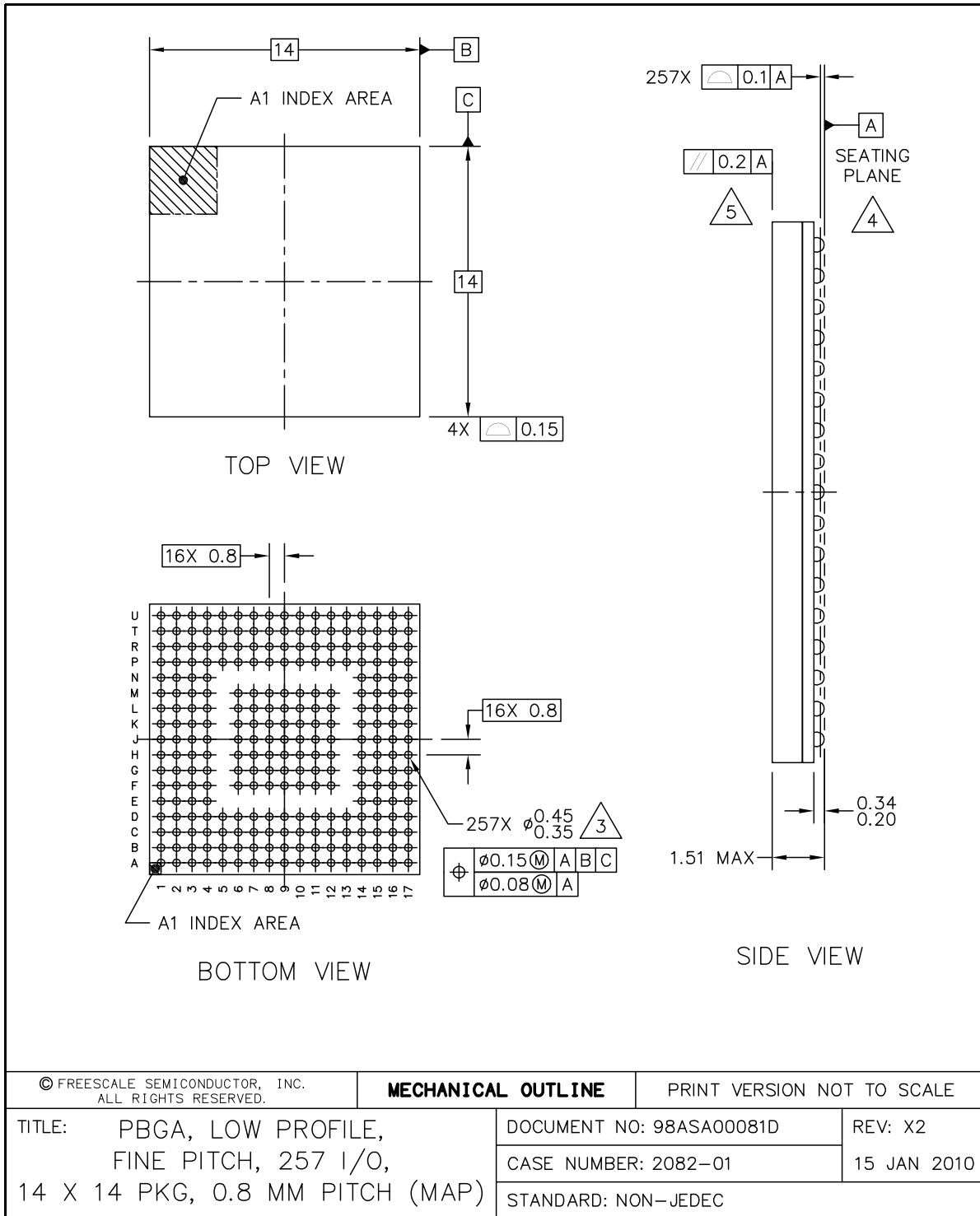


Figure 54. 257 MAPBGA mechanical data (1 of 2)

| | | | |
|--|---------------------------|----------------------------|--|
| NOTES: 1. ALL DIMENSIONS IN MILLIMETERS. 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994. 3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A. 4. DATUM A, THE SEATING PLANE, IS DETERMINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS. 5. PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE. | | | |
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| TITLE: PBGA, LOW PROFILE, FINE PITCH, 257 I/O, 14 X 14 PKG, 0.8 MM PITCH (MAP) | DOCUMENT NO: 98ASA00081D | REV: X2 | |
| | CASE NUMBER: 2082-01 | 15 JAN 2010 | |
| | STANDARD: NON-JEDEC | | |

Figure 55. 257 MAPBGA mechanical data (2 of 2)

4.1.2 473 MAPBGA

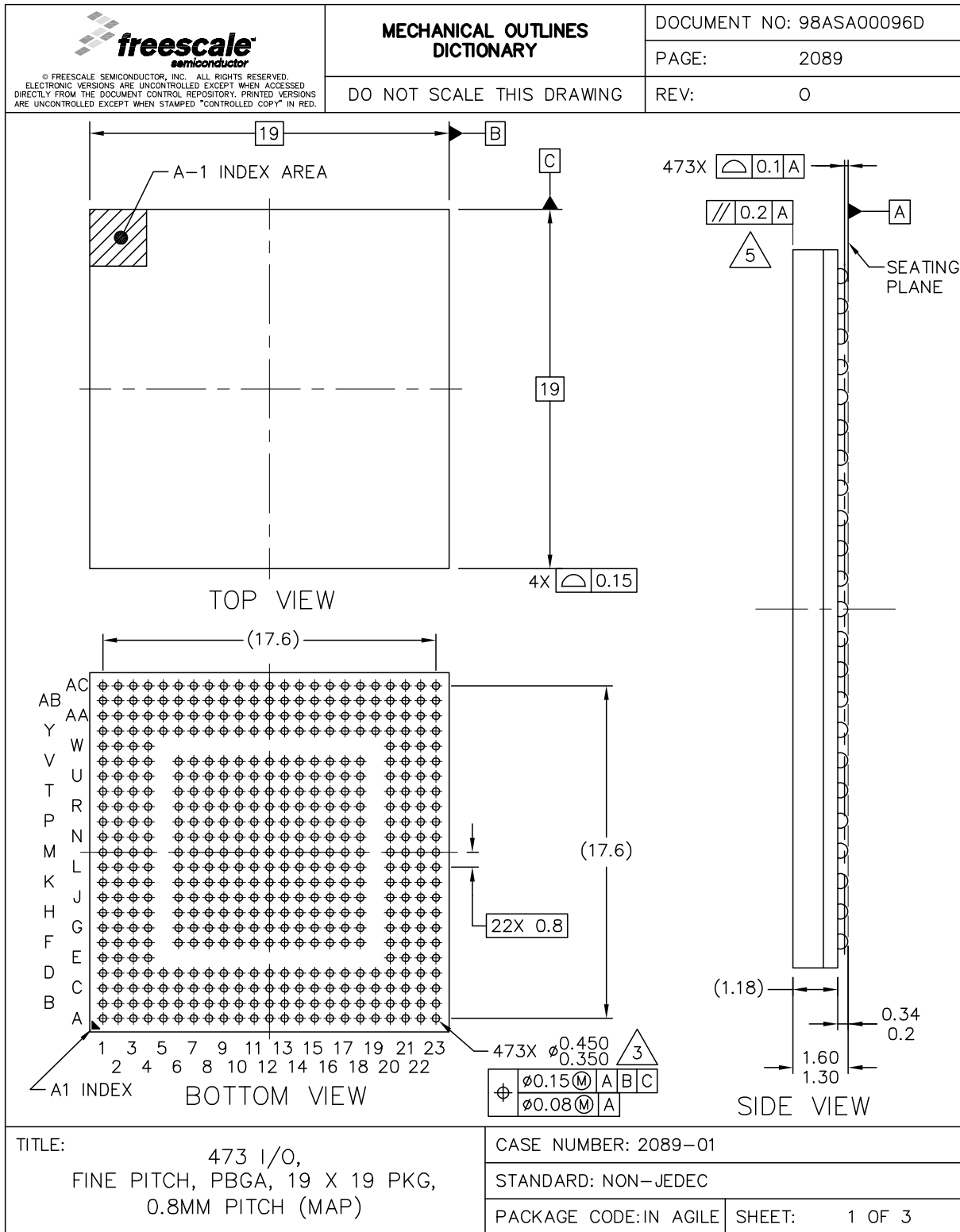


Figure 56. 473 MAPBGA package mechanical data (1 of 3)


| | | | | |
|--|---|--|--------------------------|----------|
|  <small>© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED. ELECTRONIC VERSIONS ARE UNCONTROLLED EXCEPT WHEN ACCESSED DIRECTLY FROM THE DOCUMENT CONTROL REPOSITORY. PRINTED VERSIONS ARE UNCONTROLLED EXCEPT WHEN STAMPED "CONTROLLED COPY" IN RED.</small> | MECHANICAL OUTLINES DICTIONARY | | DOCUMENT NO: 98ASA00096D | |
| | DO NOT SCALE THIS DRAWING | | PAGE: | 2089 |
| | | | REV: | 0 |
| <p>NOTES:</p> <ol style="list-style-type: none"> 1. ALL DIMENSIONS IN MILLIMETERS. 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994. 3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A. 4. DATUM A, THE SEATING PLANE, IS DETERMINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS. 5. PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE. | | | | |
| TITLE: 473 I/O, FINE PITCH, PBGA, 19 X 19 PKG, 0.8MM PITCH (MAP) | | | CASE NUMBER: 2089-01 | |
| | | | STANDARD: NON-JEDEC | |
| | | | PACKAGE CODE:IN AGILE | SHEET: 2 |

Figure 57. 473 MAPBGA package mechanical data (2 of 3)

Package characteristics


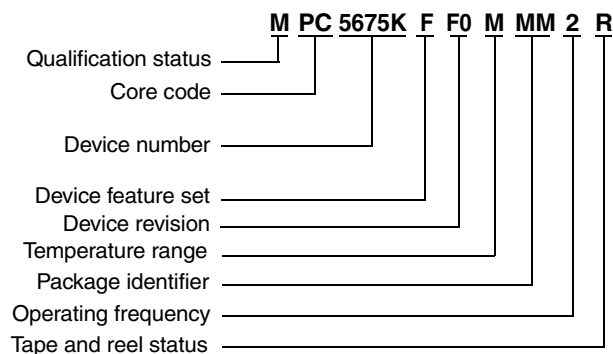
|  <small>© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED. ELECTRONIC VERSIONS ARE UNCONTROLLED EXCEPT WHEN ACCESSED DIRECTLY FROM THE DOCUMENT CONTROL REPOSITORY. PRINTED VERSIONS ARE UNCONTROLLED EXCEPT WHEN STAMPED "CONTROLLED COPY" IN RED.</small> | | <h2>REVISION HISTORY</h2> | | DOCUMENT NO: 98ASA00096D | |
|--|------------|---------------------------|-----------------------|--------------------------|---|
| | | | | PAGE: 2089 | |
| | | | | REV: 0 | |
| LTR | ORIGINATOR | REVISIONS | DRAFTER | DATE | |
| 0 | D. VO | RELEASED FOR PRODUCTION | DSS | 08 JUN 2009 | |
| | | | | | |
| TITLE: 473 I/O, FINE PITCH, PBGA, 19 X 19 PKG, 0.8MM PITCH (MAP) | | | CASE NUMBER: 2089-01 | | |
| | | | STANDARD: NON-JEDEC | | |
| | | | PACKAGE CODE:IN AGILE | SHEET: | 3 |

Figure 58. 473 MAPBGA package mechanical data (3 of 3)

5 Orderable parts



Device feature set

F = FlexRay

Device revision

F0 = Fab and Mask

Temperature range

V = -40 °C to 105 °C
M = -40 °C to 125 °C
(ambient)

Package identifier

MM = 257 BGA
MS = 473 BGA

Operating frequency

1 = 150 MHz
2 = 180 MHz

Tape and reel status

R = Tape and reel
(blank) = Trays

Qualification status

P = Pre-qualification
M = Fully spec. qualified, general market flow
S = Fully spec. qualified, automotive flow

Note: Not all options are available on all devices.

6 Reference documents

1. Nexus (IEEE-ISTO 5001™—2008)
2. Measurement of emission of ICs—IEC 61967-2
3. Measurement of emission of ICs—IEC 61967-4
4. Measurement of immunity of ICs—IEC 62132-4
5. Semiconductor Equipment and Materials International
3081 Zanker Road
San Jose, CA 95134 USA
(408) 943-6900
6. JEDEC specifications are available at <http://www.jedec.org>
7. MIL-SPEC and EIA/JESD (JEDEC) specifications are available from Global Engineering Documents at 800-854-7179 or 303-397-7956.
8. C.E. Triplett and B. Joiner, “An Experimental Characterization of a 272 PBGA Within an Automotive Engine Controller Module,” Proceedings of SemiTherm, San Diego, 1998, pp. 47–54.
9. G. Kromann, S. Shidore, and S. Addison, “Thermal Modeling of a PBGA for Air-Cooled Applications,” Electronic Packaging and Production, pp. 53–58, March 1998.
10. B. Joiner and V. Adams, “Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling,” Proceedings of SemiTherm, San Diego, 1999, pp. 212–220.

7 Document revision history

Table 79 summarizes revisions to this document.

Beginning with Rev. 4, this revision history uses clickable cross-references for ease of navigation. The numbers and titles in each cross-reference are relative to the latest published release.

Table 79. Revision history

| Revision | Date | Description of Changes |
|----------|-------------|---|
| 1 | 6 Oct 2009 | Initial release. |
| 2 | 6 Dec 2009 | Updated ball map tables, pin mux tables, supply and system pin tables. Added PMC specifications. |
| 3 | 2 Jul 2010 | Updated ball map tables, pin mux tables, supply and system pin tables. Updated pad specifications. Added reset specifications section. |
| 4 | 30 Apr 2011 | <p>Removed thickness dimension from package diagrams on cover page.</p> <p>Added footnote "Do not connect pin directly to a power supply or ground" for MDO[0:15] and MSEO[0:1] pins to Table 9 (257 MAPBGA pin multiplexing) and Table 10 (473 MAPBGA pin multiplexing).</p> <p>In Table 17 (PMC electrical specifications):</p> <ul style="list-style-type: none"> • Added minimum and maximum slew rate specifications for LvdReg. • Removed LvdC minimum and maximum hysteresis specifications • Removed HvdC minimum and maximum hysteresis specifications • Corrected HvcD nominal hysteresis from 1.32 to 1.36 <p>In Table 18 (VRC SMPS recommended external devices), updated specifications for device Q (FET).</p> <p>Renamed Section 3.9, Supply current characteristics (was "Power dissipation and current consumption").</p> <p>Renamed Table 19 (Current consumption characteristics) (was "Power dissipation characteristics").</p> <p>In Table 19 (Current consumption characteristics):</p> <ul style="list-style-type: none"> • Updated ADC current consumption to 1.2 mA per ADC plus 0.7 mA (2.0 mA total) for ADC0. • Updated Run I_{DD} to 900 mA max. <p>Updated Accuracy specification in Table 20 (Temperature sensor electrical characteristics): changed "T_J = -40 °C to T_A = 25 °C" to "T_J = -40 °C to T_A = 125 °C," removed row "T_J = T_A to 125 °C".</p> <p>In Table 21 (Main oscillator electrical characteristics), added symbol name F_{XOSCHS} for Oscillator frequency specification.</p> <p>Removed "Typical" figures for these specifications.</p> <p>Added footnote "ADC0 includes 0.7 mA dissipation for the temperature sensor (TSENS)."</p> <p>In Table 22 (FMPLL electrical characteristics), added minimum and maximum values for specification f_{FREE}, "Free running frequency."</p> <p>In Table 23 (RC oscillator electrical characteristics):</p> <ul style="list-style-type: none"> • Added specification Δ_{IRCTIM} "Internal RC oscillator trimming step." • Removed specification Δ_{RCTIM} "Post trim accuracy: The variation of the PTF from the 16 MHz" (specification replaced by Δ_{IRCTIM} "Internal RC oscillator trimming step"). <p>In Table 24 (ADC conversion characteristics), updated Gain Error (GNE) to "min = -4 max = +4 LSB".</p> <p>Added Table 30 (Code flash write access timing) and Table 31 (Data flash write access timing).</p> |

Table 79. Revision history (continued)

| Revision | Date | Description of Changes |
|----------|------------|---|
| 5 | 6 Dec 2011 | <p>Editorial changes.</p> <p>Enabled the use of cross-references in this revision-history table beginning with Rev. 4.</p> <p>Changed title of Section 1, Introduction (was “Overview”).</p> <p>Added section headings: Section 1.1, Document overview, Section 1.2, Description</p> <p>In Table 1 (MPC5675K family device comparison):</p> <ul style="list-style-type: none"> Revised the DSPI entry to reflect the proper number of chip selects on MPC5675K and MPC5674K. Revised the FlexRay entry (was optional for all chips, is present on MPC5675K and optional on the others). Deleted the “Clock output” entry. <p>In Figure 1 (MPC5675K block diagram), added SWT_0 and SWT_1.</p> <p>In Section 1.6.3, Memory Protection Unit (MPU), deleted “The Memory Protection Unit splits the physical memory into 16 different regions.”</p> <p>In Section 1.6.11, DRAM controller, deleted “DDR 2 (optional)”.</p> <p>Revised Section 1.6.14, Deserial Serial Peripheral Interface (DSPI) modules, to reflect the accurate number of available chip selects.</p> <p>In Section 1.6.16, FlexCAN, deleted “Safety CAN features on 1 CAN module as implemented on MPC5604P”.</p> <p>In Table 17 (PMC electrical specifications):</p> <ul style="list-style-type: none"> Removed Min and Max values for LVD 1.2 V variation at reset, LVD 1.2 V variation after reset, LVD 1.2 V hysteresis, HVD 1.2 V variation at reset, HVD 1.2 V variation after reset, and HVD 1.2 V hysteresis. Updated Nominal HVD 1.2 V Typ value to 1.36 V. <p>In Table 18 (VRC SMPS recommended external devices), updated the “Part description”, “Nominal”, and “Description” columns for reference designator Q.</p> <p>In Table 22 (FMPLL electrical characteristics):</p> <ul style="list-style-type: none"> Updated $f_{REF_CRYSTAL}$ and f_{REF_EXT} min to 4 MHz; max to 120 MHz. For this spec, added footnote: “PFD clock range is 4– 16 MHz. An appropriate IDF should be chosen to divide the reference frequency to this range.” Updated f_{PLL_IN} min to 4 MHz; max to 16 MHz. Updated f_{FREE} min to 19 MHz; max to 60 MHz. Updated t_{pH} max to 200 μs. Updated t_{dc} min to 20%; max to 80%. Updated C_{JITTER} max peak-to-peak to 160 ps; removed min. Added footnote on condition: “Core operating at 180 MHz.” Updated long-term jitter max to 6 ns. Updated f_{LCK} min to –4%; max to +4%. Updated f_{UL} min to –16%; max to +16%. Updated Modulation Depth f_{CS} min to $\pm 0.25\%$; max to $\pm 4\%$; f_{DS} min to –0.5%; max to –8%. Removed f_{MOD} min; updated max to 35 kHz for LDF > 63; (2240/LDF) kHz for $31 < LDF < 63$. <p>In Table 23 (RC oscillator electrical characteristics), changed the temperature in the condition for f_{RC} (was 27 °C, is 25 °C).</p> <p>In Table 24 (ADC conversion characteristics), changed the maximum specification for DNL (was 1.0 LSB, is 2 LSB).</p> <p>In Section 3.18, PDI pads specifications:</p> <ul style="list-style-type: none"> Changed bullet “VDD_HV_PDI range” to “VDD_HV_PDI range 1.8 V to 3.3 V, as specified in the following tables” and removed sub-bullets. Consolidated the three sets of DC and AC specifications (for 1.8 V, 2.5 V, and 3.3 V) into one set of specifications spanning the range 1.62–3.6 V. (Section headers 3.18.1, 3.18.2, and 3.18.3 removed, and titles of Table 38 (PDI pads DC electrical characteristics), Table 39 (Drive current), and Table 40 (PDI pads AC electrical characteristics) changed.) |

Table 79. Revision history (continued)

| Revision | Date | Description of Changes |
|--------------|------------|--|
| 5 (cont.) | 6 Dec 2011 | <p>In Section 3.19, DRAM pad specifications, added the note “0.7 V overshoot/undershoot can be allowed to occur repeatedly throughout the product expected lifetime and will not cause any long term reliability issue.”</p> <p>In Table 45 (DRAM pads DC electrical specifications (V_{DD_HV_DRAM} = 3.3 V)):</p> <ul style="list-style-type: none"> • Updated V_{DD_HV_DRAM_VTT} minimum value to V_{DD_HV_DRAM_VREF} - 0.05 (changed “x” to “-”) • Updated V_{IL} maximum value to V_{DD_HV_DRAM_VREF} - 0.2 (changed “x” to “-”) • Removed ODT conditions for V_{OH} and V_{OL}. • Updated V_{OL} maximum value to V_{DD_HV_DRAM_VTT} - 0.8 (changed “x” to “-”) <p>In Table 48 (DRAM pads DC electrical specifications (V_{DD_HV_DRAM} = 2.5 V)), removed ODT conditions for V_{OH} and V_{OL}.</p> <p>In Table 51 (DRAM pads DC electrical specifications (V_{DD_HV_DRAM} = 1.8 V)):</p> <ul style="list-style-type: none"> • Changed the minimum specification for V_{DD_HV_DRAM} (was 1.7 V, is 1.62 V). • Removed ODT conditions for V_{OH} and V_{OL}. • Updated V_{OH} minimum value to 1.42 V • Updated V_{OL} maximum value to 0.28 V <p>Added Section 3.20.2, RESET_SUP_B pin characteristics.</p> <p>Updated Note under Section 3.21.4.2, External VREG mode.</p> <p>Updated Figure 18 (External VREG mode, RESET_SUP rises after V_{DD_HV_xxx} are stable) to add T_{RSTSUP}</p> <p>Added Section 3.22.2.1, Standard interface timing, and revised the specifications in Table 62 (JTAG pin AC electrical characteristics).</p> <p>Added Section 3.22.2.2, Interface timing for Full Cycle mode.</p> <p>Replaced the contents of Section 3.22.3, Nexus timing, with the following:</p> <ul style="list-style-type: none"> • Table 64 (Nexus debug port timing Div mode = 2) and Figure 29 (Nexus SDR (Even divisor) timing) • Table 65 (Nexus debug port timing Divide by 3 SDR mode) and Figure 30 (Nexus SDR output timing for DIV=3) • Table 66 (Nexus debug port timing DIVIDE by 4 DDR mode) and Figure 31 (Nexus DDR mode timing) <p>In Section 5, Orderable parts, updated the orderable part numbers.</p> <p>Updated the entry for Rev. 4 in this revision history.</p> |

Table 79. Revision history (continued)

| Revision | Date | Description of Changes |
|----------|------------|---|
| 6 | 6 Feb 2012 | <p>In Section 1.5, Feature list, removed “Replicated 32 channel eDMA controller” under “Interrupts”.</p> <p>In Table 9 (257 MAPBGA pin multiplexing), changed “A2: ebi_Dn” to “A2: ebi_ADn” for balls H17, J17, K14, AND K15.</p> <p>In Table 10 (473 MAPBGA pin multiplexing), changed “A2: ebi_Dn” to “A2: ebi_ADn” for balls C22, D22, F21, F23, G20, G21, G22, G23, H20, J20, J21, J22, J23, K21, K22, K23, M22, M23, N20, N21, N22, N23, P20, P21, T20, T21, U21, V21, W21, Y21, Y22, and AA23.</p> <p>In Table 11 (Absolute maximum ratings):</p> <ul style="list-style-type: none"> Removed “incl. analog pins TBD” for I_{INJPAD}. Added numerical data to Note 3. <p>In Table 17 (PMC electrical specifications), added min/max information for LvdC and HvdC.</p> <p>In Table 21 (Main oscillator electrical characteristics), split “Oscillator start-up time” into two lines and added numerical data.</p> <p>In Table 22 (FMPLL electrical characteristics):</p> <ul style="list-style-type: none"> Added line numbers to table. Changed TBD to “—” and added numerical data for f_{sys}. Changed TBDs to numerical data for f_{LORL}, f_{LORH}, and f_{SCM}. Changed TBD to “—” for C_{jitter}. <p>In Table 24 (ADC conversion characteristics):</p> <ul style="list-style-type: none"> Changed t_{ADC_E} conditions from TBD to 60 MHz. Changed C_{P2} max value from TBD to 0.8 pF. Added a footnote to TUE specs noting that sample averaging is required. Changed TUE min and max values from TBDs to numerical data. Changed THD min value from TBD to -72 dB. <p>In Table 25 (Code flash memory program and erase electrical specifications), Table 26 (Data flash memory program and erase electrical specifications), Table 28 (Code flash read access timing) and Table 29 (Data flash read access timing), corrected the line numbering.</p> <p>In Table 30 (Code flash write access timing):</p> <ul style="list-style-type: none"> Removed f_{WRITE} for 60 MHz. Corrected the line numbering. Changed TBD to “—”. <p>In Table 31 (Data flash write access timing):</p> <ul style="list-style-type: none"> Removed f_{WRITE} for 60 MHz. Corrected the line numbering. Changed TBD to “—”. <p>In Table 32 (System SRAM memory read/write access timing):</p> <ul style="list-style-type: none"> Changed name from “read access timing” to “read/write access timing”. Changed symbol to S_{READ/WRITE}. Removed S_{READ/WRITE} for 60 MHz. <p>Removed table “System SRAM memory write access timing”.</p> <p>In Table 38 (PDI pads DC electrical characteristics), corrected the line numbering.</p> <p>In Table 61 (DDR and DDR2 (DDR2-400) SDRAM timing specifications):</p> <ul style="list-style-type: none"> removed t_{DQSEN} and the associated footnotes. Corrected the line numbering. <p>In Table 62 (JTAG pin AC electrical characteristics), corrected the line numbering.</p> <p>In Table 67 (External interrupt timing (NMI IRQ)):</p> <ul style="list-style-type: none"> Changed T_{IPWL} min value from TBD to 3. Changed T_{IPWH} min value from TBD to 3. Changed T_{ICYC} min value from TBD to 6. Changed all units from ns to t_{CYC}. |

Table 79. Revision history (continued)

| Revision | Date | Description of Changes |
|--------------|-------------|--|
| 6 (cont.) | 6 Feb 2012 | In Table 68 (External interrupt timing (GPIO IRQ)) : <ul style="list-style-type: none"> • Changed T_{IPWL} min value from TBD to 3. • Changed T_{IPWH} min value from TBD to 3. • Changed T_{ICYC} min value from TBD to 6. • Changed all units from ns to t_{CYC}. In Table 77 (I²C SCL and SDA input timing specifications) , corrected the line numbering. |
| 6.1 | 30 Mar 2012 | No content changes, technical or editorial, were made in this revision. Change bars are identical to those in Rev. 6. Removed the “preliminary” footers throughout. Changed “Data Sheet: Advance Information” to “Data Sheet: Technical Data” on page Removed the “product under development” disclaimer on page 1. |
| 7 | 18 May 2012 | Minor editorial changes and improvements throughout. In Section 1.3, Device comparison, Table 1 (MPC5675K family device comparison) , <ul style="list-style-type: none"> • Changed the CPU/Data Cache entry from “16 KB, 4-way with EDC (SoR)” to “16 KB, 4-way with Parity (SoR)”. • Added footnotes to stipulate the peripheral instances that are used on derivative devices: <ul style="list-style-type: none"> - Added footnote to MPC5673K DSPI module: “DSPI_0 and DSPI_1.” - Added footnote to MPC5673K I2C module: “I2C_0 and I2C_1.” - Added footnote to MPC5673K LinFlex module: “LinFlex_0, LinFlex_1, and LinFlex_2” In Section 1.4, Block diagram : <ul style="list-style-type: none"> • Added missing modules (PMC, SPE2, VLE, and flash). • Added an arrow each from Core_0 and Core_1 to the XBAR modules to represent the data path. • Updated the Redundancy Checkers to reflect the actual implementation. • Renamed the “JTAG/Nexus” block to “Debug”, with JTAG and Nexus shown as submodules. In Section 1.5, Feature list , changed “Junction temperature sensor” to “Silicon substrate (die) temperature sensor”. In Section 1.6.1, High-performance e200z7d core processor and Section 1.6.9, Cache memory , removed the bullet “Supports tag and data parity” and added the following bullets: <ul style="list-style-type: none"> — Supports tag and data cache parity — Supports EDC for instruction cache In Section 1.6.19, System Timer Module (STM) , changed “Duplicated periphery to guarantee that safety targets (SIL3) are achieved” to “Replicated periphery to provide safety measures respective to high safety integrity levels (for example, SIL 3, ASIL D)” In Section 1.6.20.2, Cross Triggering Unit (CTU) , changed “DMA support with safety features” to “Supports safety measures using DMA”. In Section 1.6.21, Redundancy Control and Checker Unit (RCCU) , changed “Duplicated module to guarantee highest possible diagnostic coverage (check of checker)” to “Duplicated module to enable high diagnostic coverage (check of checker)”. In Section 1.6.22, Software Watchdog Timer (SWT) , <ul style="list-style-type: none"> • Changed “Duplicated periphery to guarantee that safety targets (SIL3) are achieved” to “Replicated periphery to provide safety measures respective to high safety integrity levels (for example, SIL 3, ASIL D)”. • Changed “Allows high level of safety (SIL3 monitor)” to “Provides measures to target high safety integrity levels (for example, SIL 3, ASIL D)”. In Section 1.6.25, Cyclic Redundancy Checker (CRC) unit , in the sentence “Key engine to be coupled with communication periphery where CRC application is added to allow implementation of safe communication protocol”, changed “allow” to “support”. |

Table 79. Revision history (continued)

| Revision | Date | Description of Changes |
|--------------|-------------|--|
| 7 (cont.) | 18 May 2012 | <p>In Section 3.2, Absolute maximum ratings, Table 11 (Absolute maximum ratings),</p> <ul style="list-style-type: none"> Deleted footnote to the Max value “Absolute maximum voltages are currently maximum burn-in voltages. Absolute maximum specifications for device stress have not yet been determined.” Added footnote to $V_{DD_HV_DRAM}$: “As the $V_{DD_HV_DRAM_VREF}$ supply should always be constrained by the $V_{DD_HV_DRAM}$ supply for example through a voltage divider network per the JEDEC specification, the maximum ratings for the $V_{DD_HV_DRAM}$ supply should be used for the $V_{DD_HV_DRAM_VREF}$ reference as well.” Changed absolute max rating for $V_{DD_LV_PLL}$ from 1.4 to 1.32. Added footnote to Min value of T_{STG}: “If the ambient temperature is at or above the minimum storage temperature and below the recommended minimum operating temperature, power may be applied to the device safely. However, functionality is not guaranteed and a power cycle must be administered if in internal regulation mode or an assertion of $RESET_SUP_B$ must be administered if in external regulation mode once device enters into the recommended operating temperature range.” <p>In Section 3.3, Recommended operating conditions, Table 12 (Recommended operating conditions),</p> <ul style="list-style-type: none"> For T_A and T_J, added footnote “When determining if the operating temperature specifications are met, either the ambient temperature or junction temperature specification can be used. It is not necessary that both specifications be met at all times. However, it is critical that the junction temperature specification is not exceeded under any condition.” For T_A, changed the Max temperature spec for the 257 package from 105 to 125 and deleted footnote: “Preliminary data.” <p>In Section 3.8.1, PMC electrical specifications, Table 17 (PMC electrical specifications),</p> <ul style="list-style-type: none"> No. 4 LvdC and No. 5 HvdC threshold were specified as rising edge and hysteresis. The specification is changed to rising edge / falling edge. Removed No. 6, VddStepC, and renumbered subsequent lines. <p>In Section 3.9, Supply current characteristics, Table 19 (Current consumption characteristics), added a footnote to No. 3. Idd_HV_FL A. “The current specified for Idd_HV_FL A includes current consumed during programming and erase operations.”</p> <p>In Section 3.12, FMPLL electrical characteristics, Table 22 (FMPLL electrical characteristics), replaced “f_{sys}” with “$f_{FMPLLOUT}$” in rows for C_{JITTER}, f_{LCK}, f_{UL}, f_{CS}/f_{DS}, and footnote 9.</p> <p>In Section 3.14.1, Input impedance and ADC accuracy:</p> <ul style="list-style-type: none"> Changed “C_S being substantially a switched capacitance...” to “C_S and C_{P2} being substantially a switched capacitance...” Changed “and the sum of $R_S + R_F + R_L + R_{SW} + R_{AD}$, ...” to “and the sum of $R_S + R_F$...” Changed the equation $V_A \cdot \frac{R_S + R_F + R_L + R_{SW} + R_{AD}}{R_{EQ}} < \frac{1}{2} \text{LSB}$ <p>to</p> $V_A \cdot \frac{R_S + R_F}{R_{EQ}} < \frac{1}{2} \text{LSB}$ <ul style="list-style-type: none"> Added new spec after line 3 for $t_{ADC_S_PMC}$, C: Parameter: Sample time of internal PMC channels. Conditions: -, Min : 717, Typ : -, Max : -, Unit : nS. <p>In Section 3.17.1, GP pads DC specifications, Table 33 (GP pads DC electrical characteristics), added new spec for “Input pad capacitance”, No. 21.</p> |

Table 79. Revision history (continued)

| Revision | Date | Description of Changes |
|--------------|-------------|--|
| 7 (cont.) | 18 May 2012 | <p>In Section 3.18, PDI pads specifications, Table 38 (PDI pads DC electrical characteristics), added footnote to table: “Over- and undershoots occurring due to impedance mismatch of the external driver and the transmission line at PDI pads in input mode can be allowed up to 0.7 V repeatedly throughout the product expected lifetime and will not cause any long term reliability issue.”</p> <p>In Section 5, Orderable parts,</p> <ul style="list-style-type: none">• Removed “3 = 220 MHz” under Operating frequency heading and changed the Operating frequency of the example from “3” to “2”.• Deleted Table 73 (Orderable part number summary). |

Table 79. Revision history (continued)

| Revision | Date | Description of Changes |
|----------|-----------------|--|
| 8 | 29 October 2013 | <p>In Table 1 (MPC5675K family device comparison):</p> <ul style="list-style-type: none"> added "(ECC)" to all code flash and data flash memory regions. footnote 6 changed to "any two of the three I2C can be chosen". Flexray module made optional for MPC5675K also. <p>Added new sections - Section 3.17.3, I/O pad current specifications, Section 3.18.1, PDI pad current specifications and Section 3.19.4, DRAM Pad Current Specifications.</p> <p>Added new sections - Section 3.17.4, Power Sequence Pin States for GPIO Pads, Section 3.18.2, Power Sequence Pin States for PDI Pads and Section 3.19.5, Power Sequence Pin States for DRAM Pads.</p> <p>In Section 3.22.8.1, MII receive signal timing (RXD[3:0], RX_DV, RX_ER, and RX_CLK), changed the text from "In addition, the system clock frequency must exceed four times the RX_CLK frequency." to "In addition, the system clock frequency must exceed two times the RX_CLK frequency".</p> <p>In Section 3.22.8.2, MII transmit signal timing (TXD[3:0], TX_EN, TX_ER, TX_CLK), changed the text from "In addition, the system clock frequency must exceed four times the TX_CLK frequency." to "In addition, the system clock frequency must exceed two times the TX_CLK frequency".</p> <p>Added a foot note for TCK pin in Table 7 (257 MAPBGA system pins) and Table 8 (473 MAPBGA system pins) - "If LBIST is enabled, an external pull between 1K and 100K ohm must be connected from TCK to either power or ground to avoid LBIST failures".</p> <p>In Table 11 (Absolute maximum ratings), changed max absolute maximum ratings from 3.6 V to 3.63 V for all 3 V rails.</p> <p>In Table 12 (Recommended operating conditions),</p> <ul style="list-style-type: none"> changed recommended operating conditions from 3.6 V to 3.63 V for all 3 V rails. added a footnote for $V_{DD_HV_ADR_x}$ - "If this supply is not above its absolute minimum recommended operating level, LBIST operations can fail". <p>Removed the table footnote - "These specifications are design targets and are subject to change per device characterization" from Table 12 (Recommended operating conditions), Table 13 (Thermal characteristics for package options), Table 25 (Code flash memory program and erase electrical specifications), Table 26 (Data flash memory program and erase electrical specifications) and Table 33 (GP pads DC electrical characteristics).</p> <p>In Table 17 (PMC electrical specifications):</p> <ul style="list-style-type: none"> added row for V_{adctol}. changed typical value of $V_{DD_LV_COR}$ from 1.28 V to 1.24 V. updated voltage levels for $V_{DD_LV_COR}$, LvdC and HvdC. updated the wording for "$V_{DD_LV_COR}$" parameter. added new voltage levels for LvdReg. removed "LVD 3.3 V variation at reset", "LVD 3.3 V variation after reset", and "LVD 3.3 V hysteresis" entries for "LvdReg" parameter. <p>In Table 24 (ADC conversion characteristics), added a sentence on 7th table note - "The ADC1 self test limit for the S2 algorithm needs to be modified by the user to accommodate for the increased TUE limit of +/-10 counts when operating the device in internal regulation mode. This can be accomplished by reading the current value from the test flash and subtracting 4 counts before storing the value to the ADC1 Self Test Analog Watchdog Register 2 (STAW2R)".</p> <p>In Table 26 (Data flash memory program and erase electrical specifications), description of $T_{DWPORGAM}$ changed to "Single word (32 bits) program time".</p> <p>In Table 33 (GP pads DC electrical characteristics),</p> <ul style="list-style-type: none"> added rows for V_{ILRSB} and V_{IHRSB}. in I_{IL}, added two new rows for two new parameters to specify the spec for analog pad leakage for shared and single ADC pads - "Input leakage current (All single ADC channels)" and "Input leakage current (All shared ADC channels)". |

Document revision history

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|-------------|-----------------|--|
| 8 (Contd..) | 29 October 2013 | In Table 58 (RESET sequences) , changed min values of T_{DRB} and T_{ERLB} from 60 to 50 ms and typ values from 65 to 60 ms. In Table 62 (JTAG pin AC electrical characteristics) , updated the footnote to - " $f_{TCK} = 1/t_{TCK}$. f_{TCK} must not exceed 1/4 the frequency of the system clock (SYS_CLK)." Reverted the first term of Equation 11 . |
| 8.1 | 24 April 2020 | Changed Freescale to NXP throughout the data sheet. |

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